Memory User Guide for Nexus Platform

Technical Note

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Acronyms in This Document

A list of acronyms used in this document.

Acronym	Definition
ASCII	American Standard Code for Information Interchange
AW	Address Width
CIB	Common Interface Block
DW	Data Width
EBR	Embedded Block RAM
ECC	Error-Correcting Code
EDIF	Electronic Design Interchange Format
FIFO	First In First Out
IP	Intellectual Property
LRAM	Large Random Access Memory
LSB	Least Significant Bit
LUT	Look-up Table
MSB	Most Significant Bit
PFU	Programmable Function Unit
PMI	Parameterizable Module Instantiation
RAM	Random Access Memory
ROM	Read-Only Memory
RST	Reset
SECDED	Single Error Correction – Double Error Detection
SRAM	Static Random Access Memory
VHDL	VHSIC Hardware Description Language

1. Introduction

This technical note discusses memory usage for the Lattice Semiconductor devices built on the Lattice Nexus™ platform, which include CrossLink™-NX, Certus™-NX, CertusPro™-NX, and MachXO5™-NX. It is intended to be used by design engineers as a guide when integrating the Embedded Block RAM (EBR)-based, Programmable Function Unit (PFU)-based, and peripheral Static Random Access Memory (SRAM) memories for these device families in Lattice Radiant™ software.

The architecture of these devices provides many resources for memory-intensive applications. The sysMEM™ EBR complements its distributed PFU-based memory. Single-Port RAM, Dual-Port RAM, pseudo Dual-Port RAM, FIFO, and ROM memories can be constructed using the EBR. The Look-up Tables (LUTs) and PFUs can implement Distributed Single-Port RAM, Dual-Port RAM, and ROM. LUTs within PFUs can implement Distributed Single-Port RAM, Dual-Port RAM, and ROM. The sysMEM Peripheral Block SRAM, Large RAM, can implement Single-Port RAM, Dual-Port RAM, ROM, and pseudo Dual-Port RAM.

The capabilities of the EBR Block RAM, PFU RAM, and Large RAM are referred to in this document. You can utilize the memory primitives in three separate ways:

- Through the IP Catalog – The IP Catalog interface allows you to specify the memory type and size required. The IP Catalog takes this specification and constructs a netlist to implement the desired memory by using one or more of the memory primitives.
- Through Parameterizable Module Inferencing (PMI) – PMI allows experienced users to skip the graphical interface and utilize the configurable memory primitives on-the-fly from the Lattice Radiant project navigator. The parameters and the control signals needed, either in Verilog or VHDL, can be set. The top-level design has the parameters defined and signals declared so the interface can automatically generate the black box during synthesis.
- Through the Instantiation of Memory Primitives – Memory primitives are called directly by the top-level module and instantiated in your design. This is an advanced method and requires a thorough understanding of memory hook-ups and design interfaces.

The remainder of this document discusses these methods.

2. Memory Generation

You can utilize the IP Catalog to easily specify a variety of memories in your designs. These modules are constructed using one or more memory primitives, along with general-purpose routing and LUTs as required.

The available modules in the IP Catalog are:

- Distributed Memory Modules
  - Distributed Dual-Port RAM (Distributed_DPRAM)
  - Distributed ROM (Distributed_ROM)
  - Distributed Single-Port RAM (Distributed_SPRAM)
- EBR Components or EBR-based Modules
  - Dual-Port RAM (RAM_DP_TRUE)
  - Pseudo Dual-Port RAM (RAM_DP)
  - Single-Port RAM (RAM_DQ)
  - Read-Only Memory (ROM)
- First In First Out Memory (EBR or LUT)
  - FIFO Single-Clock (FIFO)
  - FIFO Dual-Clock (FIFO_DC)
- Large RAM
  - Single-Port Large RAM (Large_RAM_SP)
  - True Dual-Port Large RAM (Large_RAM_DP_True)
  - Pseudo Dual-Port Large RAM (Large_RAM_DP)
  - Read-Only Memory (Large_ROM)

Figure 2.1 shows the memory modules under IP Catalog in Lattice Radiant software.

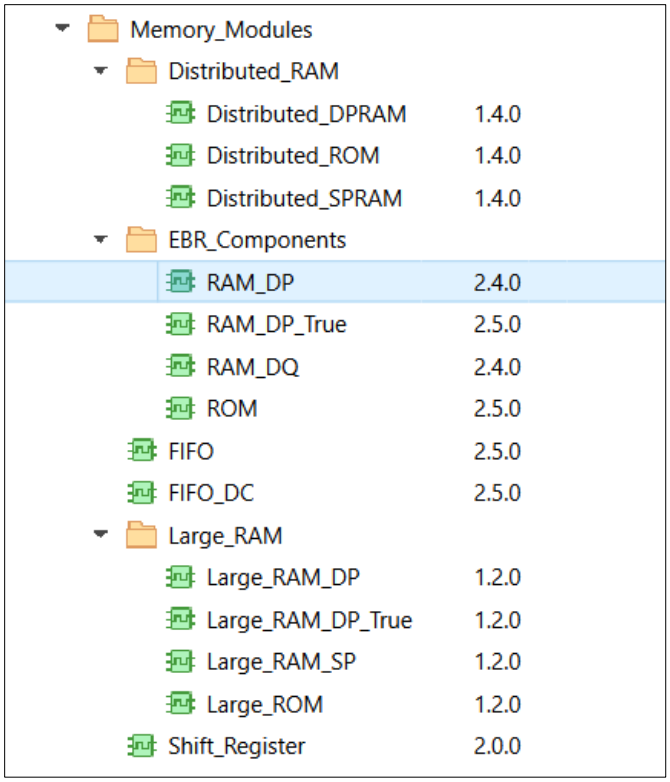

Figure 2.1. Memory Modules Available in IP Catalog

2.1. IP Catalog Flow

The IP Catalog allows you to generate, create, or open any of the available modules for Nexus platform devices.

In the Lattice Radiant software, choose **View** > **Show Views** > **IP Catalog**, or click the IP Catalog icon in the toolbar. This opens the IP Catalog window, as shown in Figure 2.2.

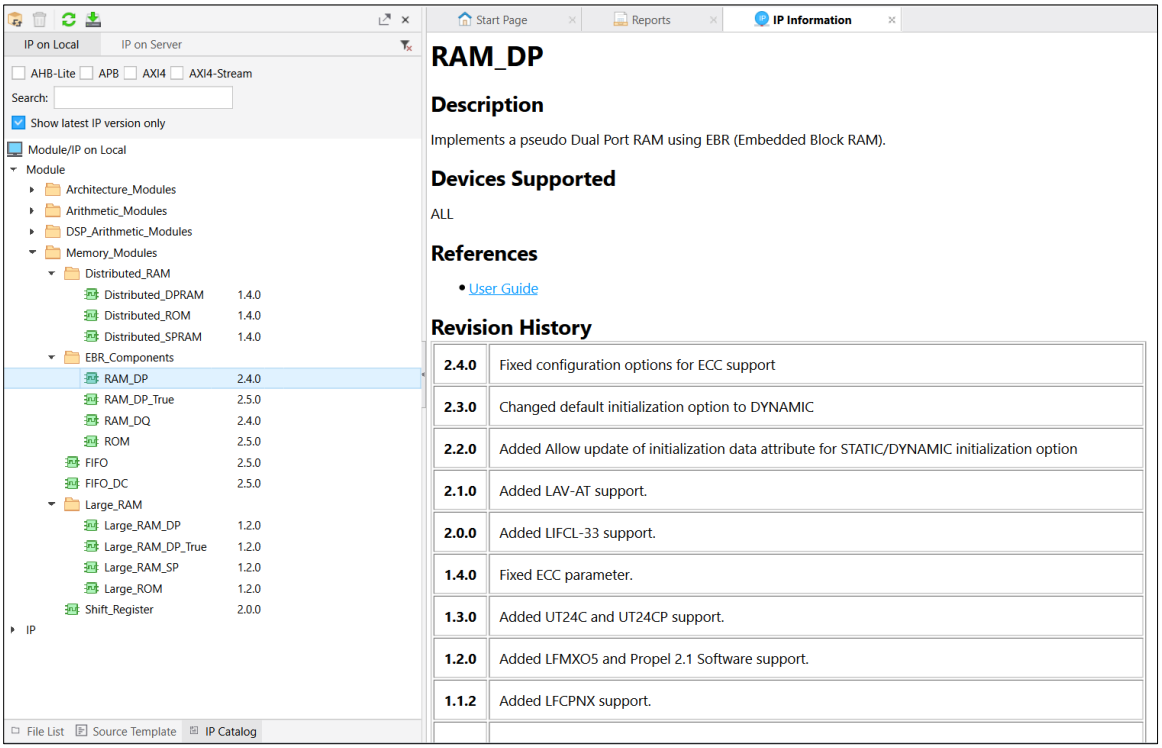

Figure 2.2. IP Catalog in Lattice Radiant Software

The left section of the IP Catalog window includes the Module Tree. The memory modules are categorized as Distributed RAM, EBR Components FIFOs, Large RAM, and Shift Register. The right section of the window shows the description of the module selected and links to the documentation for additional information.

This section provides an example of generating an EBR-based pseudo Dual-Port RAM of size 512 x 18.

To generate an EBR-based pseudo Dual-Port RAM:

1. Double-click **ram_dp** under the **EBR_Components**.
2. Fill out the information of the module to generate, as shown in Figure 2.3.
3. Click the **Next** button.

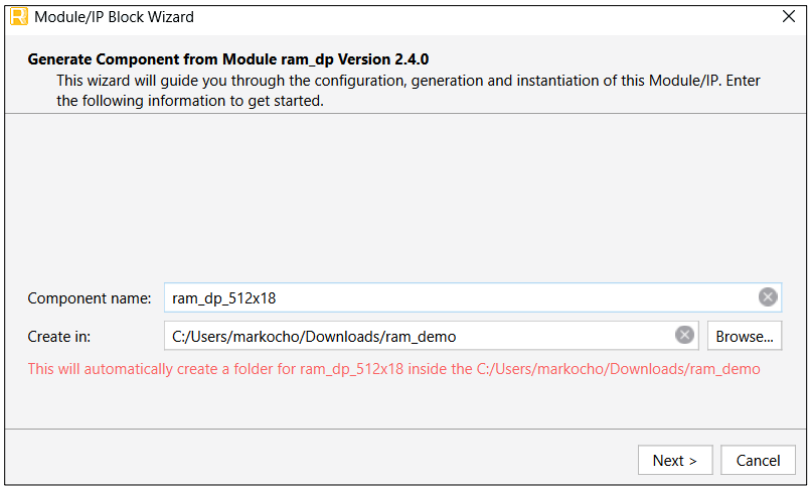

Figure 2.3. Example: Generating Pseudo Dual-Port RAM RAM_DP Using IP Catalog

4. Customize the EBR-based DPRAM in the **Module/IP Block Wizard** window, as shown in Figure 2.4.

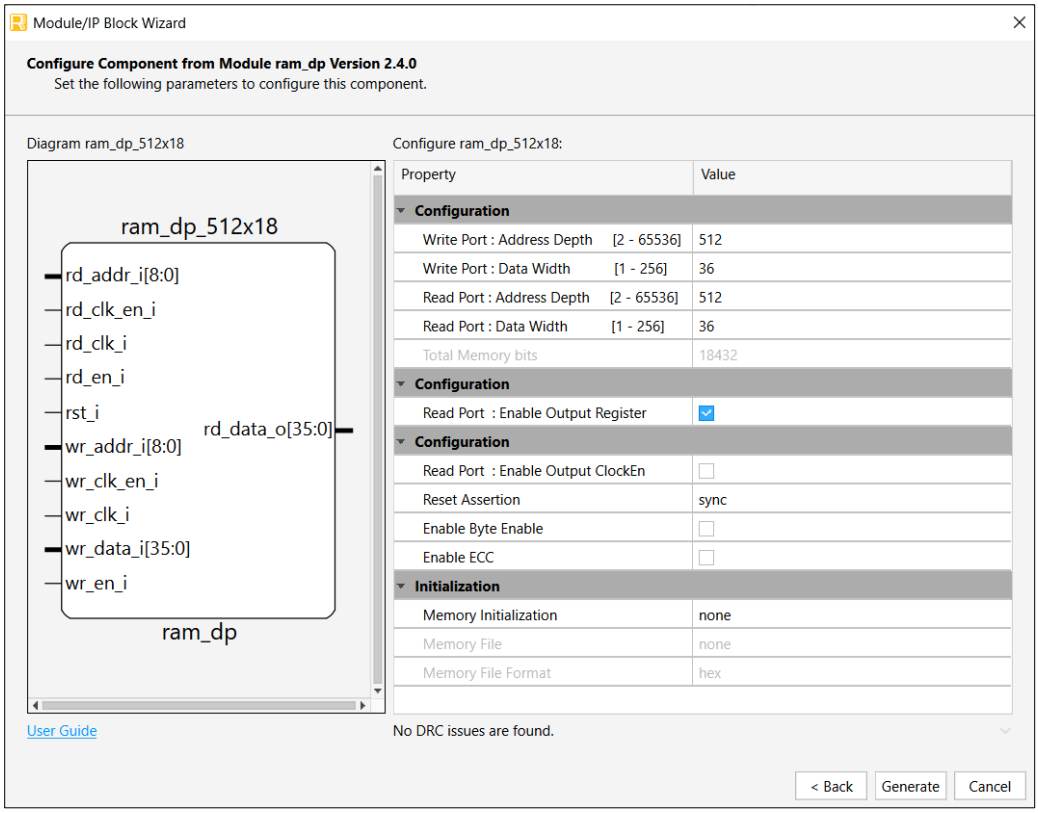

Figure 2.4. Example: Generating Pseudo Dual-Port RAM RAM_DP Module Customization – General Options

5. When all the options for the module being generated are filled out, click **Generate**.

This module, once in the Lattice Radiant project, can be instantiated within other modules.

2.2. Utilizing PMI

The parameters and control signals needed can be set in either Verilog or VHDL. The top-level design includes defined memory parameters and declared signals. The interface can then automatically generate the black box during synthesis, and Lattice Radiant can generate the netlist on-the-fly. The Lattice memories are the same as industry standard memories, so you can get the parameters for each module from any memory-related guide, which is available through the online help system.

To do this, create a Verilog or VHDL behavior code for the memory, and the synthesis tool automatically identifies it as memory and synthesize it as a distributed or EBR memory. Memory sizes smaller than 2 kb are automatically mapped to Distributed mode, and those larger than 2 kb are implemented using EBRs. This default option can be overridden using the RAM_STYLE attribute in Synopsys Synplify Pro®.

2.3. Utilizing Direct Instantiation of Memory Primitives

Another way to use the memories in the designs is by directly instantiating the memory primitives for the Nexus Platform devices. When instantiating the primitives, you must work at the EBR block level. If there is a need to have a memory that spans multiple modules, you are required to create the cascading memory on your own.

Lattice provides library files containing all the primitives in a VHDL/Verilog file under the cae_library/synthesis folder in the Lattice Radiant software installation folder.

3. Memory Features

The RAMs can be generated with Error Correction and Byte Enable that mask selective bits. These features are available in the EBR-based RAM modules.

3.1. ECC in Memory Modules

An Error-Correcting Code (ECC) code is a system of adding redundant data, or parity data, to a message such that it can be recovered by a receiver even when several errors are introduced, either during the process of transmission or on storage.

EBR-based memory modules in the IP Catalog allow you to implement ECC. There is a check box to enable ECC in the Configuration tab for the module.

Enabling the ECC check box allows error correction of single errors and detection of 2-bit errors. This is only supported in 512 x 32 EBR configuration mode.

The two bits indicate the error, if any, and the following shows you what each of these bits means:

- Error[1:0] = 00 Indicates there is no error.
- Error[0] = 1 Indicates there was a 1-bit error which was fixed.
- Error[1] = 1 Indicates there was a 2-bit error which cannot be corrected.

The error flags are aligned to the output data and are available in the same cycle as their respective data.

Note: ECC is only supported in Large RAM (LRAM) across all modes, and in Pseudo Dual-Port RAM (RAM_DP).

3.2. Byte Enable

Byte Enable is a feature available in the selected RAM modules where you can mask the bytes written in the RAM. Each Byte Enable bit controls the enable to 9 bits. The selection can be made in the IP Catalog while generating the module.

Each bit of the BE signal corresponds to the corresponding 9-bit selection, starting from the LSB side. For example, if you add Byte Enable to an 18-bit wide RAM, then Table 3.1 explains how the written data, Data In, is masked for a 9-bit Byte Size. Bits 8, 17, 26, and 35 are parity bits, which you ignore in x8, x16, and x32 modes.

Table 3.1. Masked Data In Bits for a 9-Bit Byte Size

Byte Enable Bit	Data In Bits that Get Masked with 9-bit Byte Size
ByteEn(0)	Data(8:0)
ByteEn(1)	Data(17:9)
ByteEn(2)	Data(26:18)
ByteEn(3)	Data(35:27)

Note that the ByteEn and ECC are mutually exclusive and cannot be used together.

4. Memory Modules

The following sections discuss the different modules, the size of memory that each EBR block or the Distributive primitive can support, and any special options for the module.

When you specify the width and depth of the memory in the IP Catalog, the tool generates the memory by depth cascading and/or width cascading, EBR blocks, or distributed RAM primitives. The IP Catalog automatically allows you to create memories larger than the width and depth supported for each primitive.

4.1. Memory Cascading

For memory sizes that are smaller than what can fit in a single EBR block or the distributed primitive, the module utilizes the complete block or primitive.

For memory sizes larger than that of a single module, the multiple modules are cascaded, either in depth or width, to create a larger module.

4.1.1. Input and Output Register

The architecture of the EBR blocks in Nexus platform devices is designed such that the inputs that go into memory are always registered. This means that the input data and address are always registered at the input of the memory array. The output data of the memory is optionally registered at the output. You can choose this option by selecting the Enable Output Register check box in the IP Catalog while customizing the module.

Control signals like WE and Byte Enable that go into the EBR block are also registered.

4.1.2. Reset

The EBRs also support the Reset signal. The Reset (RST) signal resets the output registers of the RAM. It does not reset the contents of the memory.

4.1.3. Timing

To correctly write into a memory cell in the EBR block, the correct address should be registered by the logic. Hence, it is important to note that while running the trace on the EBR blocks, there should be no setup or hold time violations on the address registers. Failing to meet these requirements can result in incorrect addressing and corruption of memory contents.

During a read cycle, a similar issue can occur. The correct contents are not read if the address is not correctly registered in the memory.

A Post-Place and Route timing report in the Lattice Radiant design software can be run to verify that no such timing errors occur. Refer to the timing preferences in the Online Help document.

4.2. Single-Port RAM (RAM_DQ) – EBR-Based

FPGAs built on the Nexus platform support all the features of a Single-Port Memory Module or RAM_DQ. The IP Catalog allows you to generate the Verilog-HDL or VHDL along with the Electronic Design Interchange Format (EDIF) netlist for the memory size as per the design requirement.

IP Catalog generates the memory module, as shown in Figure 4.1.

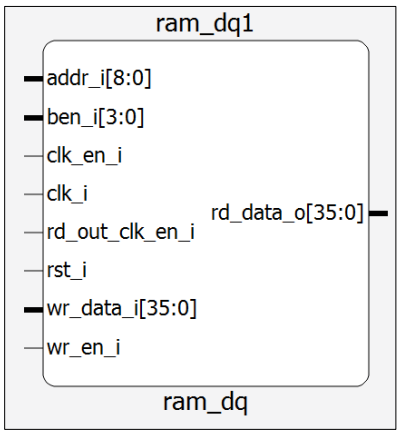

Figure 4.1. Single-Port Memory Module Generated by IP Catalog

Figure 4.2 provides the primitive that can be instantiated for the Single-Port RAM. The primitive name is SP16K, and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under the cae_library/synthesis folder in the Lattice Radiant software installation folder.

It is to be noted that each EBR can accommodate 18 kb of memory. If the memory required is larger than 18 kb, then cascading can be used using the CS port.

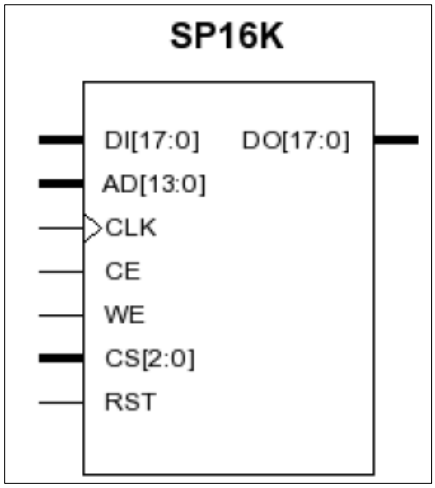

Figure 4.2. Single-Port RAM Primitive for Nexus Platform Devices

The various ports and their definitions for Single-Port Memory are listed in Table 4.1. The table lists the corresponding ports for the module generated by IP Catalog.

Table 4.1. EBR-Based Single-Port Memory Port Definitions[1]

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	Input Clock Enable
rd_out_clk_en_i	Input	1	Read Output Register Enable (Present is Enable Output Register == TRUE)
wr_en_i	Input	1	Write Enable
wr_data_i	Input	Data Width	Data Input
addr_i	Input	Address Width	Address Bus
rd_data_o	Output	Data Width	Data Output
ben_i	Input	4	Byte Enable

Note:

1. Address width is calculated from address depth.

Each EBR block consists of 18,432 bits of RAM. The address value x and data value y of each EBR block are listed in Table 4.2.

Table 4.2. Single-Port Memory Sizes for 18 kb Memory in Nexus Platform Devices

Single-Port Memory Size	Input Data	Output Data	Address [MSB:LSB]
16,384 × 1	DI	DO	AD[13:0]
8,192 × 2	DI[1:0]	DO[1:0]	AD[12:0]
4,096 × 4	DI[3:0]	DO[3:0]	AD[11:0]
2,048 × 9	DI[8:0]	DO[8:0]	AD[10:0]
1,024 × 18	DI[17:0]	DO[17:0]	AD[9:0]
512 × 36	DI[35:0]	DO[35:0]	AD[8:0]

Table 4.3 shows the various attributes available for the Single-Port Memory, RAM_DQ. You can select some of these attributes through the IP Catalog interface.

The ones without selectable options in the IP Catalog are handled by the engine. However, you can access these options if you are working with direct primitive instantiation.

Table 4.3. Single-Port Memory Attributes in Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the Read and Write port.	2–<Max that can fit in the device>	512
Data Width	Data word width of the Read and Write port.	1–512	36
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	True, False	True
Enable Output ClockEn	Clock Enable for the output clock. This option requires enabling Enable Output Register.	True, False	False
Enable Byte Enable	Allows you to select Byte Enable options.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock.	async, sync	sync
Memory Initialization	Allows you to initialize your memory to all 1s, 0s, or to use a custom initialization by providing a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for the custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for RAM_DQ. The waveforms in Figure 4.3 and Figure 4.4 show the internal timing waveforms for the Single-Port RAM, RAM_DQ, without output registers and with output registers respectively.

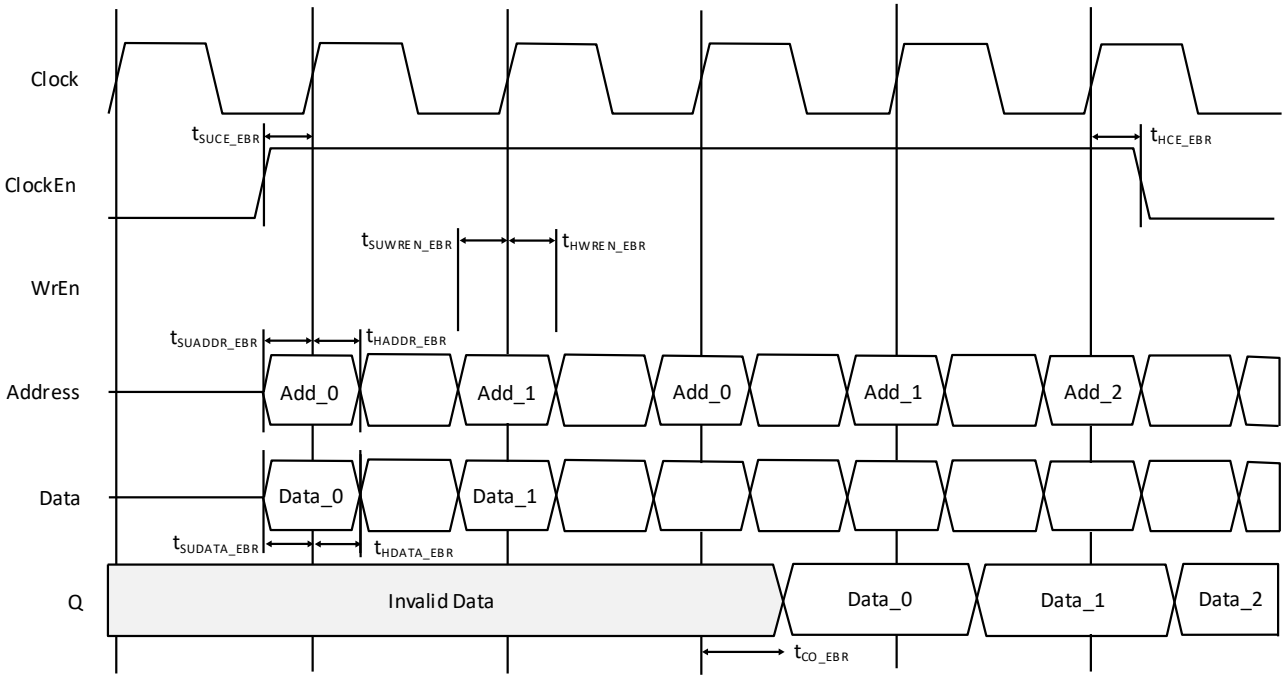

Figure 4.3. Single-Port RAM Timing Waveform – without Output Registers

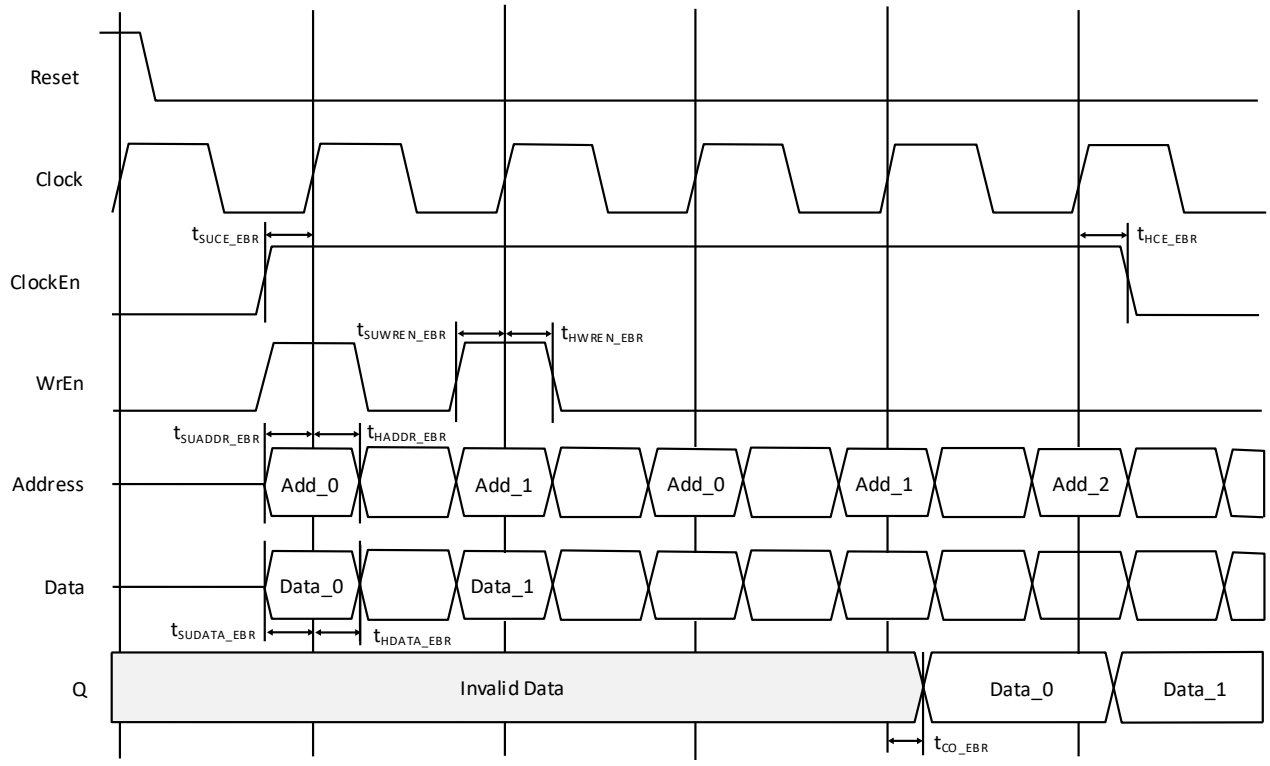

Figure 4.4. Single-Port RAM Timing Waveform – with Output Registers

4.3. True Dual-Port RAM (RAM_DP_TRUE) – EBR-Based

The EBR blocks in the Nexus platform devices can be configured as True-Dual Port RAM, RAM_DP_TRUE. The IP Catalog allows you to generate the Verilog-HDL, VHDL, or EDIF netlists for the memory size as per design requirements.

IP Catalog generates the memory module, as shown in Figure 4.5.

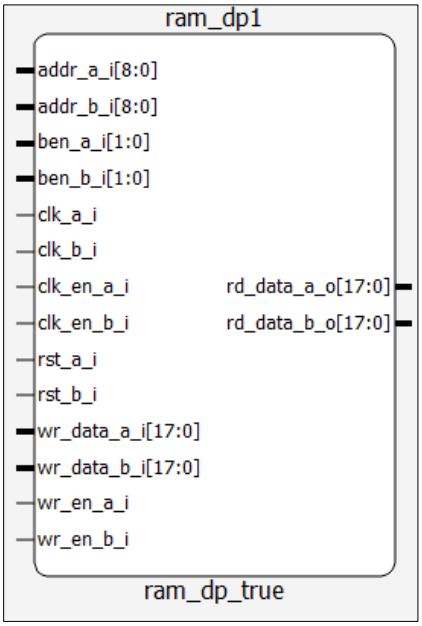

Figure 4.5. True Dual-Port Memory Module Generated by IP Catalog

Figure 4.6 provides the primitive that can be instantiated for the True Dual-Port RAM. The primitive name is DP16K, and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under the cae_library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 18 kb of memory. If the memory required is larger than 18 kb, then cascading can be used using the CS port. In this case, CSA and CSB are the CS ports.

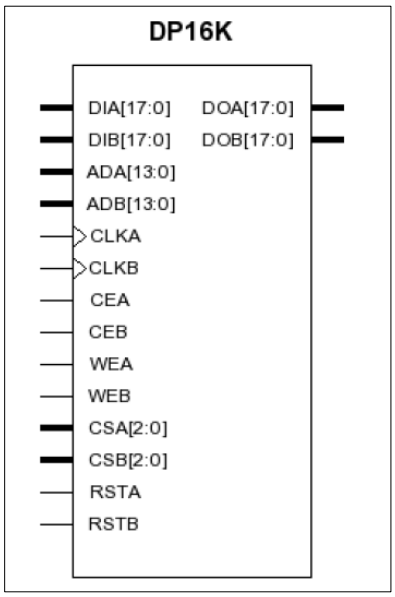

Figure 4.6. True Dual-Port RAM Primitive for Nexus Platform Devices

The various ports and their definitions for true Dual-Port RAM are listed in Table 4.4. The table lists the corresponding ports for the module generated by the IP Catalog.

Table 4.4. EBR-Based True Dual-Port Memory Port Definitions

Port Name	Direction	Width	Description
clk_a_i	Input	1	Clock for Port A
rst_a_i	Input	1	Reset for Port A
clk_en_a_i	Input	1	Clock Enable for Port A
wr_en_a_i	Input	1	Write Enable for Port A
wr_data_a_i	Input	Data Width	Data Input for Port A
addr_a_i	Input	Address Width	Address Bus for Port A
rd_data_a_o	Output	Data Width	Data Output for Port A
ben_a_i	Input	2	Byte Enable for Port A
clk_b_i	Input	1	Clock for Port B
rst_b_i	Input	1	Reset for Port B
clk_en_b_i	Input	1	Clock Enable for Port B
wr_en_b_i	Input	1	Write Enable for Port B
wr_data_b_i	Input	Data Width	Data Input for Port B
addr_b_i	Input	Address Width	Address Bus for Port B
rd_data_b_o	Output	Data Width	Data Output for Port B
ben_b_i	Input	2	Byte Enable for Port B

Each EBR block consists of 18,432 bits of RAM. The address values w and x and data value y and z for each EBR block are listed in Table 4.5.

Table 4.5. Dual Port Memory Sizes for 18 kb Memory for Nexus Platform Devices

Dual Port Memory Size	Input Data Port A	Input Data Port B	Output Data Port A	Output Data Port B	Address Port A	Address Port B
16384 × 1	DataInA	DataInB	QA	QB	AddressA(13:0)	AddressB(13:0)
8192 × 2	DataInA(1:0)	DataInB(1:0)	QA(1:0)	QB(1:0)	AddressA(12:0)	AddressB(12:0)
4096 × 4	DataInA(3:0)	DataInB(3:0)	QA(3:0)	QB(3:0)	AddressA(11:0)	AddressB(11:0)
2049 × 9	DataInA(8:0)	DataInB(8:0)	QA(8:0)	QB(8:0)	AddressA(10:0)	AddressB(10:0)
1024 × 18	DataInA(17:0)	DataInB(17:0)	QA(17:0)	QB(17:0)	AddressA(9:0)	AddressB(9:0)

Table 4.6 shows the various attributes available for True Dual-Port Memory, RAM_DP_TRUE. You can select some of these attributes through the IP Catalog interface.

Table 4.6. True Dual-Port RAM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Port A Address Depth	Port A address depth of the read and write port	2–<Max that can fit in the device>	512
Port A Data Width	Port A data word width of the read and write port	1–512	18
Port B Address Depth	Port B address depth of the read and write port	2–<Max that can fit in the device>	512
Port B Data Width	Port B data word width of the read and write port	1–512	18
Port A Enable Output Register	The Port A Data Out port (QA) can be registered or not using this selection	True, False	True
Port B Enable Output Register	The Port B Data Out port (QB) can be registered or not using this selection	True, False	True
Enable Byte Enable A	Allows you to select Byte Enable options.	True, False	False
Enable Byte Enable B	Allows you to select Byte Enable options.	True, False	False
Reset Assertion A	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Assertion B	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Deassertion A	Selection for the reset deassertion to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Deassertion B	Selection for the Reset deassertion to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize your memory to all 1s, 0s, or use a custom initialization by providing a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for RAM_DP_TRUE. The waveforms in Figure 4.7 and Figure 4.8 show the internal timing waveforms for the True Dual-Port RAM, RAM_DP_TRUE, without output registers and with output registers respectively.

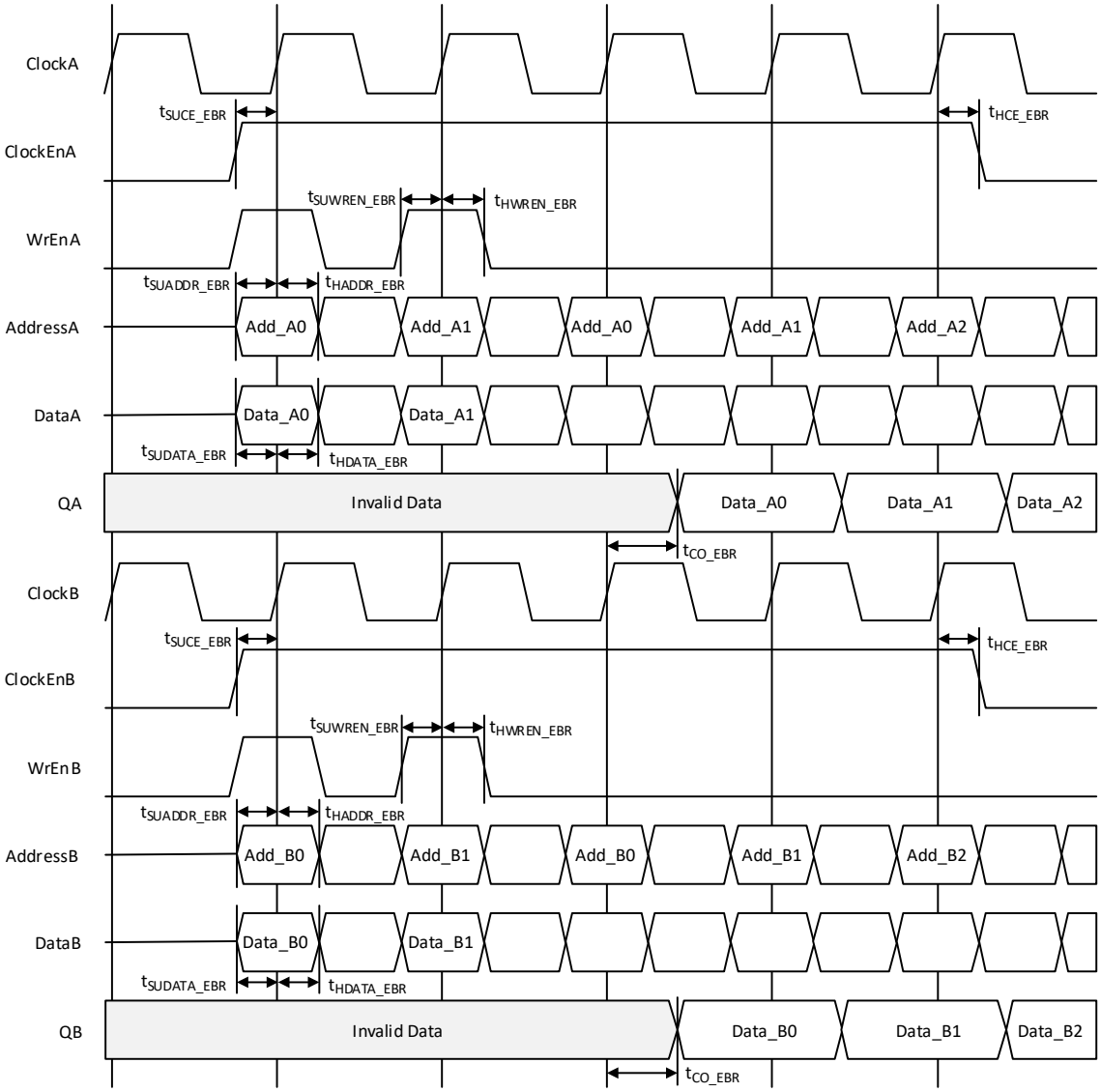

Figure 4.7. True Dual-Port RAM Timing Waveform – without Output Registers

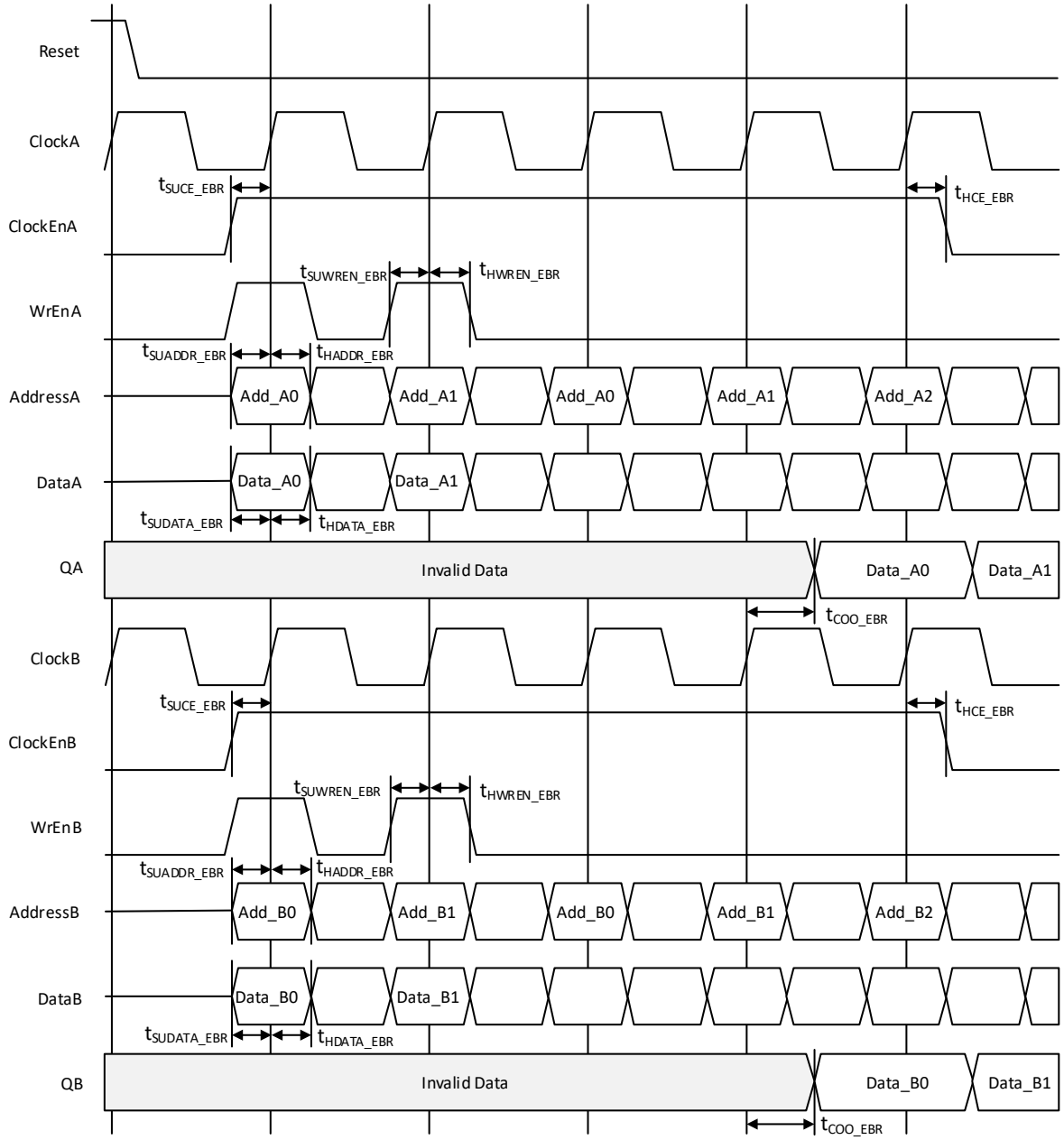

Figure 4.8. True Dual-Port RAM Timing Waveform – with Output Registers

4.4. Pseudo Dual-Port RAM (RAM_DP) – EBR-Based

FPGAs built on the Nexus platform support all the features of the Pseudo Dual-Port Memory Module, RAM_DP. The IP Catalog allows you to generate the Verilog-HDL or VHDL along with the EDIF netlist for the memory size as per the design requirement.

IP Catalog generates the memory module shown in Figure 4.9.

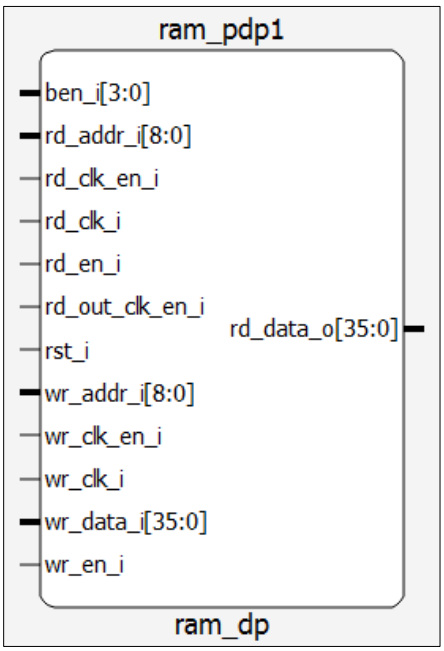

Figure 4.9. Pseudo Dual-Port Memory Module Generated by IP Catalog

Figure 4.10 provides the primitive that can be instantiated for the Pseudo Dual-Port RAM. The primitive name is PDPW16K, and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under the cae_library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 18 kb of memory. If the memory required is larger than 18 kb, then cascading can be used using the CS ports, CSW and CSR in this case.

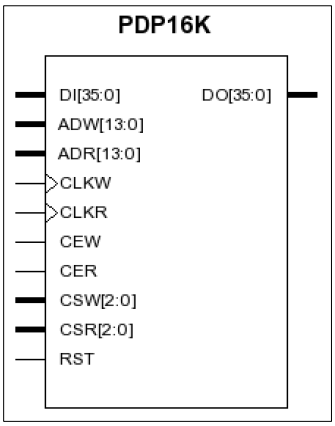

Figure 4.10. Pseudo Dual-Port RAM Primitive for Nexus Platform Devices

The various ports and their definitions for Pseudo Dual-Port memory are listed in Table 4.7. The table lists the corresponding ports for the module generated by the IP Catalog.

Table 4.7. EBR-Based Pseudo Dual-Port Memory Port Definitions

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
wr_clk_en_i	Input	1	Write Clock Enable
rd_en_i	Input	1	Read Enable
rd_clk_en_i	Input	1	Read Clock Enable
rd_out_clk_en_i	Input	1	Read Output Register Clock Enable
wr_en_i	Input	1	Write Enable
ben_i	Input	4	Byte Enable
wr_data_i	Input	Write Port Data Width	Write Data
wr_addr_i	Input	Write Port Address Width	Write Address
rd_addr_i	Input	Read Address Width	Read Address
rd_data_o	Output	Read Port Data Width	Read Data

Each EBR block consists of 18,432 bits of RAM. The address values w and x and data values y and z for each EBR block are listed in Table 4.8.

Table 4.8. Pseudo Dual-Port Memory Sizes for 18 kb Memory for Nexus Platform Devices

Dual-Port Memory Size	Input Data Write Port	Output Data Read Port	Address Write Port	Address Read Port
16384 × 1	Data	Q	WrAddress(13:0)	RdAddress(13:0)
8192 × 2	Data(1:0)	Q(1:0)	WrAddress(12:0)	RdAddress(12:0)
4096 × 4	Data(3:0)	Q(3:0)	WrAddress(11:0)	RdAddress(11:0)
2049 × 9	Data(8:0)	Q(8:0)	WrAddress(10:0)	RdAddress(10:0)
1024 × 18	Data(17:0)	Q(17:0)	WrAddress(9:0)	RdAddress(9:0)
512 × 36	Data(35:0)	Q(35:0)	WrAddress(8:0)	RdAddress(8:0)

Table 4.9 shows the various attributes available for the Pseudo Dual-Port Memory, RAM_DP. You can select some of these attributes through the IP Catalog interface.

Table 4.9. Pseudo Dual-Port RAM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Read Port Address Depth	Read port address depth	2–65536	512
Read Port Data Width	Read port data word width	1–256	36
Write Port Address Depth	Write port address depth	2–65536	512
Write Port Data Width	Write port data word width	1–256	36
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	True, False	True
Enable Output ClockEn	Clock Enable for the output clock. This option requires enabling Enable Output Register.	True, False	False
Enable Byte Enable[1]	Allows you to select Byte Enable options.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize your memory to all 1s, 0s, or use a custom initialization by providing a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for the custom initialization of RAM.	—	—

Configuration Tab Attributes	Description	Values	Default Value
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex
Enable ECC[1,2]	This option allows you to enable error correction codes. This option is not available for memories that are wider than 64 bits.	Ture, False	False

Notes:
1. ECC and Byte-Enable cannot be used together.
2. ECC is available only if WDATA_WIDTH = RDATA_WIDTH.

You have the option to enable the output registers for Pseudo Dual-Port RAM, RAM_DP. The waveforms in Figure 4.11 and Figure 4.12 show the internal timing waveforms for Pseudo Dual-Port RAM, RAM_DP, without output registers and with output registers respectively.

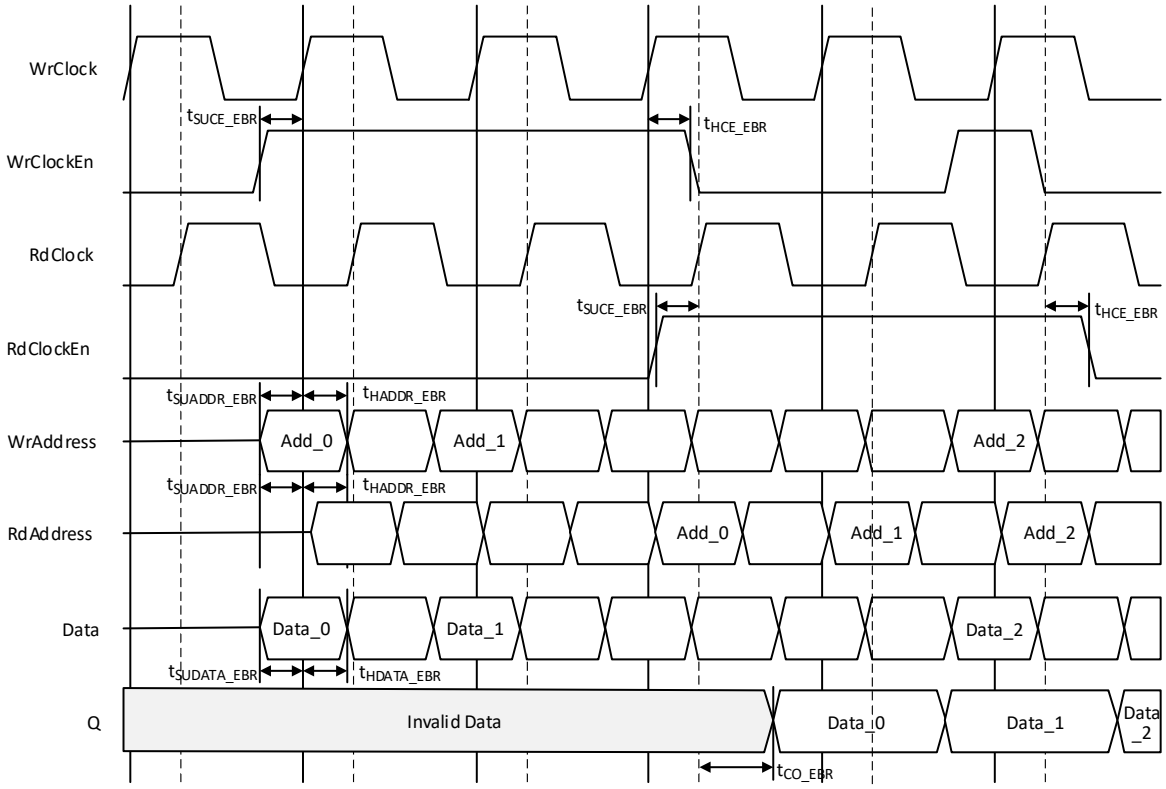

Figure 4.11. Pseudo Dual-Port RAM Timing Diagram – without Output Registers

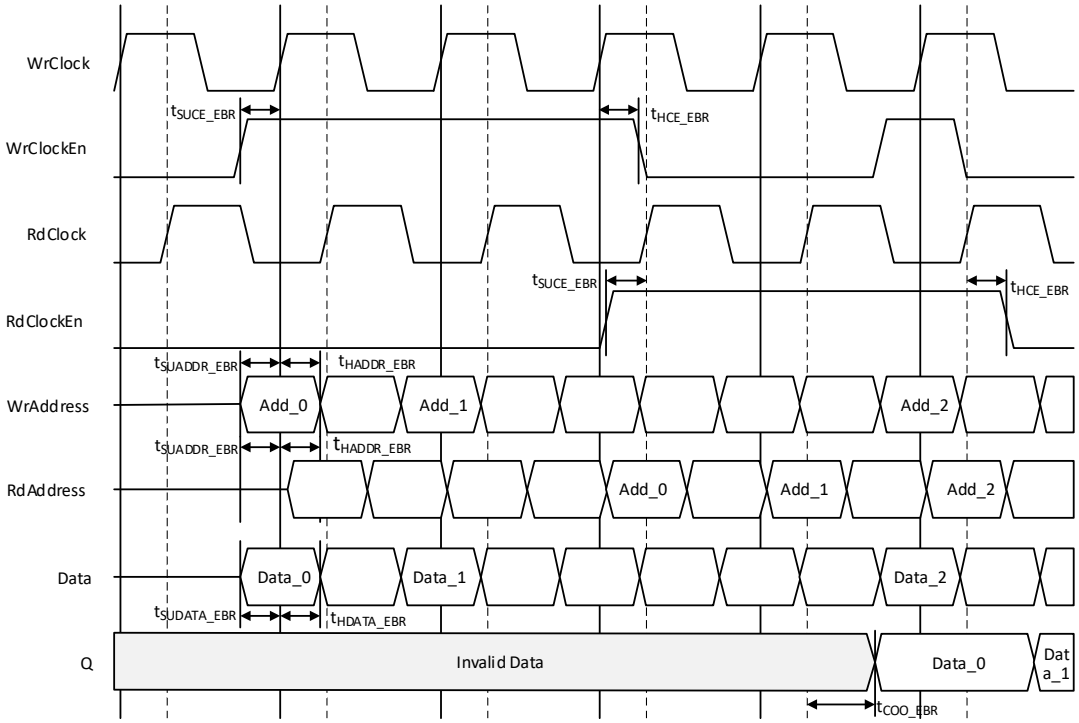

Figure 4.12. Pseudo Dual-Port RAM Timing Diagram – with Output Registers

4.5. Read-Only Memory (ROM) – EBR-Based

FPGAs built on the Nexus platform support all the features of the ROM Memory Module, or ROM. The IP Catalog allows you to generate the Verilog-HDL or VHDL along with the EDIF netlist for the memory size as per the design requirement. You are required to provide the ROM memory content in the form of an initialization file.

The IP Catalog generates the memory module shown in Figure 4.13.

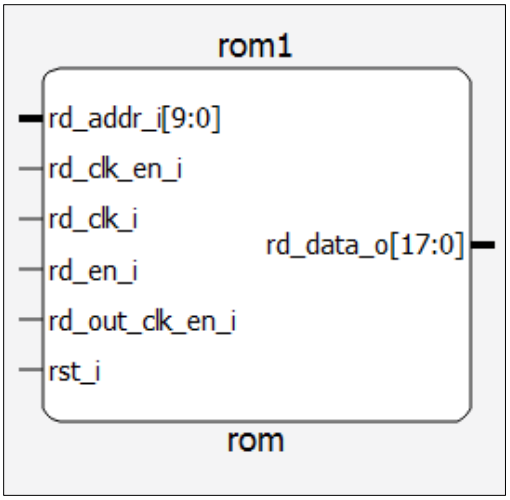

Figure 4.13. ROM – Read-Only Memory Module Generated by IP Catalog

The various ports and their definitions are listed in Table 4.10. The table lists the corresponding ports for the module generated by the IP Catalog and for the ROM primitive.

Table 4.10. EBR-Based ROM Port Definitions

Port Name	Direction	Width	Description
rd_clk_i	Input	1	Clock
rst_i	Input	1	Reset
rd_en_i	Input	1	Read Enable
rd_clk_en_i	Input	1	Input Clock Enable
rd_out_clk_en_i	Input	1	Output Clock Enable
rd_addr_i	Input	Address Width	Address Bus
rd_data_o	Input	Data Width	Data Output

When generating ROM using the IP Catalog, you must provide the initialization file to pre-initialize the contents of the ROM. These files are *.mem files, and they can be in binary or hex formats. The initialization files are discussed in detail in the Initializing Memory section of this document.

Each EBR block consists of 18,432 bits of RAM. The address value x and data value y for each EBR block for the devices are included in Table 4.11.

Table 4.11. ROM Memory Sizes for 16 kb Memory for Nexus Platform Devices

Dual-Port Memory Size	Output Data Read Port	Address Write Port
16384 × 1	Q	WrAddress(13:0)
8192 × 2	Q(1:0)	WrAddress(12:0)
4096 × 4	Q(3:0)	WrAddress(11:0)
2049 × 9	Q(8:0)	WrAddress(10:0)
1024 × 18	Q(17:0)	WrAddress(9:0)
512 × 36	Q(35:0)	WrAddress(8:0)

Table 4.12 shows the various attributes available for the Read-Only Memory (ROM). You can select some of these attributes through the IP Catalog interface.

Table 4.12. ROM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2–65536	512
Data Width	Data word width of the read and write port	1–512	36
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	True, False	True
Enable Output ClockEn	Enables the read output clock.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize the memory by providing a custom initialization through a memory file.	Memory file	Memory file
Memory File	When Memory File is selected, you can browse to the memory file for the custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for ROM. Figure 4.14 and Figure 4.15 show the internal timing waveforms for ROM without output registers and with output registers respectively.

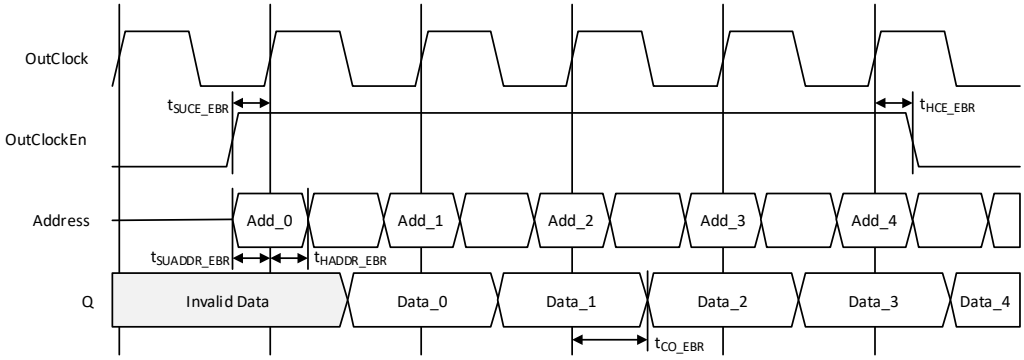

Figure 4.14. ROM Timing Waveform – without Output Registers

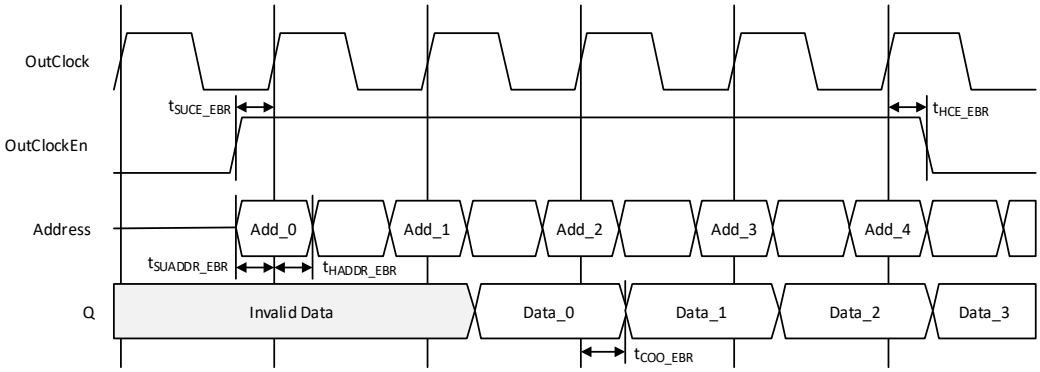

Figure 4.15. ROM Timing Waveform – with Output Registers

5. FIFO Memory

Nexus platform devices support two different types of FIFOs:

- Single-Clock FIFO (FIFO)
- Dual-Clock FIFO (FIFO_DC)

The EBR blocks in Nexus platform devices can be configured as LUT-based or EBR-based, as well as Single-Clock First In First Out Memory (FIFO) or Dual-Clock First In First Out Memory (FIFO_DC). IP Catalog allows you to generate the Verilog-HDL or VHDL netlist for various memory sizes depending on design requirements.

IP Catalog generated FIFO modules and their operation are discussed in detail in this section.

5.1. Single-Clock FIFO (FIFO) – EBR and LUT

Figure 5.1 shows the module that is generated by the IP Catalog for FIFO.

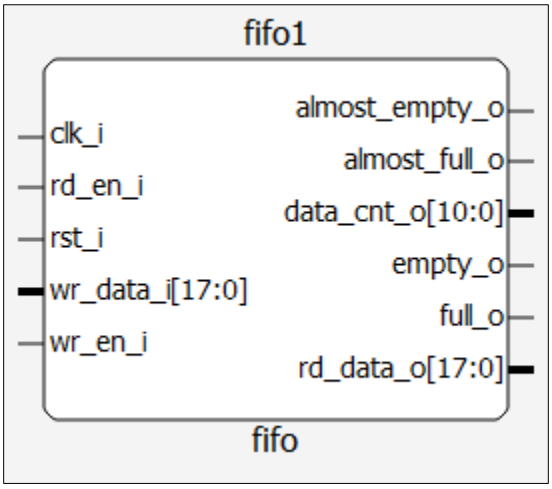

Figure 5.1. FIFO Module Generated by IP Catalog

The various ports and their definitions for the FIFO are listed in Table 5.1.

Table 5.1. Port Names and Definitions for FIFO

Port Name	Direction	Width	Description
clk_i	Input	1	Write Clock
rst_i	Input	1	Reset
wr_en_i	Input	1	Write Enable
rd_en_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
rd_data_o	Output	Data Width	Read Data
full_o	Output	1	Full Flag
empty_o	Output	1	Empty Flag
almost_full_o	Output	1	Almost Full Flag
almost_empty_o	Output	1	Almost Empty Flag
data_cnt_o	Output	Address Width	Data Counter Width based on Memory Address Width

Table 5.2. FIFO Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Implementation Type	EBR-based or LUT-based	EBR, LUT	EBR
Address Depth	Address depth of the read and write port Values are powers of 2.	2–<Max that can fit in the device>	1024
Data Width	Data word width of the read and write port	1–256	18
Enable Output Register	The Data Out port Q can be registered or not using this selection.	True, False	True
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	async
Enable FWFT	Enables First-Word-Fall-Through.	True, False	False
Enable Almost Empty Flag	Enables the generation of the Almost Empty flag	True, False	True
Almost Empty Assertion Type	This option allows you to select the type of threshold to be used for the Almost Empty flag. The Static threshold is set by constant parameter while the Dynamic threshold is set through the input ports. The Single threshold provides only the assertion level while the Dual threshold provides both assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Single
Almost Empty Threshold Assert	This option allows you to set the assertion level of the Almost Empty flag. This is applicable for the Static-Single or Static-Dual threshold mode.	1 to Address Depth – 1	1
Almost Empty Threshold Deassert	This option allows you to set the de-assertion level of the Almost Empty flag after it goes high. This is applicable only for the Static-Dual threshold mode.	Almost Empty Threshold Assert + 1 to Address Depth – 1	2
Enable Almost Full Flag	Enables the generation of the Almost Full flag.	True, False	True
Almost Full Assertion Type	This option allows you to select the type of threshold to be used for the Almost Full flag. The Static threshold is set by constant parameters while the Dynamic threshold is set through the input ports. The Single threshold provides only the assertion level while the Dual threshold provides both the assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Single
Almost Full Threshold Assert	This option allows you to set the assertion level of the Almost Full flag. This is applicable for the Static-Single or Static-Dual threshold mode.	2 to Address Depth – 1	1023
Almost Full Threshold Deassert	This option allows you to set the de-assertion level of the Almost Full flag after it goes high. This option is applicable only for the Static-Dual threshold mode.	1 to Almost Full Threshold Assert – 1	1022
Enable Data Count	This option allows you to enable the generation of write data count.	True, False	False
Use HI-SPEED Implementation	When using an Area-Optimized (HW) Controller Implementation, this option can be checked for an aggressive FIFO routing resulting in significantly faster f_{max}. However, doing so can consume a large amount of EBR resources.	True, False	False
Controller Implementation[1]	Chooses how the FIFO controller is implemented. If you use LIFCL or LFD2NX devices, you can opt for an area-optimized or feature-rich option.	Area-Optimized (HW), Feature-Rich (LUT)	Area-Optimized (HW)

Note:

1. For more information on controller implementation type combinations, refer to Section 2.8. First in First Out Single Clock (FIFO) of Memory Modules - Lattice Radiant Software User Guide (FPGA-IPUG-02033).

The non-pipelined FIFO or the FIFO without output registers is discussed first. Figure 5.2 shows the operation of the FIFO when it is empty and the data begins to be written into it.

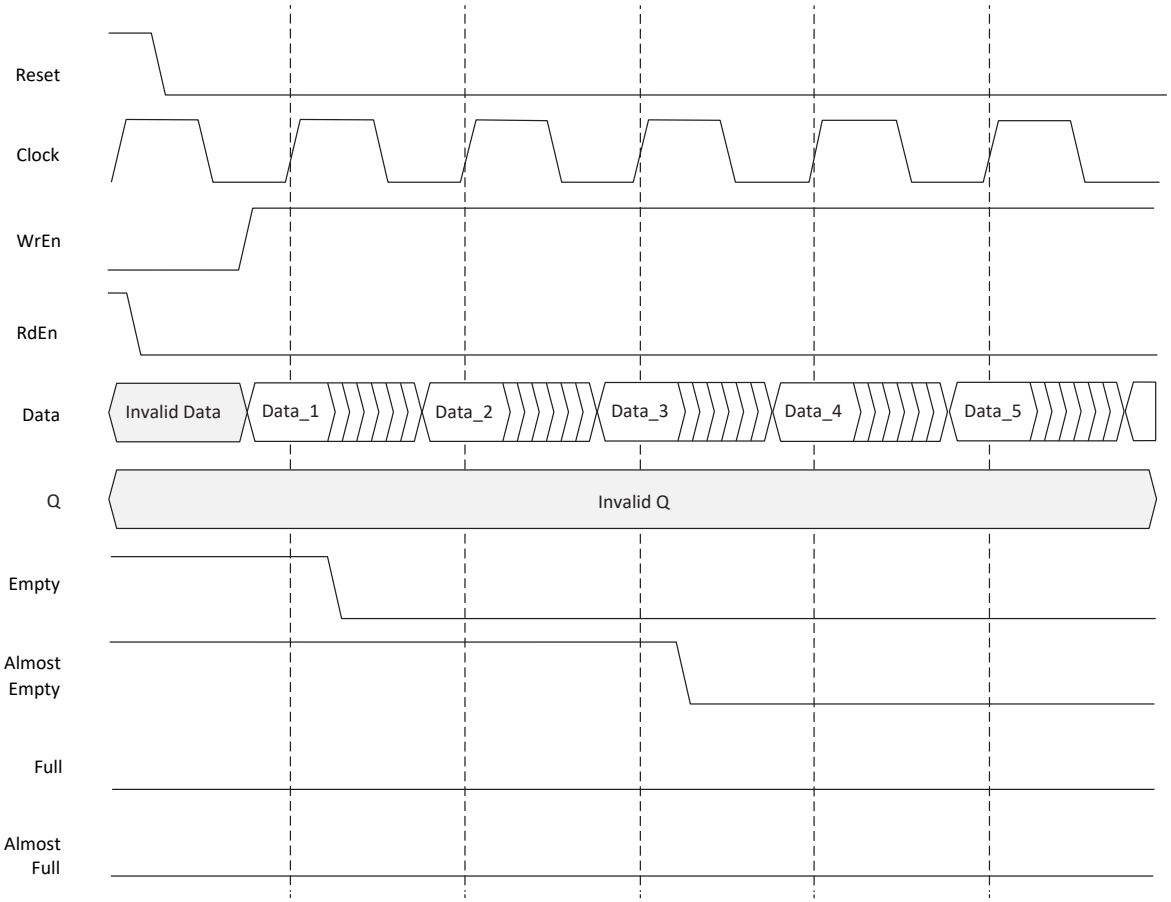

Figure 5.2. FIFO without Output Registers, Start of Data Write Cycle

The WrEn signal must be high to start writing into the FIFO. The Empty and Almost Empty flags are high to begin, and Full and Almost Full are low.

When the first data is written into the FIFO, the Empty flag de-asserts or goes low since the FIFO is no longer empty. In this figure, it is assumed that the Almost Empty flag setting is three, address location three. As such, the Almost Empty flag is de-asserted when the third address location is filled.

Assume that you continue to write into the FIFO to fill it. When the FIFO is filled, the Almost Full and Full flags are asserted. Figure 5.3 shows the behavior of these flags. In this figure, it is assumed that the FIFO depth is N.

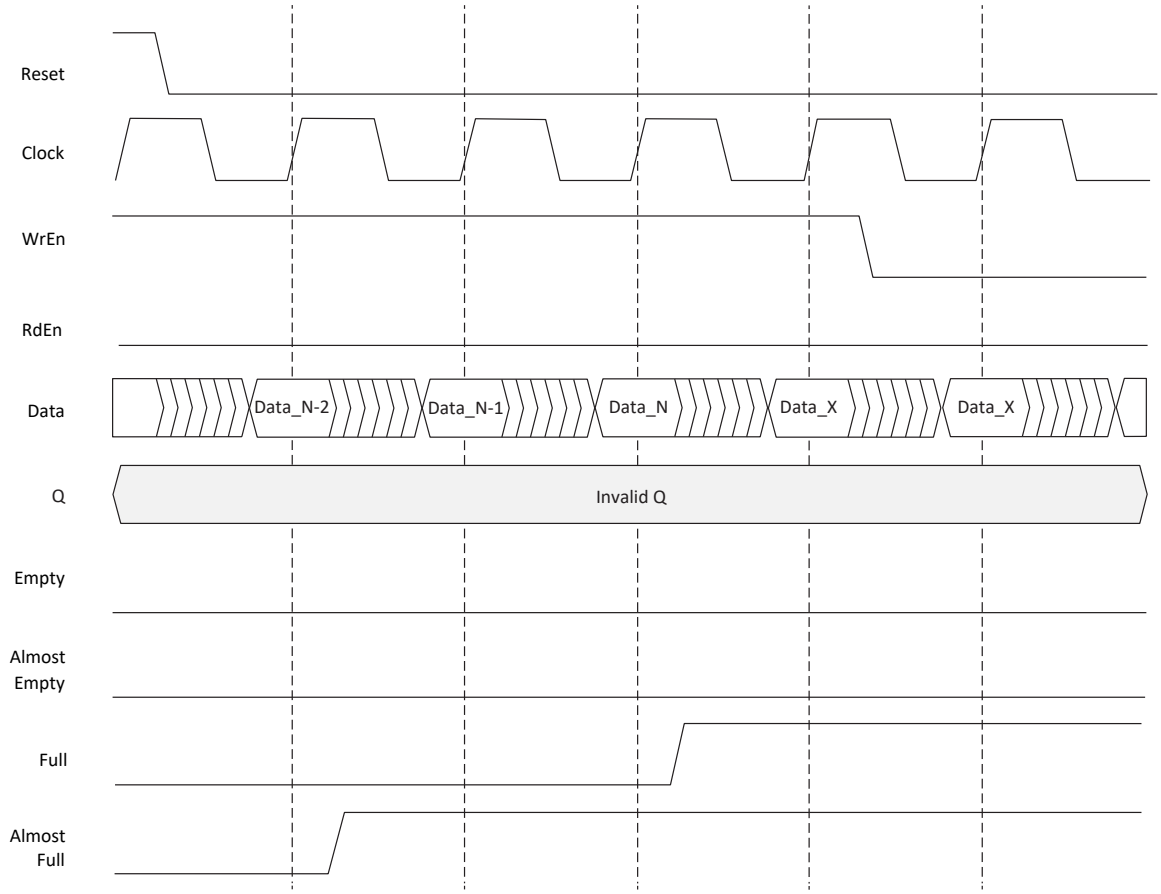

Figure 5.3. FIFO without Output Registers, End of Data Write Cycle

In Figure 5.3, the almost full flag is two locations before the FIFO is filled. The almost full flag is asserted when the N-2 location is written, and the full flag is asserted when the last word is written into the FIFO.

Data_X data inputs are not written since the FIFO is full, that is, the full flag is high.

Examine the waveforms when the contents of the FIFO are read out. Figure 5.4 shows the start of the read cycle. RdEn goes high, and the data read starts. The full and almost full flags are de-asserted.

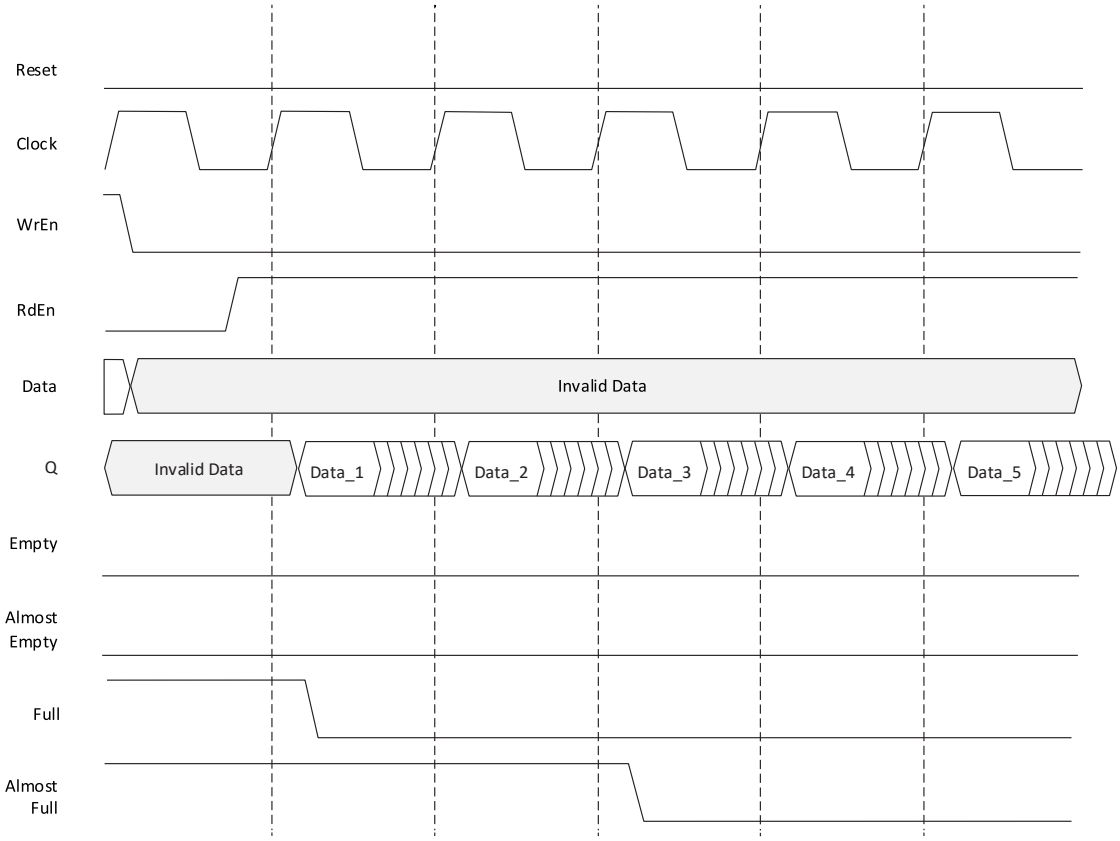

Figure 5.4. FIFO without Output Registers, Start of Data Read Cycle

Similarly, as the data is read out and FIFO is emptied, the Almost Empty and Empty flags are asserted (Figure 5.5).

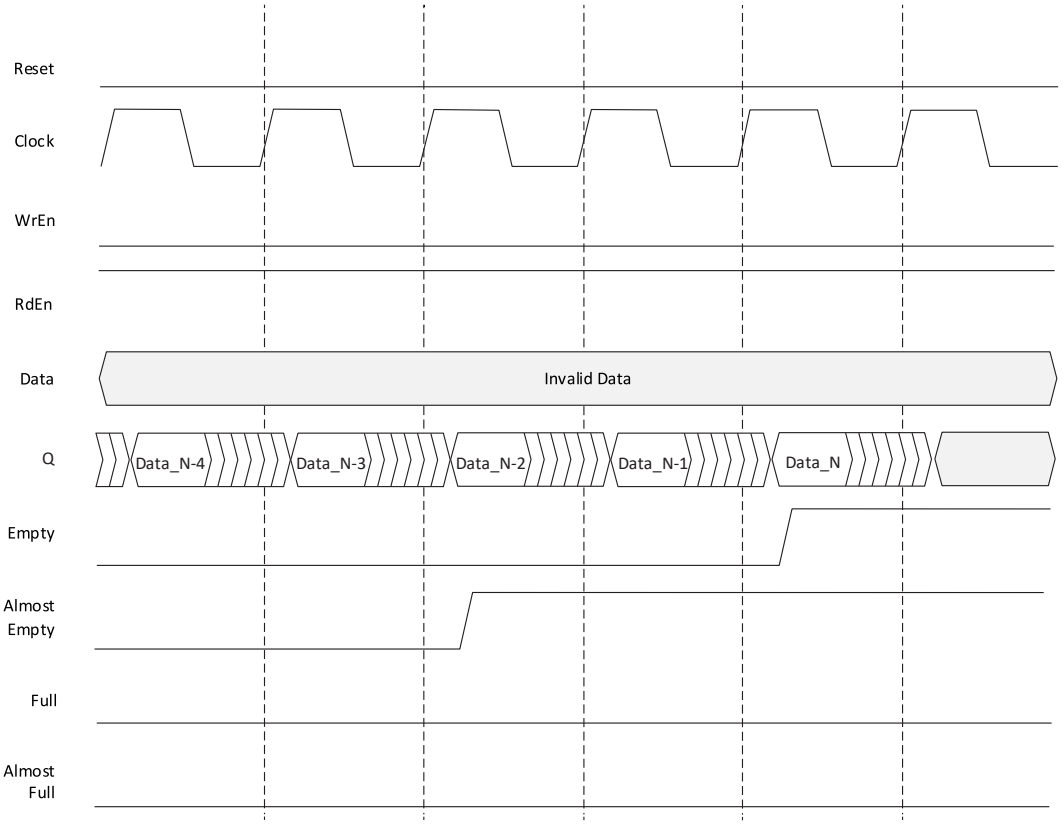

Figure 5.5. FIFO without Output Registers, End of Data Read Cycle

Figure 5.1 to Figure 5.4 show the behavior of non-pipelined FIFO or FIFO without output registers. When the registers are pipelined, the output data is delayed by one clock cycle. There is also an option for output registers to be enabled by the RdEn signal.

Figure 5.6 to Figure 5.9 show similar waveforms for the FIFO with an output register and an output register enabled with RdEn. Note that flags are asserted and de-asserted with similar timing to the FIFO without output registers.

Only the data out Q is delayed by one clock cycle.

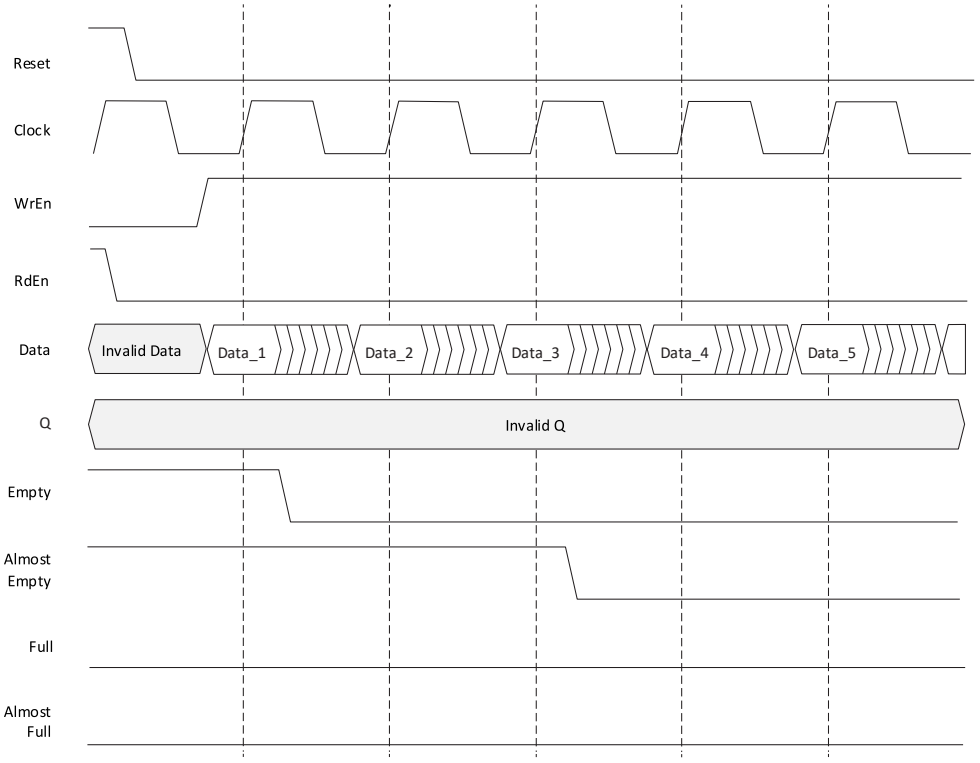

Figure 5.6. FIFO with Output Registers, Start of Data Write Cycle

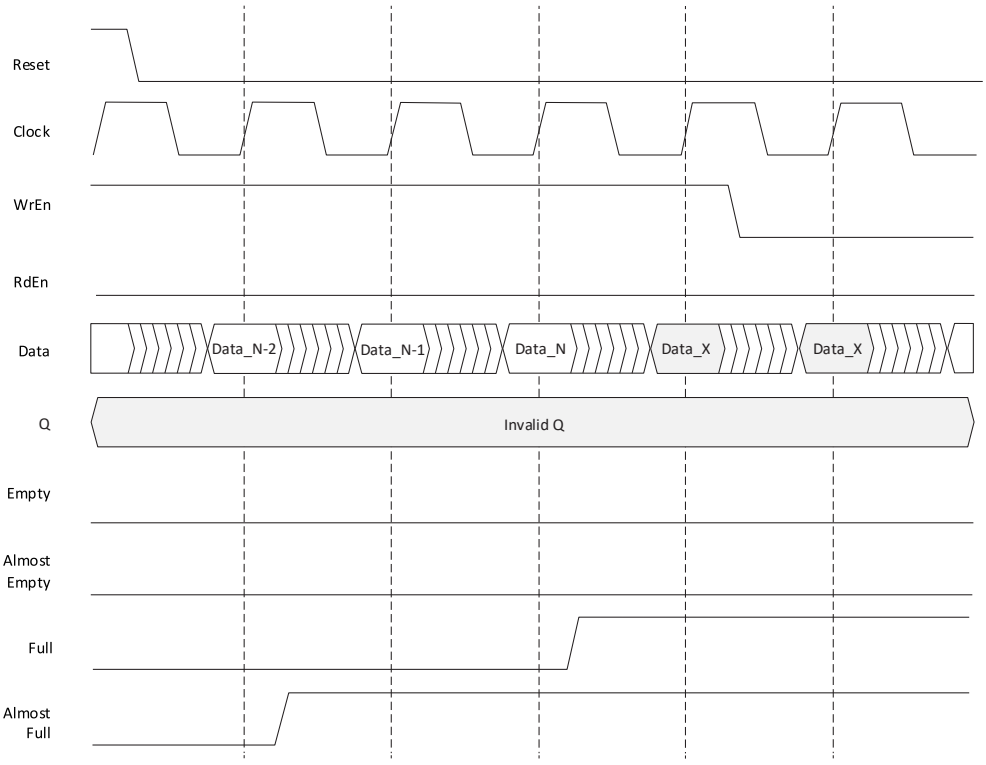

Figure 5.7. FIFO with Output Registers, End of Data Write Cycle

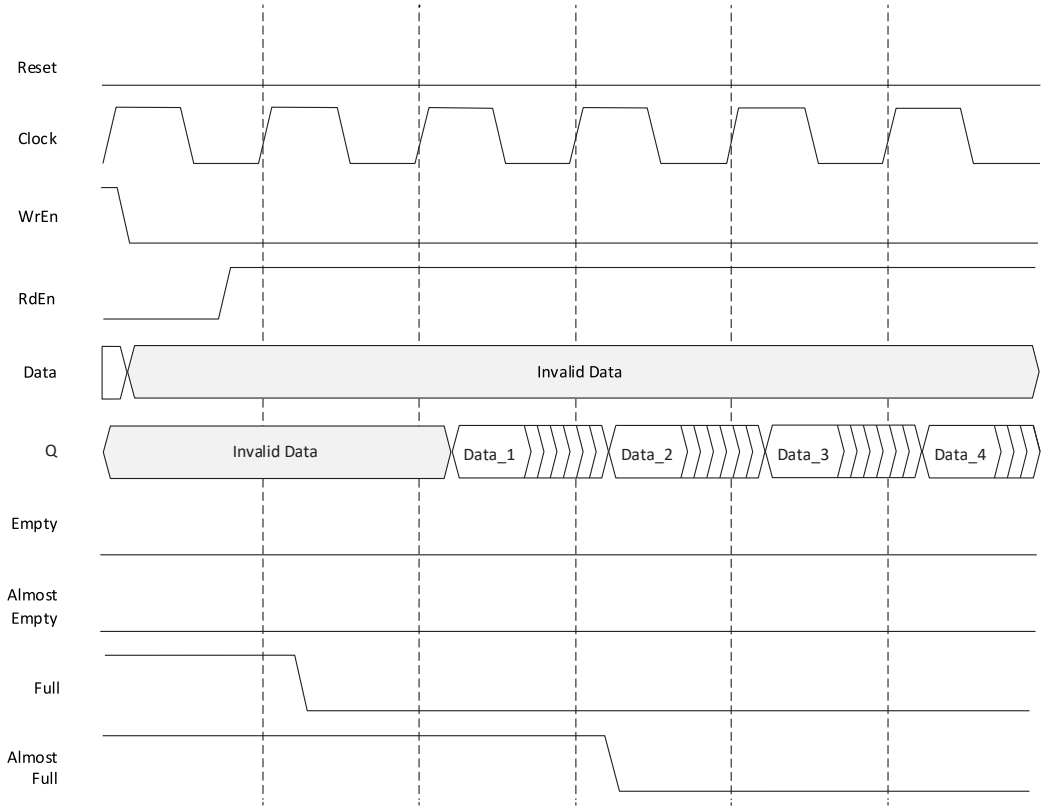

Figure 5.8. FIFO with Output Registers, Start of Data Read Cycle

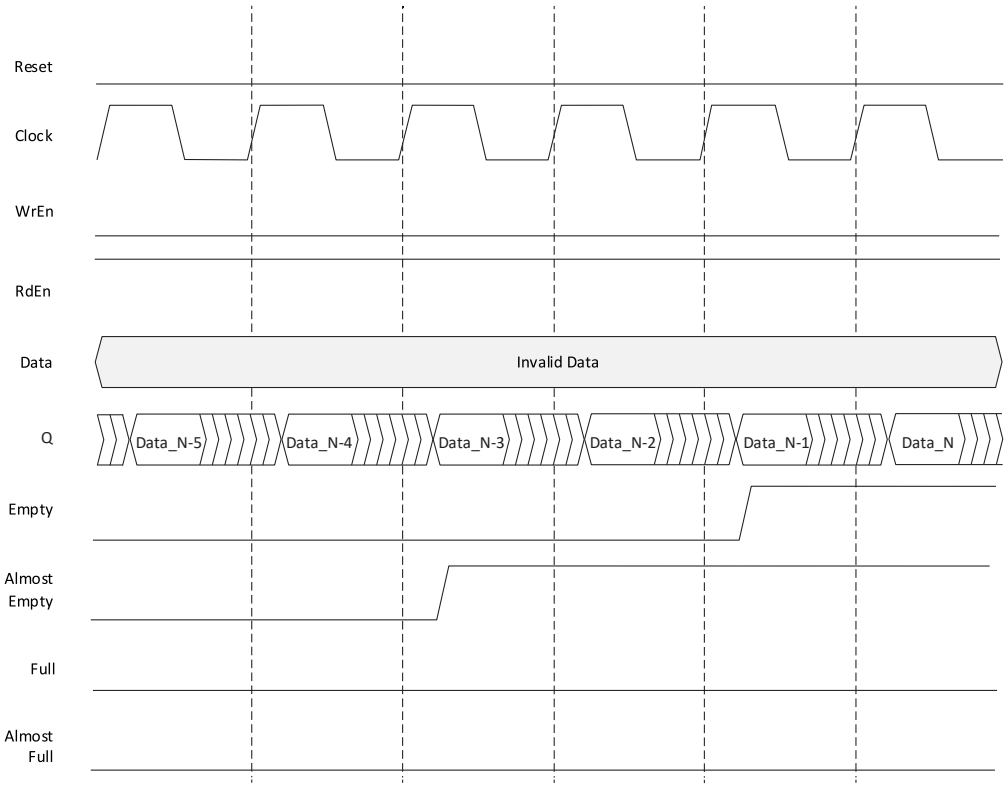

Figure 5.9. FIFO with Output Registers, End of Data Read Cycle

If the option enable output register with RdEn is selected, it still delays the data out by one clock cycle, as compared to the non-pipelined FIFO. The RdEn should also be high during that clock cycle. Otherwise, the data takes an extra clock cycle when the RdEn signal goes true (Figure 5.10).

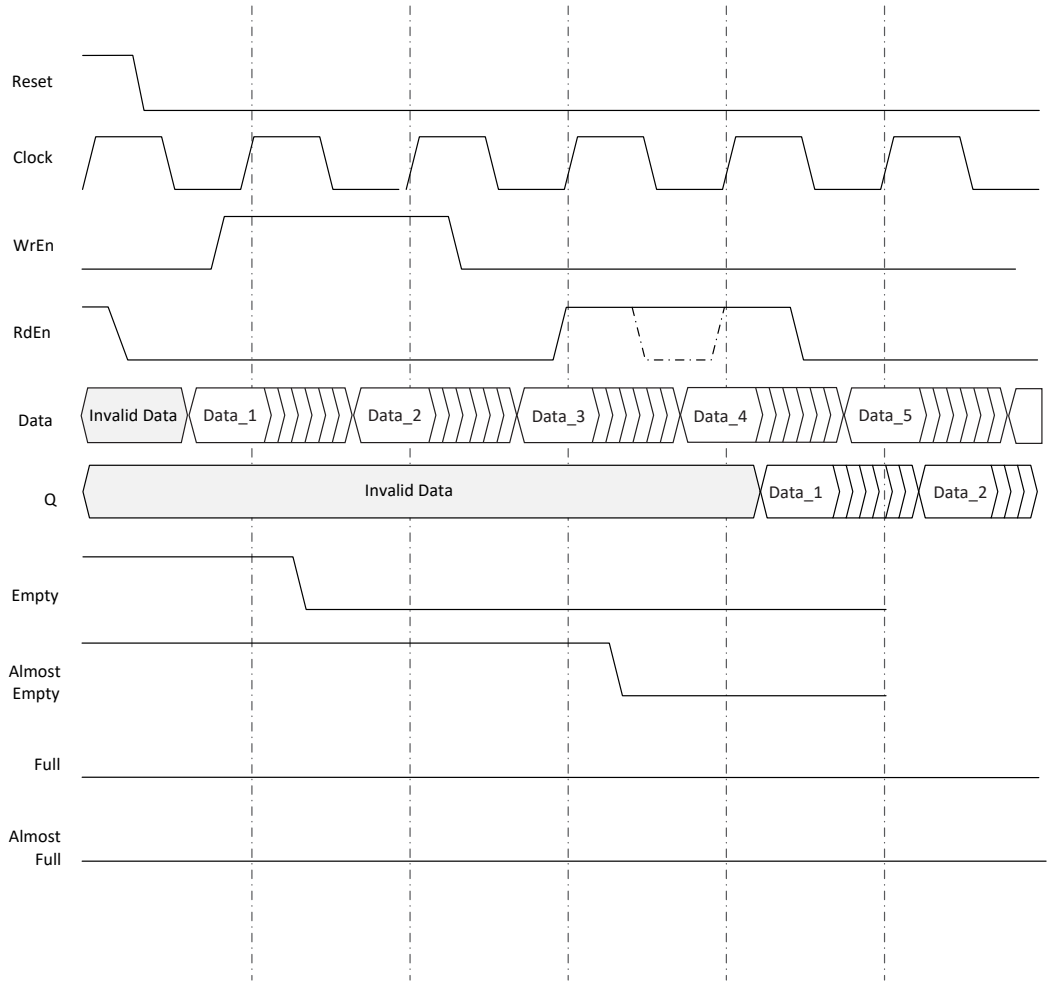

Figure 5.10. FIFO with Output Registers and RdEn on Output Registers

5.2. Dual-Clock First In First Out (FIFO_DC) – EBR-Based or LUT-Based

Figure 5.11 shows the module that is generated by the IP Catalog for FIFO.

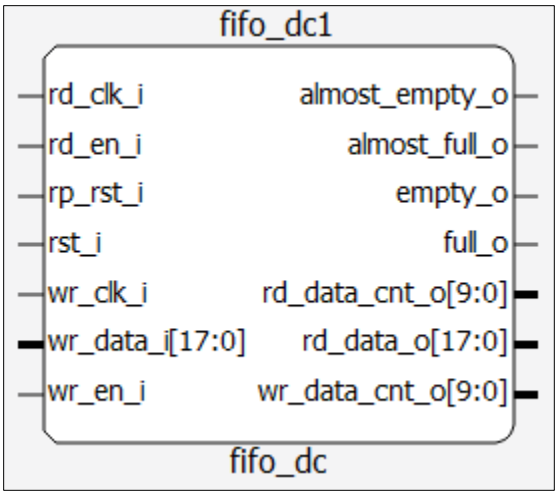

Figure 5.11. FIFO_DC Module Generated by IP Catalog

The various ports and their definitions for the FIFO_DC are listed in Table 5.3. The software attributes are listed in Table 5.4.

Table 5.3. Port Names and Definitions for FIFO_DC

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
rp_rst_i	Input	1	Read Pointer Reset
wr_en_i	Input	1	Write Enable
rd_en_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
rd_data_o	Output	Data Width	Read Data
full_o	Output	1	Full Flag
empty_o	Output	1	Empty Flag
almost_full_o	Output	1	Almost Full Flag
almost_empty_o	Output	1	Almost Empty Flag
wr_data_cnt_o	Output	Address Width	Write Data Counter
rd_data_cnt_o	Output	Address Width	Read Data Counter

Table 5.4. FIFO_DC Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Implementation Type	EBR-based or LUT-based	EBR, LUT	EBR
Write Address Depth	Address depth of the write port Values are powers of 2.	2–<Max that can fit in the device>	512
Write Data Width	Data word width of the write port	1–256	18
Read Data Width	Data word width of the read port	1–256	18
Read Address Depth	Address depth of the read port Note: If Read Address Depth is not equal to Write Address Depth, the valid values are powers of two such that the ratio between Write and Read data widths are also powers of 2.	2–<Max that can fit in the device>	512
Enable Output Register	Data Out port, rd_data_o, can be registered or not using this selection.	True, False	True
Reset Mode	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	async
Enable Almost Empty Flag	Enables the generation of the Almost Empty flag.	True, False	True
Almost Empty Assertion Type	This option allows you to select the type of threshold to be used for the Almost Empty flag. The Static threshold is set by constant parameters while the Dynamic threshold is set through the input ports. The Single threshold provides only the assertion level while the Dual threshold provides both the assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Single
Almost Empty Threshold Assert	This option allows you to set the assertion level of the Almost Empty flag. This is applicable for the Static-Single or Static-Dual threshold mode.	1 to Address Depth – 1	1
Almost Empty Threshold Deassert	This option allows you to set the de-assertion level of the Almost Empty flag after it goes high. This is applicable only for the Static-Dual threshold mode.	Almost Empty Threshold Assert + 1 to Address Depth – 1	2
Enable Almost Full Flag	Enables the generation of the Almost Full flag.	True, False	True
Almost Full Assertion Type	This option allows you to select the type of threshold to be used for the Almost Full flag. Static threshold is set by constant parameters while the Dynamic threshold is set through the input ports. The Single threshold provides only the assertion level while the Dual threshold provides both the assertion and de-assertion level.	Static-Single, Static-Dual, Dynamic-Single, Dynamic-Dual	Static-Single
Almost Full Threshold Assert	This option allows you to set the assertion level of the Almost Full flag. This is applicable for the Static-Single or Static-Dual threshold mode.	2 to Address Depth – 1	511
Almost Full Threshold Deassert	This option allows you to set the de-assertion level of the Almost Full flag after it goes high. This is applicable only for the Static-Dual threshold mode.	1 to Almost Full Threshold Assert – 1	510
Enable Data Count (Write)	This option allows you to enable the generation of the write data count.	True, False	False
Enable Data Count (Read)	This option allows you to enable generation of the read data count.	True, False	False
Enable FWFT	Enables First-Word-Fall-Through.	True, False	False

Configuration Tab Attributes	Description	Values	Default Value
Use HI-SPEED Implementation	When using an Area-Optimized (HW) Controller Implementation, this option can be checked for an aggressive FIFO routing, resulting in a significantly faster f_{max}. However, doing so can consume a large amount of EBR resources.	True, False	False
Controller Implementation[1]	Chooses how the FIFO controller is implemented. If you use LIFCL or LFD2NX devices, you can opt for an area-optimized or feature-rich option.	Area-Optimized (HW), Feature-Rich (LUT)	Area-Optimized (HW)

Note:

1. For more information on controller implementation type combinations, refer to section 2.9. First in First Out Dual-Clock (FIFO_DC) of Memory Modules - Lattice Radiant Software User Guide (FPGA-IPUG-02033).

5.2.1. FIFO_DC Flags

As a hardware FIFO, FIFO_DC avoids latency to the flags during assertion or de-assertion, which distinguishes it from devices with emulated FIFO.

The waveforms for FIFO_DC without output registers are shown. Figure 5.12 shows the operation of the FIFO_DC when it is empty and the data begins to be written into it.

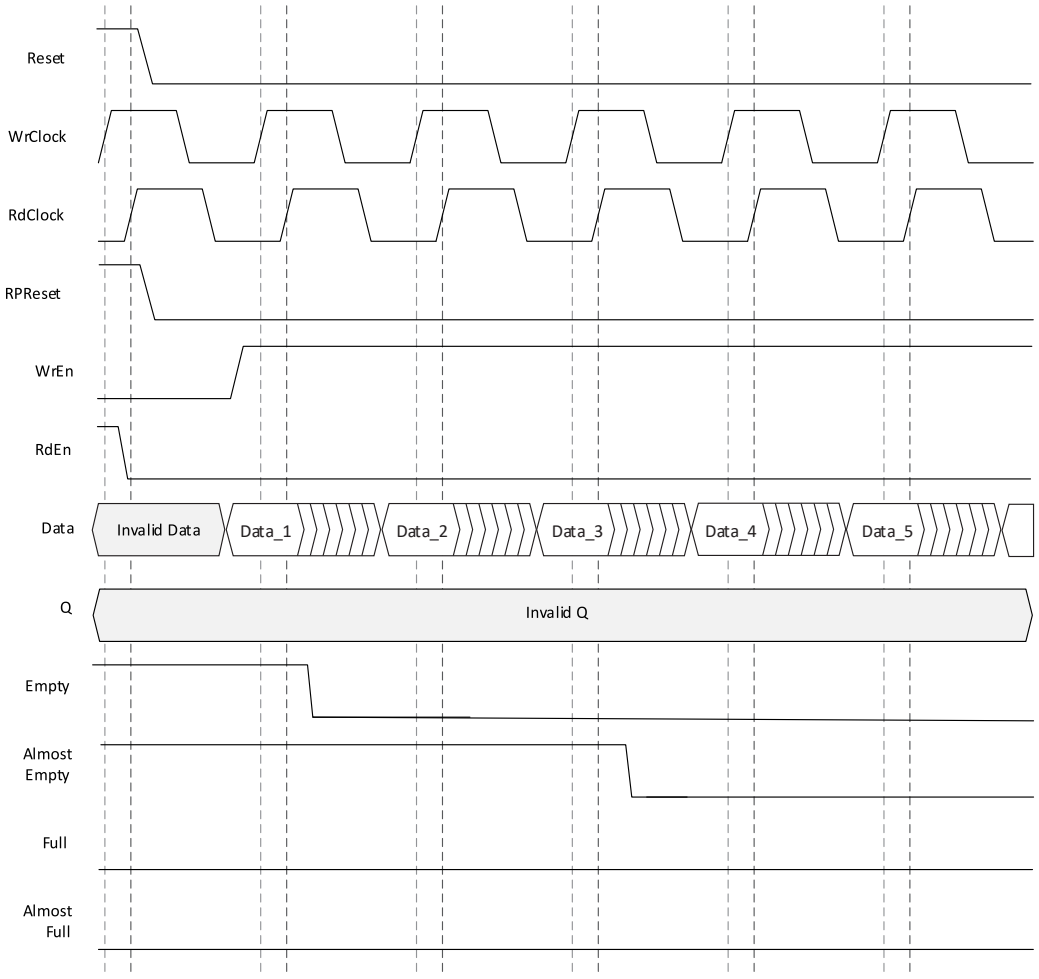

Figure 5.12. FIFO_DC without Output Registers, Start of Data Write Cycle

The WrEn signal must be high to start writing into the FIFO_DC. The Empty and Almost Empty flags are high to begin, and Full and Almost Full are low.

When the first data is written into the FIFO_DC, the Empty flag de-asserts or goes low, as the FIFO_DC is no longer empty. In this figure, it is assumed that the Almost Empty flag setting is three, address location three. The Almost Empty flag is de-asserted when the third address location is filled.

Assume that you continue to write into FIFO_DC to fill it. When the FIFO_DC is filled, the Almost Full and Full flags are asserted. Figure 5.13 shows the behavior of these flags. In this figure, it is assumed that the FIFO_DC depth is N.

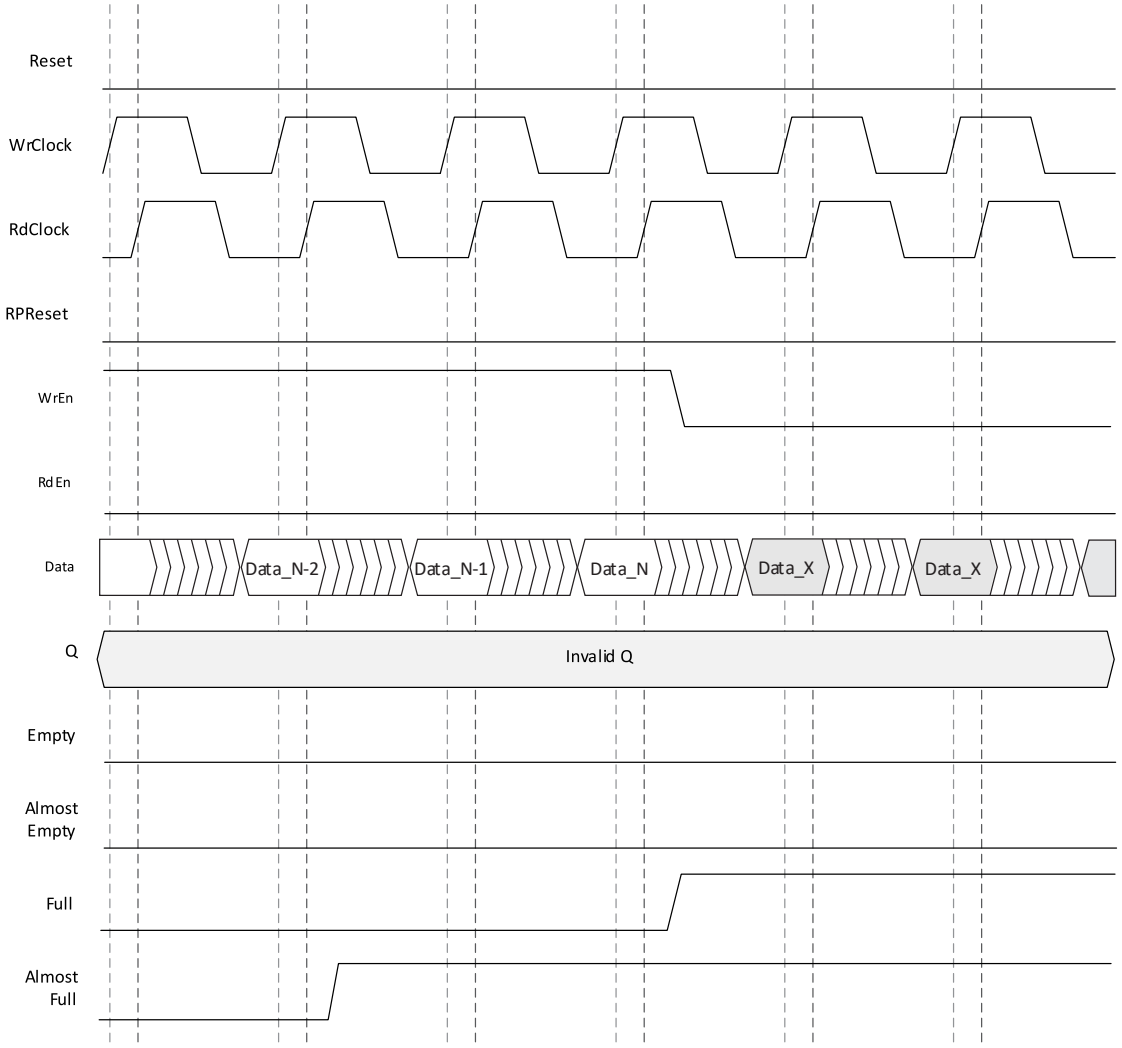

Figure 5.13. FIFO_DC without Output Registers, End of Data Write Cycle

In Figure 5.13, the Almost Full flag is two locations before the FIFO_DC is filled. The Almost Full flag is asserted when the N-2 location is written, and the Full flag is asserted when the last word is written into the FIFO_DC.

Data_X data inputs are not written since the FIFO_DC is full, that is, the full flag is high.

Note that the assertion of these flags is immediate, and there is no latency when they go true.

Examine the waveforms when the contents of the FIFO_DC are read out. Figure 5.14 shows the start of the read cycle. RdEn goes high, and the data read starts. The full and almost full flags are de-asserted as shown in Figure 5.14.

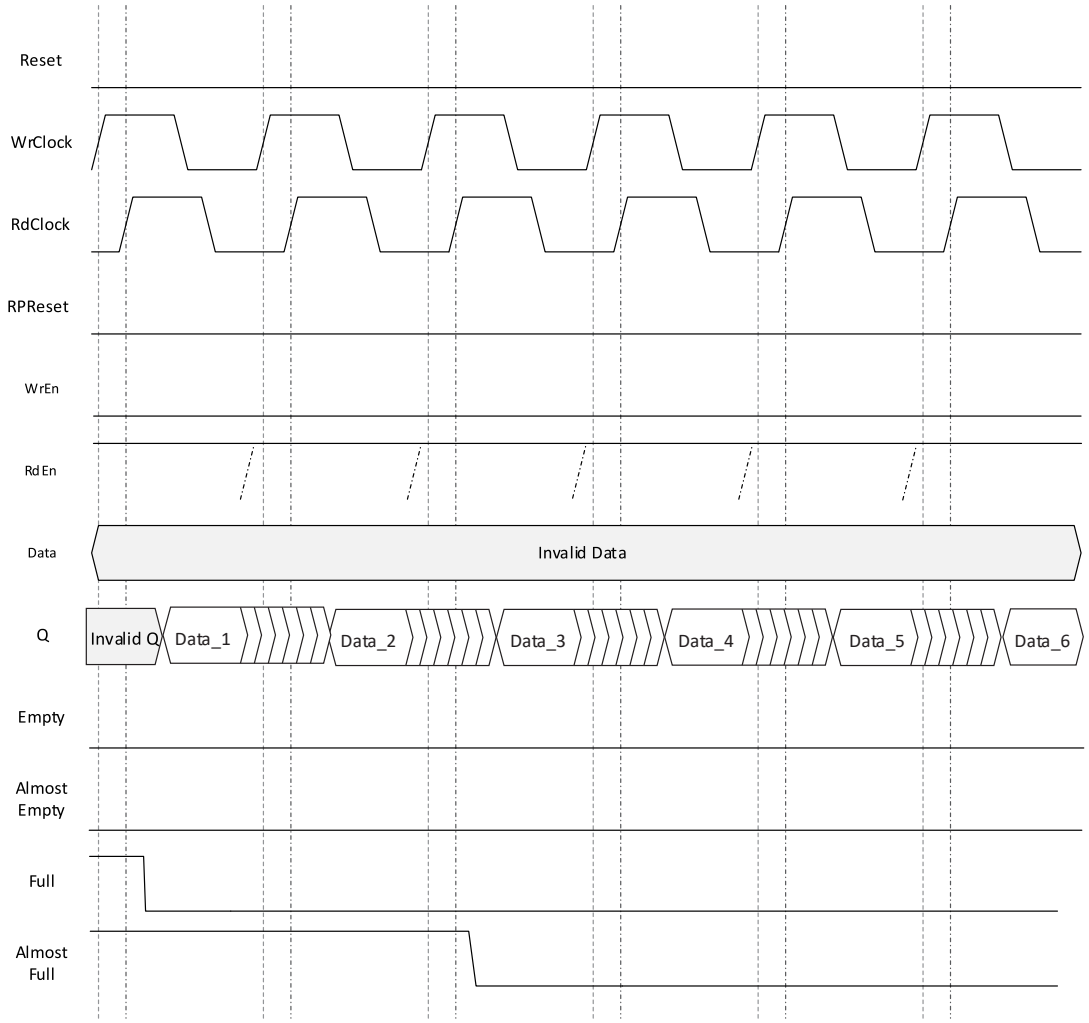

Figure 5.14. FIFO_DC without Output Registers, Start of Data Read Cycle

Similarly, as the data is read out and FIFO_DC is emptied, the Almost Empty and Empty flags are asserted (Figure 5.15).

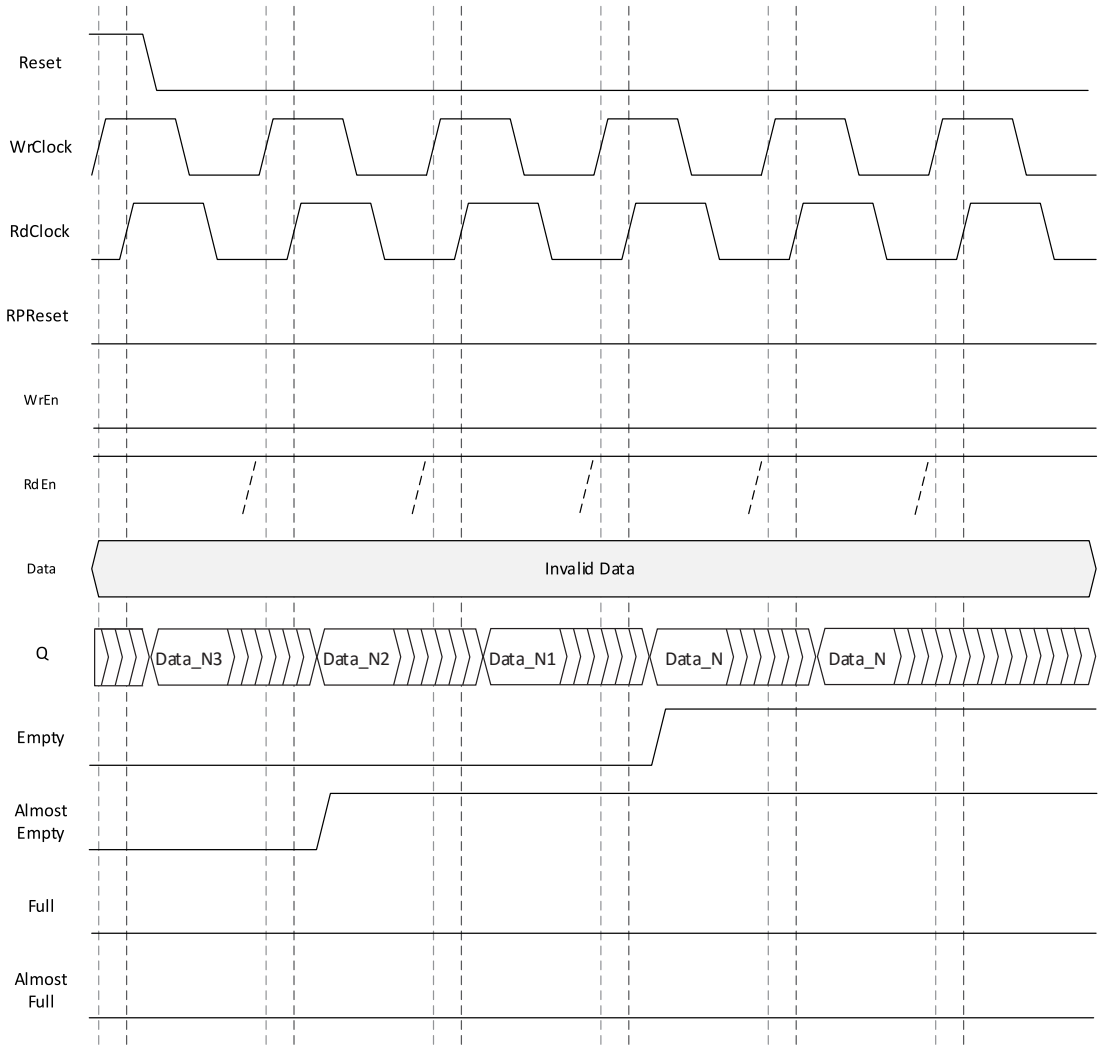

Figure 5.15. FIFO_DC without Output Registers, Start of Data Read Cycle

Figure 5.12 to Figure 5.15 show the behavior of the non-pipelined FIFO_DC or FIFO_DC without output registers. When you pipeline the registers, the output data is delayed by one clock cycle. There is an extra option for output registers to be enabled by the RdEn signal.

Figure 5.16 to Figure 5.19 show similar waveforms for the FIFO_DC with and without the output register enabled with RdEn. Note that flags are asserted and de-asserted with timing similar to the FIFO_DC without output registers. However, only the data output Q is delayed by one clock cycle.

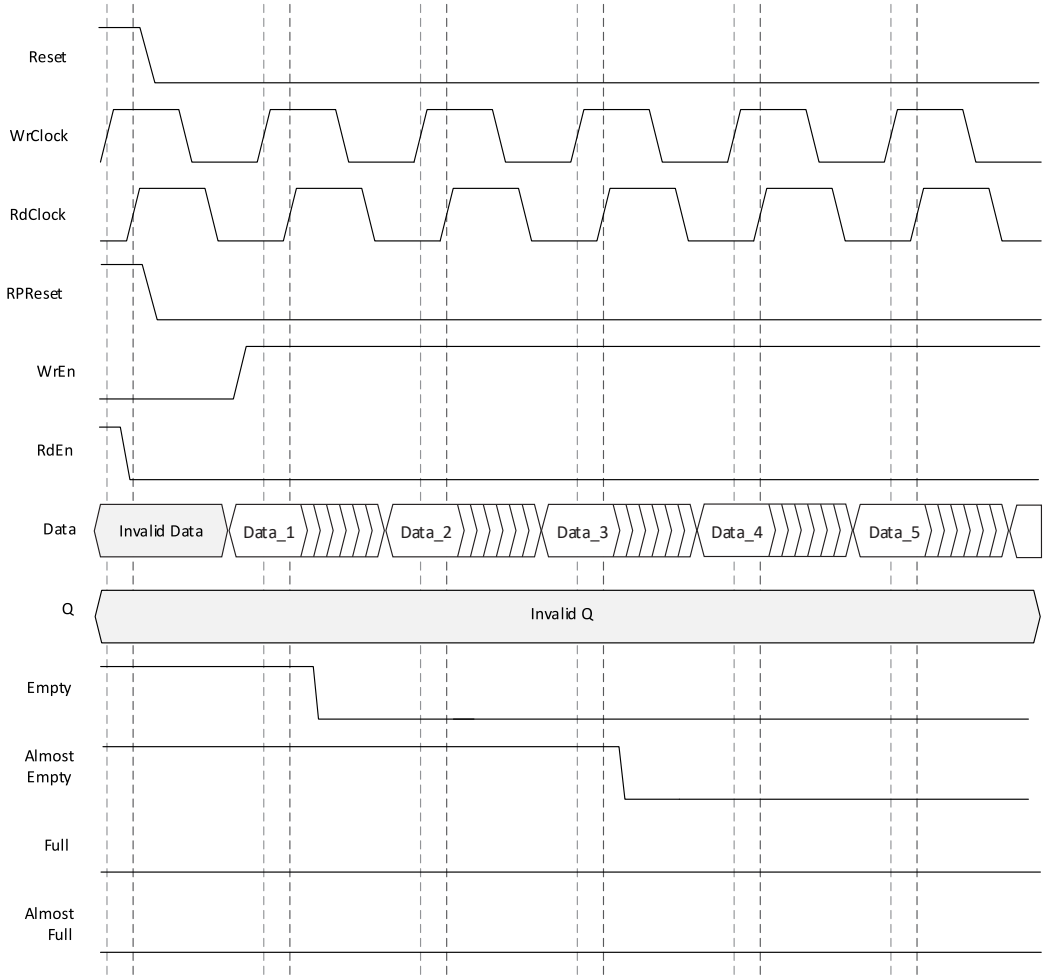

Figure 5.16. FIFO_DC with Output Registers, Start of Data Write Cycle

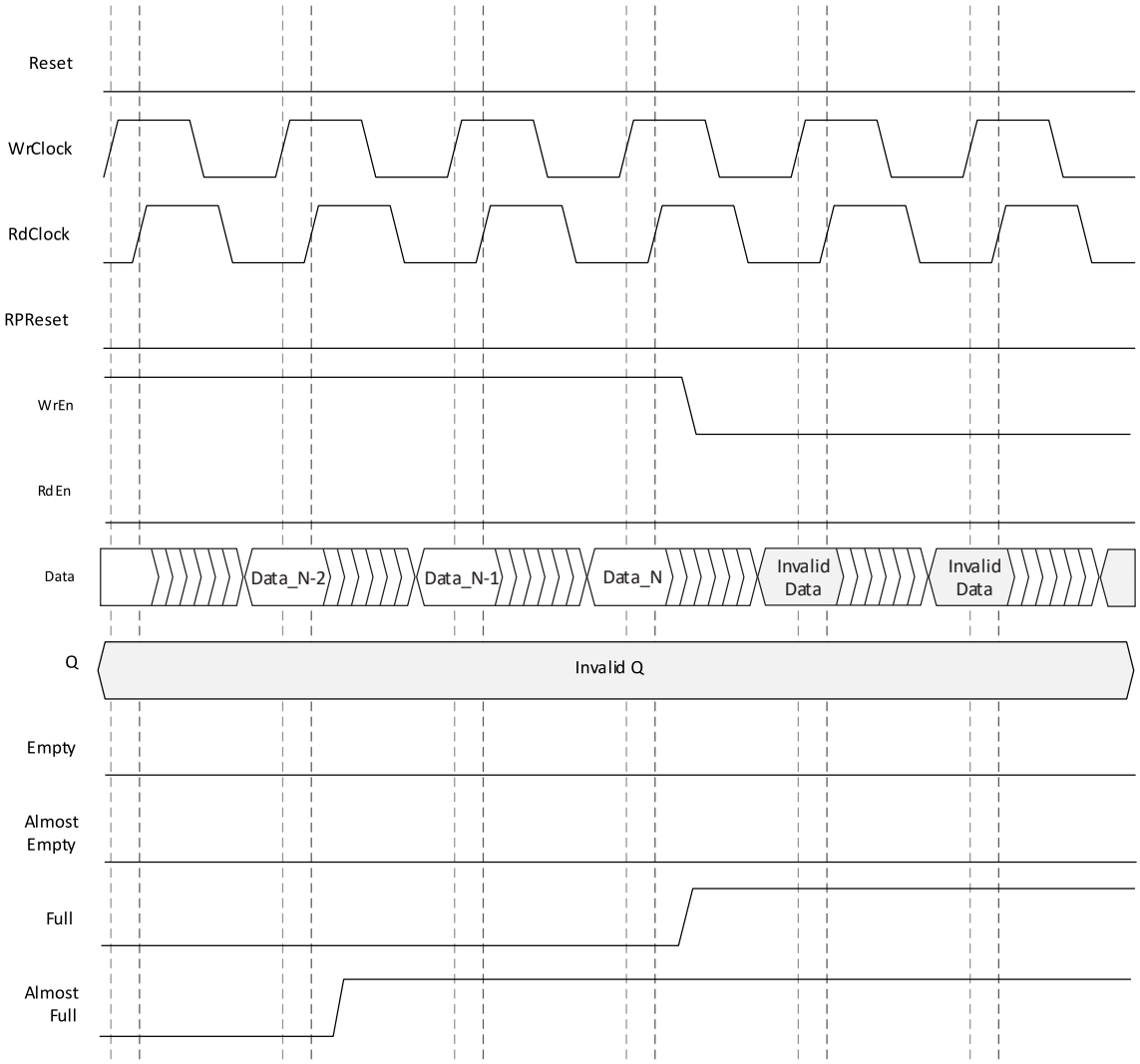

Figure 5.17. FIFO_DC with Output Registers, End of Data Write Cycle

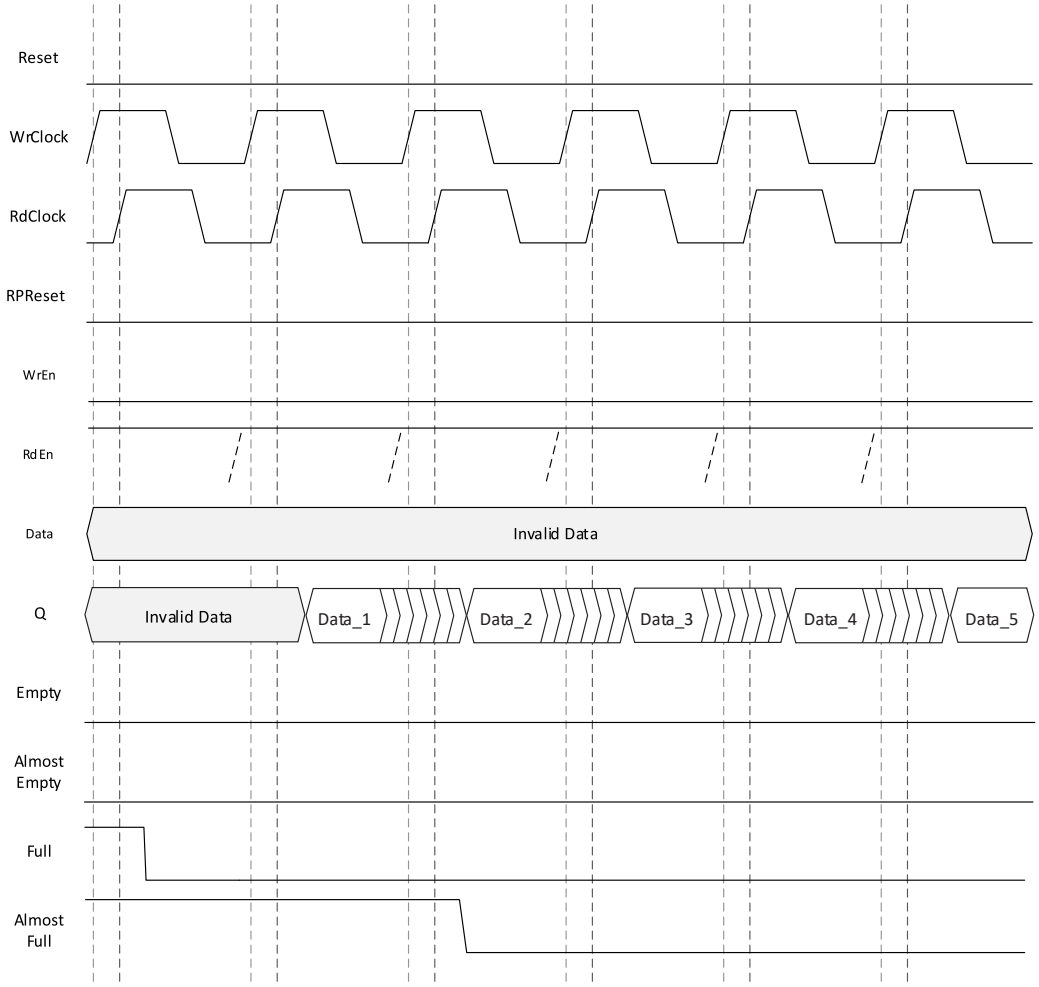

Figure 5.18. FIFO_DC with Output Registers, Start of Data Read Cycle

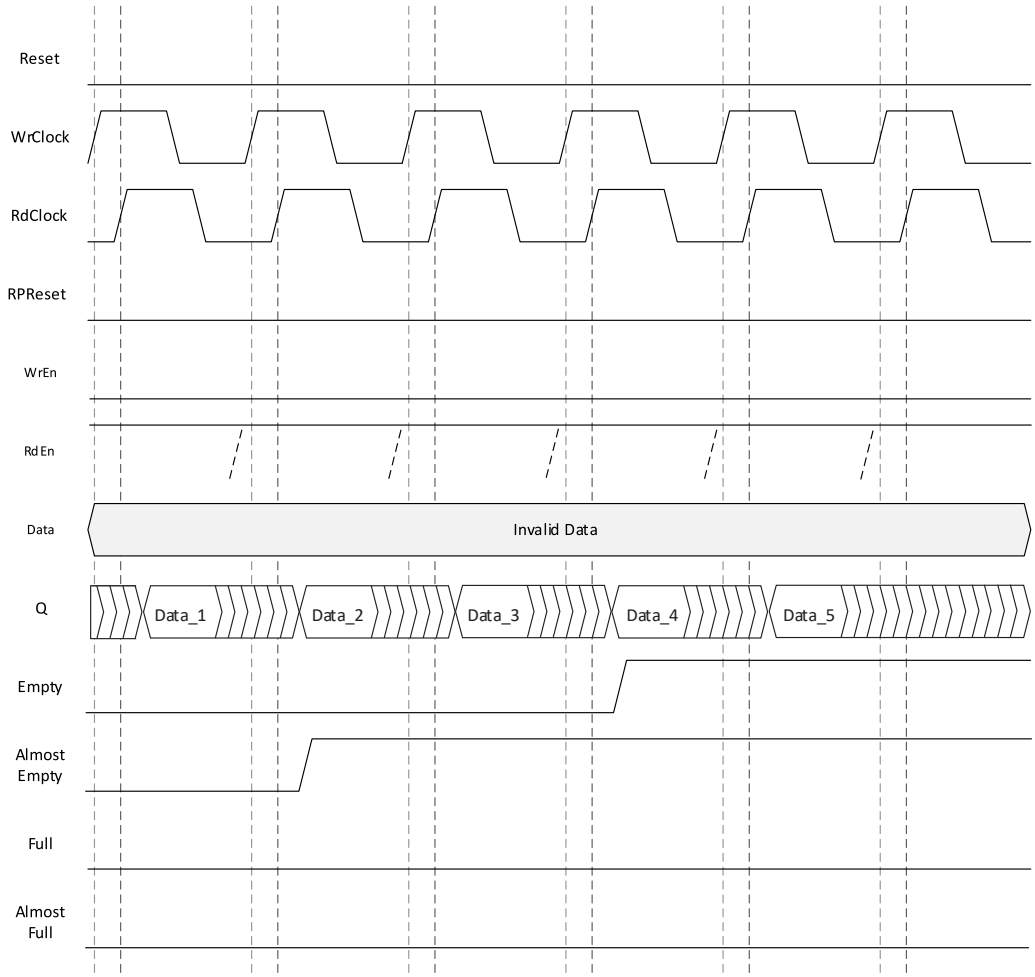

Figure 5.19. FIFO_DC with Output Registers, End of Data Read Cycle

If you select the option to enable the output register with RdEn, data out is still delayed by one clock cycle, as compared to the non-pipelined FIFO_DC. RdEn should also be high during that clock cycle. Otherwise, the data takes an extra clock cycle when the RdEn is true (Figure 5.20).

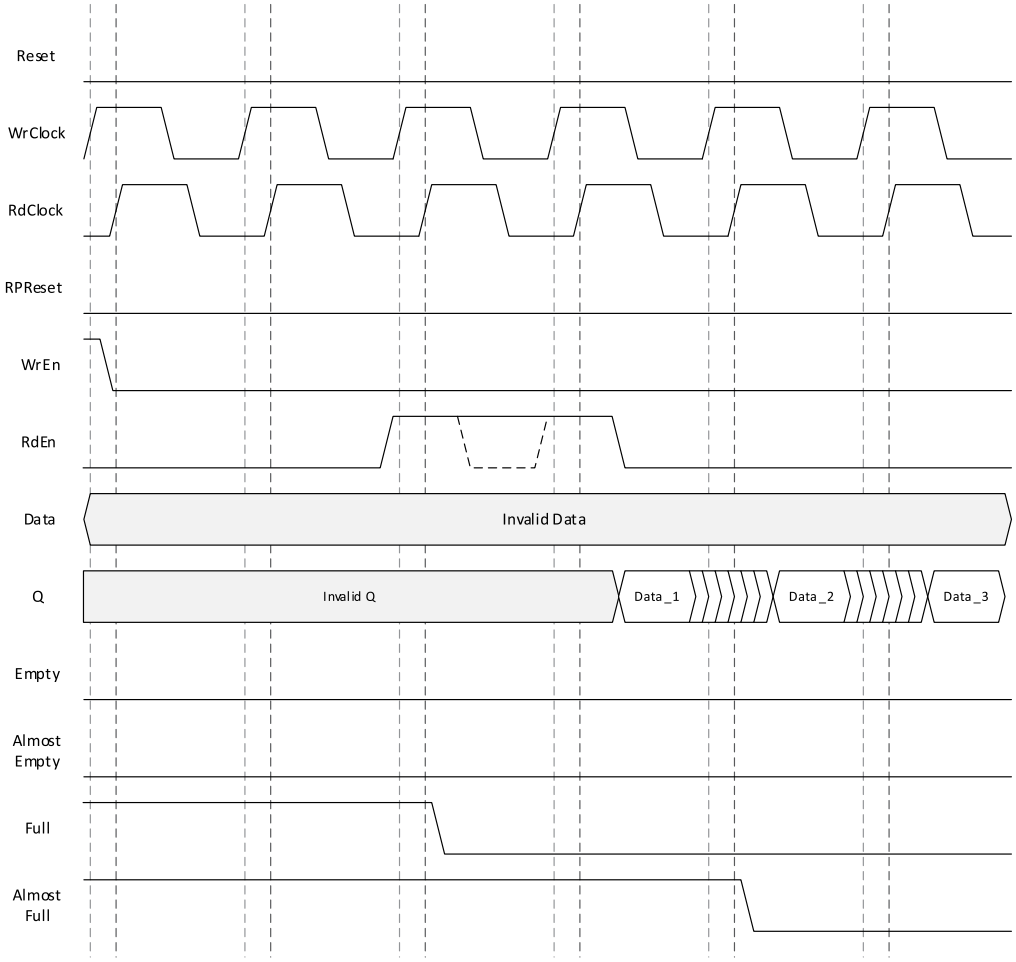

Figure 5.20. FIFO_DC with Output Registers and RdEn on Output Registers

When using FIFO_DC with different data widths on read and write ports, make sure that the wider data width is a multiple of the smaller one. In addition to that, the words written or read out should follow the same relationship. For example, assume that the DataIn write port width is 8 bits and the DataOut read port is 16 bits. In this case, there is a factor of 2 between the two. For every two words written in the FIFO_DC, one word is read out. If you write an odd number of words, such as seven, for example, then the read port reads three complete words and one half-word. The other half of the incomplete word is either all zeroes (0s) or prior data written at the 8th location.

If you reverse the number of bits on DataIn and DataOut, then for every written word, two words are read out. To completely read the FIFO_DC, you need twice the number of clock cycles on the write port.

FIFO_DC does not include any arbitration logic. It must be implemented outside of FIFO_DC. Read and Write Count pointers can be used to aid in counting the number of written or read words.

6. Distributed Single-Port RAM (Distributed_SPRAM) – PFU-Based

PFU-based Distributed Single-Port RAM is created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 6.1 shows the Distributed Single-Port RAM module generated by the IP Catalog.

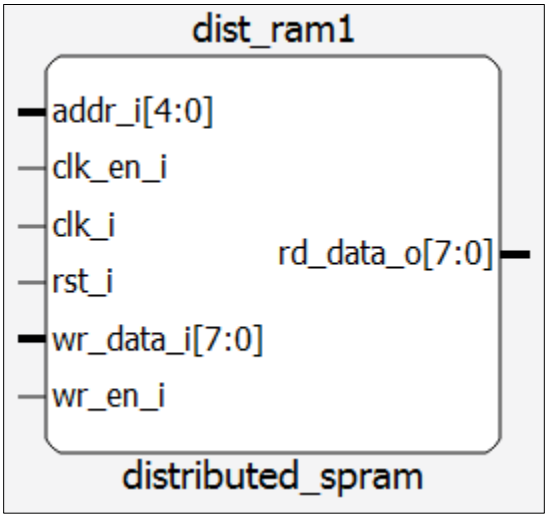

Figure 6.1. Distributed Single-Port RAM Module Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic, such as a clock or reset, is generated by utilizing the resources available in the PFU.

Ports such as Read Clock (RdClock) and Read Clock Enable (RdClockEn), are not available in the hardware primitive. These are generated by the IP Catalog when you want to enable the output registers in the IP Catalog configuration.

Figure 6.2 provides the primitive that can be instantiated for the Single-Port Distributed RAM. The primitive name is SPR16X4C, and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under the cae_library/synthesis folder in Lattice Radiant software installation folder.

It is to be noted that each EBR can accommodate 64 bits of memory. If the memory required is larger than 64 bits, then cascading can be used. Furthermore, the ports can be registered using external PFU registers.

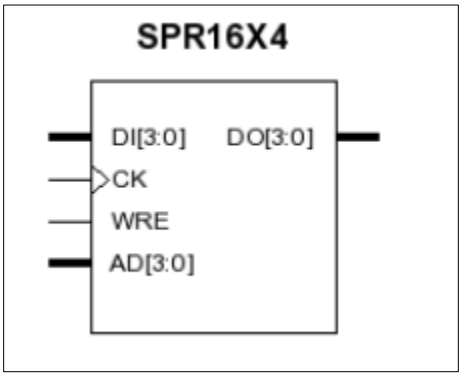

Figure 6.2. Single-Port Distributed RAM Primitive for Nexus Platform Devices

The various ports and their definitions are listed in Table 6.1. The table lists the corresponding ports for the module generated by the IP Catalog and for the primitive.

Table 6.1. PFU-Based Distributed Single-Port RAM Port Definitions

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	Clock Enable
we_i	Input	1	Read Enable
wr_data_i	Input	Data Width	Write Data
addr_i	Input	Address Width	Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed SPRAM are included in Table 6.2.

Table 6.2. Distributed_SPRAM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2–<Max that can fit in the device>	32
Data Width	Data word width of the read and write port	1–256	8
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	TRUE, FALSE	TRUE
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize the memory to all 1s, 0s, or to use a custom initialization by providing a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

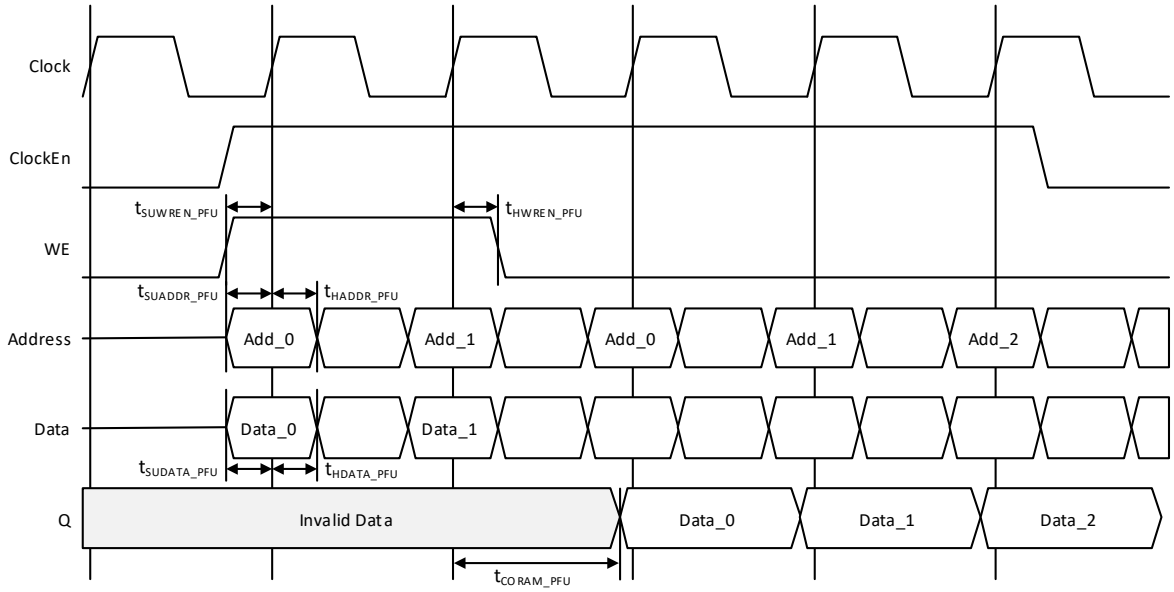

Figure 6.3. PFU-Based Distributed Single-Port RAM Timing Waveform – without Output Registers

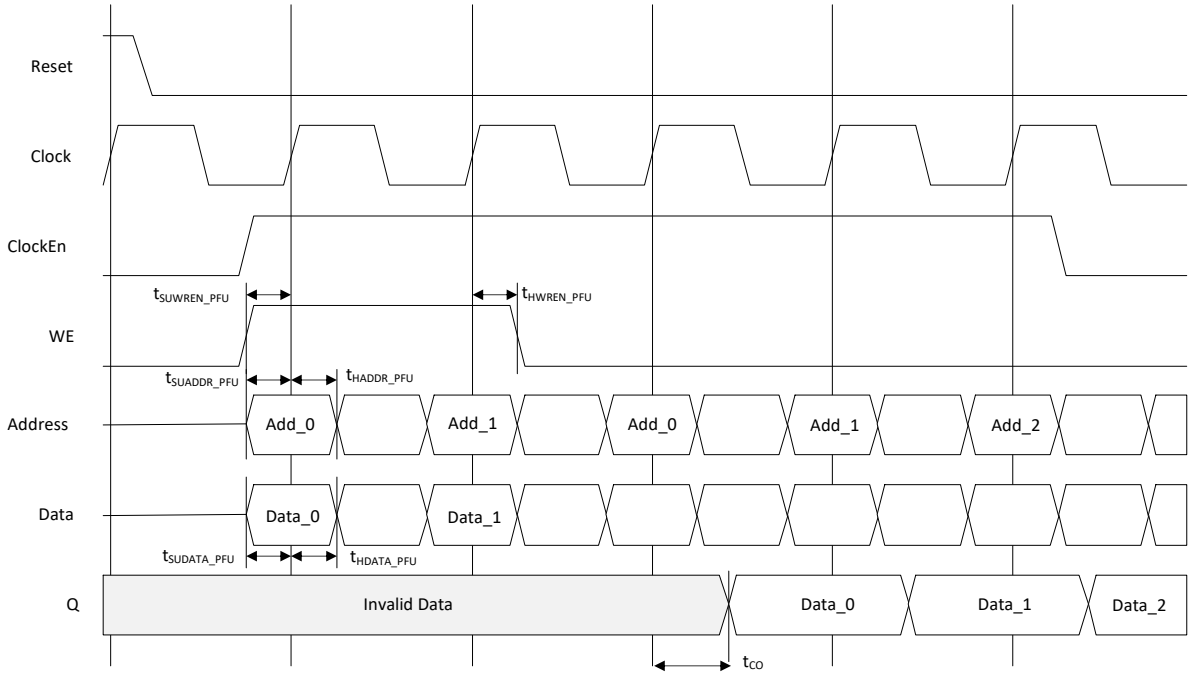

Figure 6.4. PFU-Based Distributed Single-Port RAM Timing Waveform – with Output Registers

7. Distributed Dual-Port RAM (Distributed_DPRAM) – PFU-Based

PFU-based Distributed Dual-Port RAM is also created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 7.1 shows the Distributed Single-Port RAM module generated by the IP Catalog.

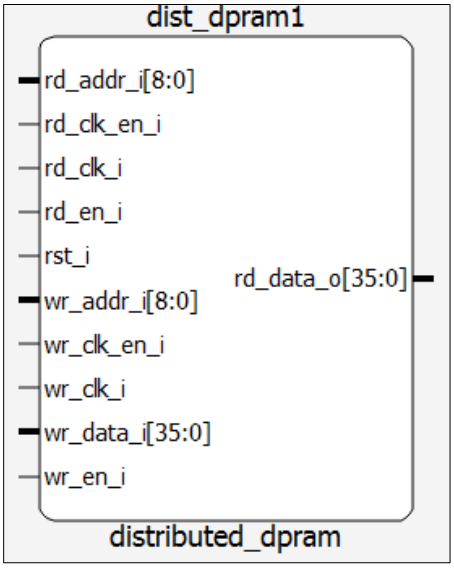

Figure 7.1. Distributed Dual-Port RAM Module Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic, such as a clock or reset, is generated by utilizing the resources available in the PFU.

Ports such as Read Clock and Read Clock Enable are not available in the hardware primitive. These are generated by IP Catalog when you want to enable the output registers in the IP Catalog configuration.

Figure 7.2 provides the primitive that can be instantiated for the Dual-Port Distributed RAM. The primitive name is DPR16X4, and it can be directly instantiated in the code. Check the details on the port and port names under the primitives available under the cae_library/synthesis folder in the Lattice Radiant software installation folder.

Note that each EBR can accommodate 64 bits of memory. If the memory required is larger than 64 bits, then cascading can be used. Furthermore, the ports can be registered using external PFU registers.

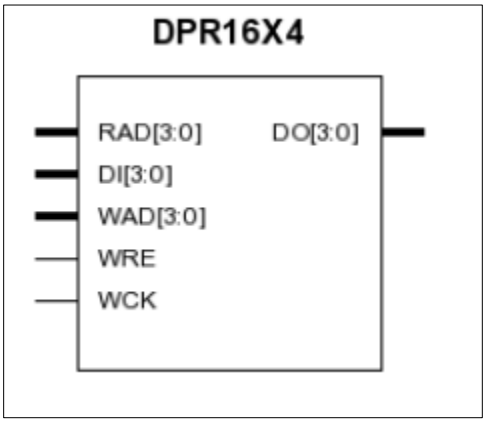

Figure 7.2. Dual-Port Distributed RAM Primitive for Nexus Platform Devices

The various ports and their definitions are listed in Table 7.1. The table lists the corresponding ports for the module generated by the IP Catalog and for the primitive.

Table 7.1. PFU-Based Distributed Dual-Port RAM Port Definitions

Port Name	Direction	Width	Description
wr_clk_i	Input	1	Write Clock
rd_clk_i	Input	1	Read Clock
rst_i	Input	1	Reset
wr_clk_en_i	Input	1	Write Clock Enable
rd_clk_en_i	Input	1	Read Clock Enable
rd_en_i	Input	1	Read Enable
wr_en_i	Input	1	Write Enable
wr_data_i	Input	Data Width	Write Data
wr_addr_i	Input	Address Width	Read Address
rd_addr_i	Input	Address Width	Read Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed DPRAM are described in Table 7.2.

Table 7.2. Distributed_DPRAM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2–<Max that can fit in the device>	512
Data Width	Data word width of the read and write port	1–512	36
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	True, False	True
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	This option allows you to initialize your memory to all 1s, 0s, or to use a custom initialization by providing a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

You have the option of enabling the output registers for Distributed Dual-Port RAM, Distributed_DPRAM. Figure 7.3 and Figure 7.4 show the internal timing waveforms for the Distributed Dual-Port RAM Distributed_DPRAM without and with output registers respectively.

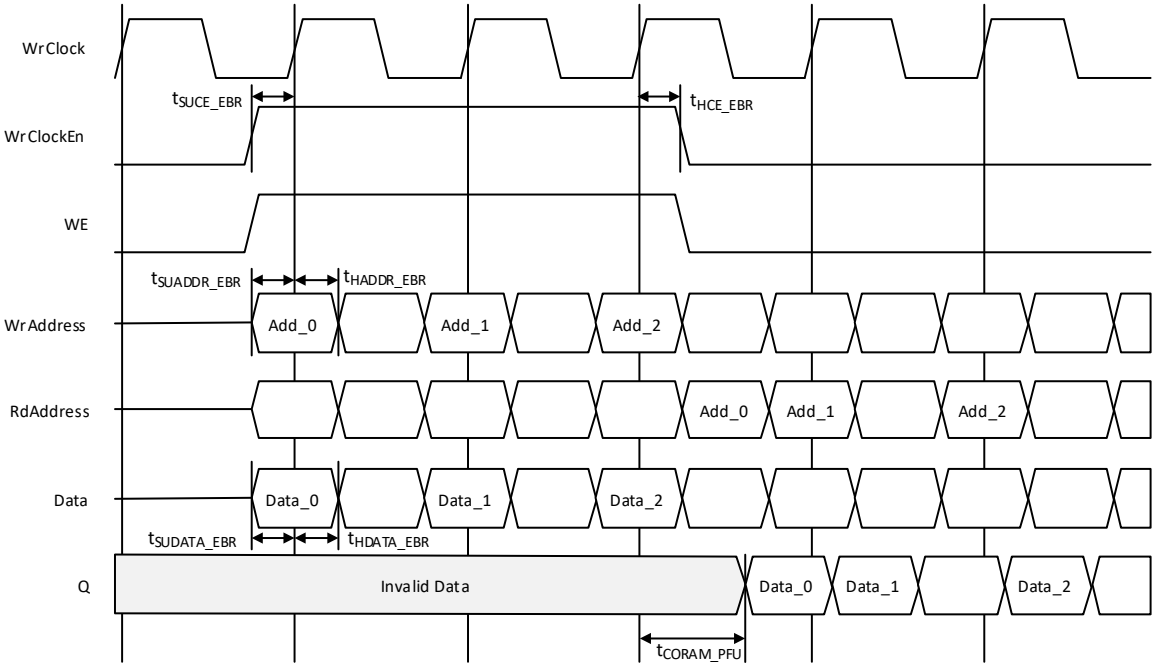

Figure 7.3. PFU-Based Distributed Dual-Port RAM Timing Waveform – without Output Registers

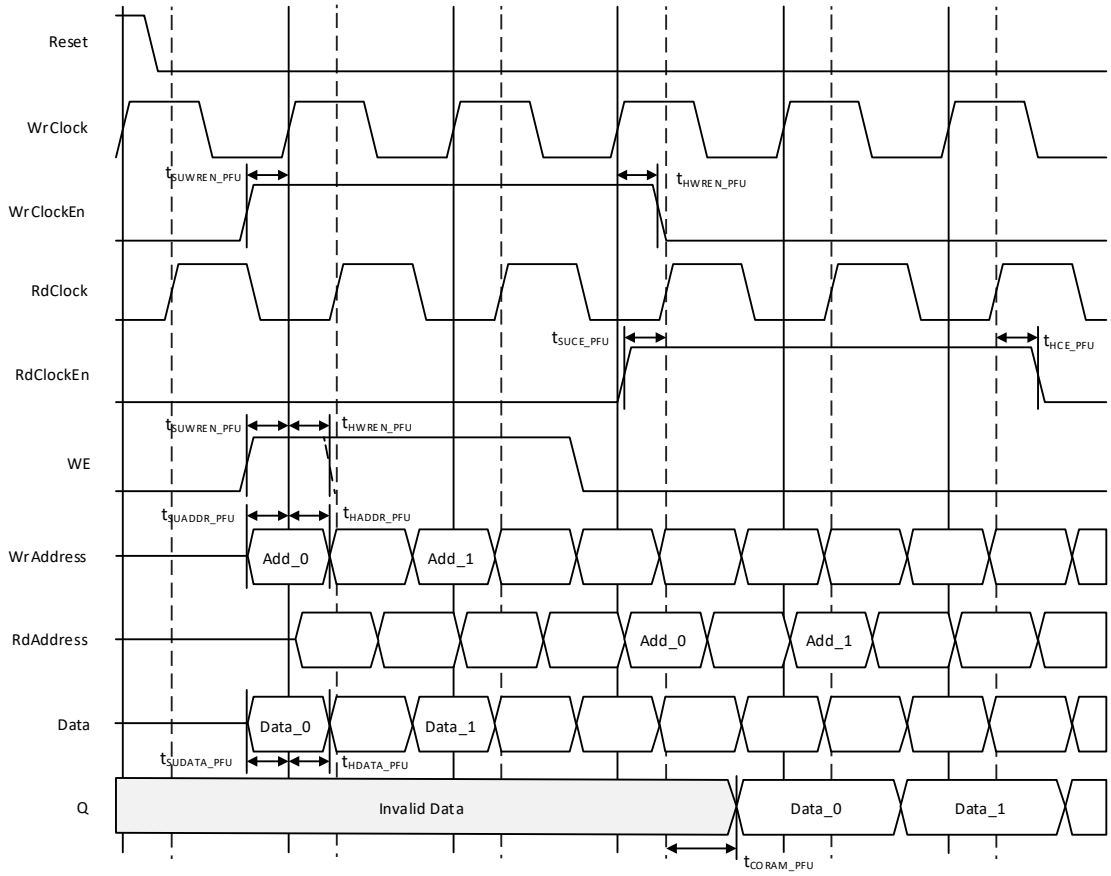

Figure 7.4. PFU-Based Distributed Dual-Port RAM Timing Waveform – without Output Registers

8. Distributed ROM (Distributed_ROM) – PFU-Based

A PFU-based Distributed ROM is also created using the 4-input LUTs available in the PFU. These LUTs can be cascaded to create larger distributed memory sizes.

Figure 8.1 shows the Distributed ROM module generated by the IP Catalog.

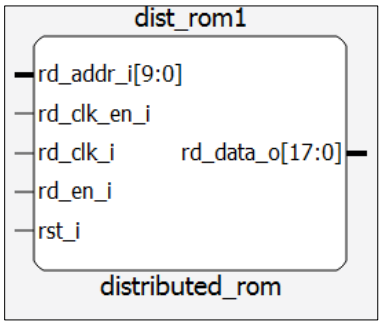

Figure 8.1. Distributed ROM Generated by IP Catalog

The generated module makes use of the 4-input LUTs available in the PFU. Additional logic, such as a clock or reset, is generated by utilizing the resources available in the PFU.

Ports such as Out Clock and Out Clock Enable are not available in the hardware primitive. These are generated by IP Catalog when you want to enable the output registers in the IP Catalog configuration.

If the memory required is larger than what can fit in the primitive bits, then cascading can be used. Furthermore, the ports can be registered by using external PFU registers.

The various ports and their definitions are listed in Table 8.1. The table lists the corresponding ports for the module generated by the IP Catalog and for the primitive.

Table 8.1. PFU-Based Distributed ROM Port Definitions

Port Name	Direction	Width	Description
clk_i	Input	1	Clock
rst_i	Input	1	Reset
clk_en_i	Input	1	Clock Enable
addr_i	Input	Address Width	Address
rd_data_o	Output	Data Width	Read Data

The software attributes for the Distributed ROM are included in Table 8.2.

Table 8.2. Distributed ROM Attributes for Nexus Platform Devices

Configuration Tab Attributes	Description	Values	Default Value
Address Depth	Address depth of the read and write port	2–<Max that can fit in the device>	1024
Data Width	Data word width of the read and write port	1–512	18
Enable Output Register	The Data Out Port Q can be registered or not using this selection.	True, False	True
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Memory Initialization	Allows you to initialize the memory by providing a custom initialization through a memory file.	Memory File	Memory File
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	—
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex

You have the option to enable the output registers for the Distributed ROM, Distributed_ROM. Figure 8.2 and Figure 8.3 show the internal timing waveforms for the Distributed ROM without output registers and with output registers respectively.

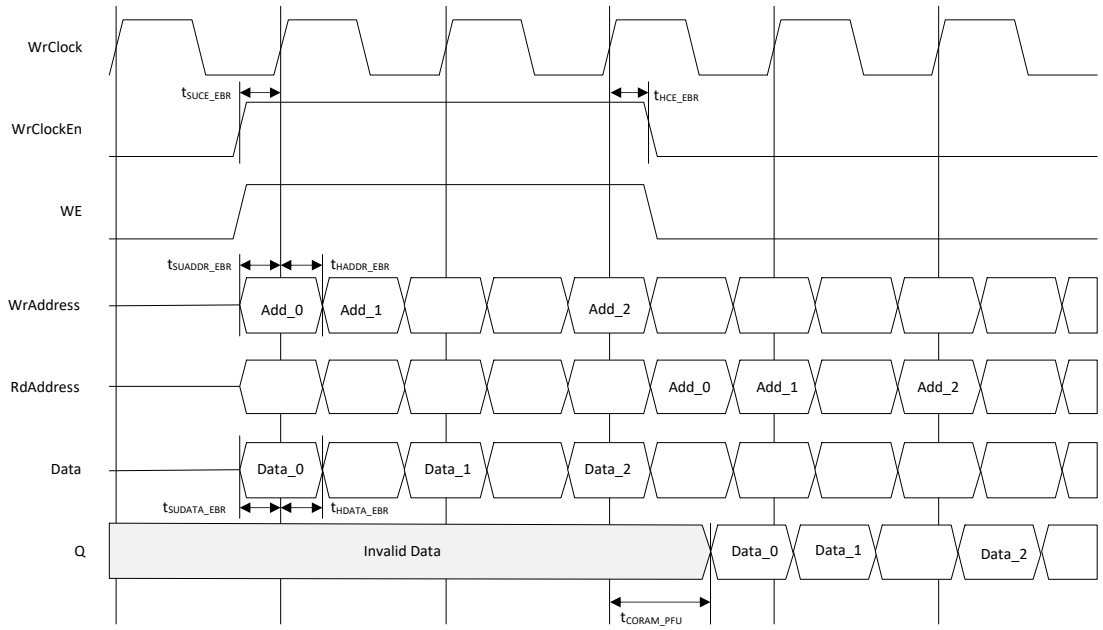

Figure 8.2. PFU-Based Distributed ROM Timing Waveform – without Output Registers

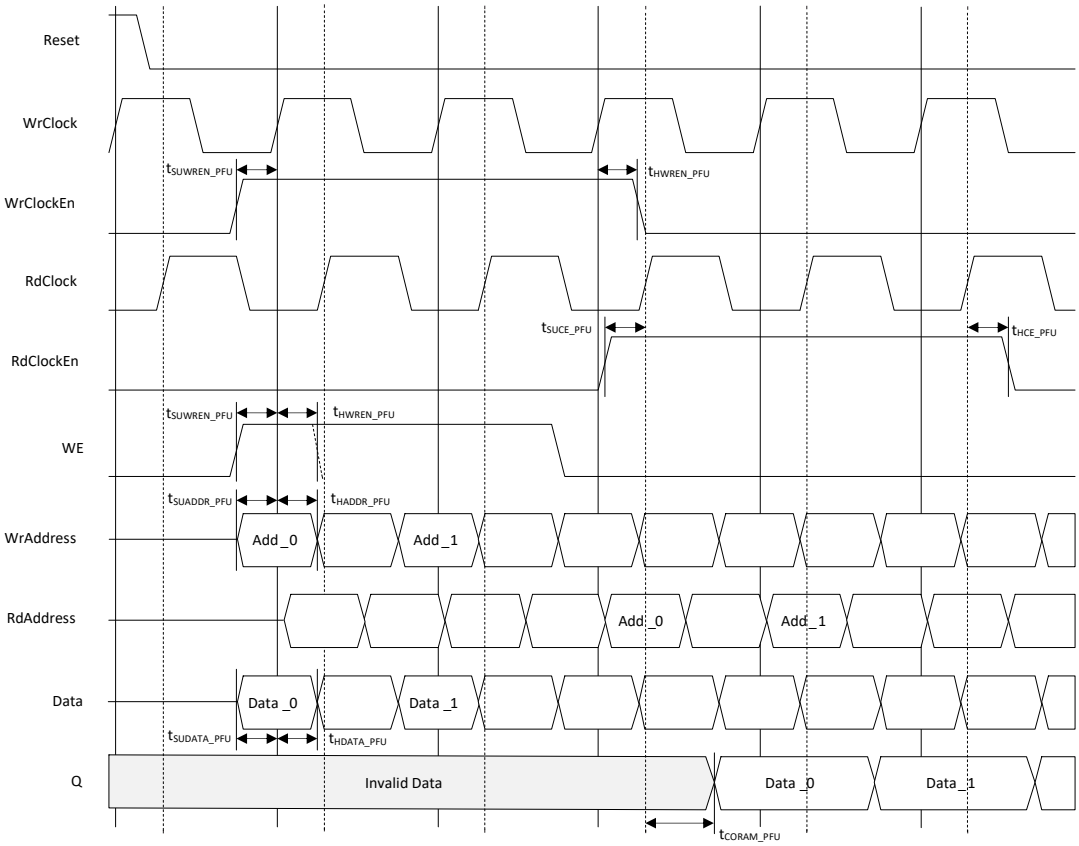

Figure 8.3. PFU-Based Distributed ROM Timing Waveform – with Output Registers

9. Large RAM (LRAM)

The Lattice Semiconductor Large Random-Access Memory (LRAM) IP Core is designed to work as Single-Port RAM, Dual-Port RAM, Pseudo Dual-Port RAM, and ROM memories. It is meant to function as additional memory resources beyond what is available in the EBR and PFU. The following sections cover each of the LRAM configuration modes.

9.1. Single-Port LRAM (Large_RAM_SP)

In the Single-Port Mode, only one port is used to write and read. Input can be configured as register in, and output can be configured as register out. The SRAM enclosed in the Large RAM IP is synchronous. IP Catalog generates the memory module, as shown in Figure 9.1.

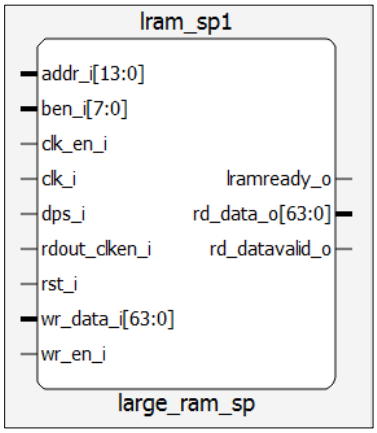

Figure 9.1. Single-Port Large RAM Generated by IP Catalog

Table 9.1 lists the ports and definitions for the Single-Port mode of the Large RAM primitive.

Table 9.1. Single-Port Mode Signals

Port Name	Direction	Width	Description
clk_i	Input	1	Clock for Port A
wr_data_i[DWA-1:0]	Input	Data Width	Input Data Port A (1–32 bits)
addr_i[AWA-1:0]	Input	Address Width	Port A Address (10–16 bits)
wr_en_i	Input	1	Port A Write Enable
clk_en_i	Input	1	Port A Clock Enable
ben_i[n-1:0]	Input	4	Port A Byte Enable n takes values from 1 to 4. Optional signal For each bit position: 0 – The corresponding byte should be written. 1 – The corresponding byte should not be written.
rst_i	Input	1	Port A Logic Reset
rdout_clken_i	Input	1	Port A Output Register Clock Enable
rd_datavalid_o	Output	1	Output Enable Port A
rd_data_o[DWA-1:0]	Output	Data Width	Output Data Port A
dps_i	Input	1	Dynamic Power Select
lramready_o	Output	1	Large RAM IP Ready Indicator
errdeca_o[1:0]	Output	2	Error Correction Indicator
errdet_o	Output	1	Large RAM IP Error Status

Note: The lramready_o signal is LOW if dps_i is asserted.

Table 9.2 shows the attributes for the Single-Port mode of the Large RAM primitive.

Table 9.2. Attributes Summary for Single-Port Mode

Attributes	Description	Values	Default Value
Configuration			
Address Depth	Address depth of the Read and Write port	2–131072	16384
Data Width	Data word width of the Read and Write port	1–64	32
Enable Output Register	The Data Out port (rd_data_o) can be registered or not using this selection	True, False	True
Enable Read Out Clock En	Clock Enable for the output clock. This option requires enabling the output register.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset De-Assertion	Selection for the reset de-assertion to be synchronous or asynchronous to the Clock. This option requires an asynchronous reset assert.	async, sync	sync
Enable Byte Enable[1, 2, 3]	Enables the Byte Enable function for the write port.	True, False	False
Initialization			
Memory Initialization	Allows you to initialize the memory to all 1s, 0s, or provide custom initialization through a memory file.	none, Initialize to all 0s, Initialize to all 1s, Memory File	none
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	none
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex
Miscellaneous Options			
Write/Read Related			
Enable ECC[2, 4]	Enables the ECC functionality of the IP.	True, False	False
Select Write Mode	Sets the behavior of the output port rd_data_o based on the current write transaction.	normal, write-through, read-before-write	normal
Enable Unaligned Read[3, 4]	Enables the unaligned read functionality of the Soft IP which shifts the data out based on the current port input at the time of the read command.	True, False	False
Others			
Enable Preserve Array	Allows the LRAM to preserve the array when the IP is set to the low power mode.	True, False	True
Enable GSR	Enables the GSR to reset this IP.	True, False	True

Notes:

1. Byte-Enable can only be used for write ports >= 16 bits.
2. Byte-Enable CANNOT be used with ECC.
3. The Byte-Enable port ben_i is shared with the Unaligned Read functionality. The port functions as byte-enable if wr_en_i is high, and as unaligned read when wr_en_i is low.
4. ECC and Unaligned Read can only be enabled when DATA_WIDTH = 32.

The waveforms in the following figures show the internal timing for the single-port LRAM with the various input and output registers that enable permutations.

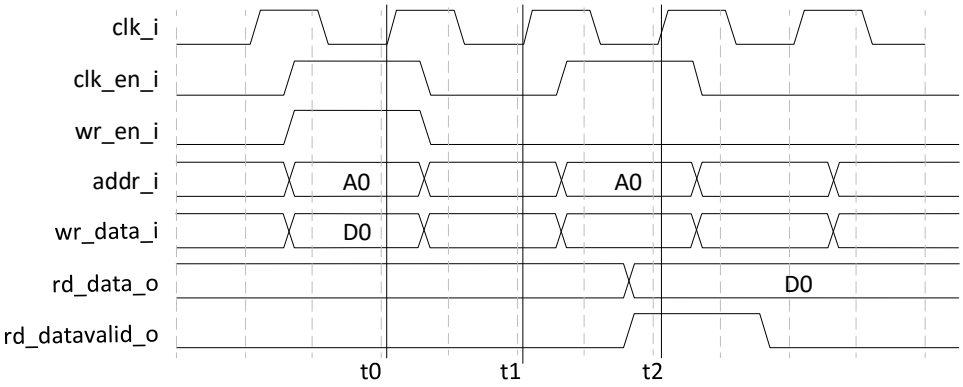

Figure 9.2. Single-Port Mode Timing Diagram with Both Input and Output Registers Disabled

As shown in Figure 9.2, the data flow is as follows:

1. addr_i and wr_data_i are clocked in the SRAM at t0.
2. When you read the data, set the clk_en_i and wr_en_i port values after t1.
3. You get the read-back data at t2.

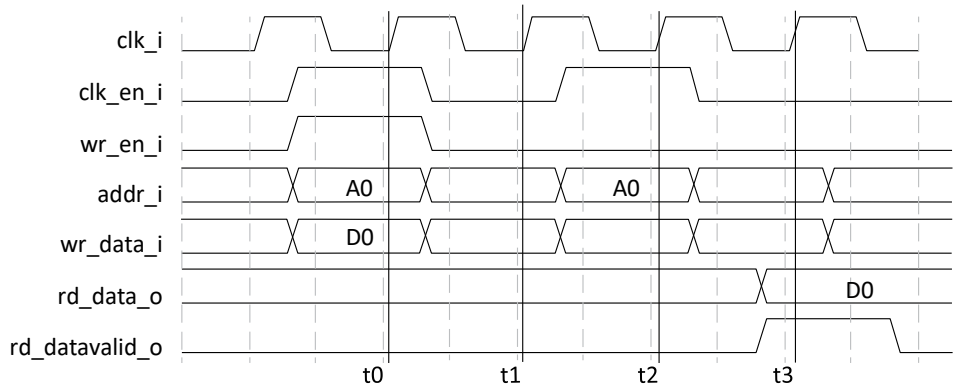

Figure 9.3. Single-Port Mode Timing Diagram with Either Input Register Enabled/Output Register Disabled or Input Register Disabled/Output Register Enabled

As shown in Figure 9.3, the data flow is as follows:

1. For both cases, first, addr_i and wr_data_i are clocked in the SRAM at t0 in the user's view.
2. For the Input Register Enabled/Output Register Disabled case, Large RAM registers input signals clk_en_i, wr_en_i, addr_i, and wr_data_i with input registers, and those signals are clocked in the SRAM at t1 in the user's view.
3. When you read the data, the Large RAM IP registers the input signals after t2 and connects those input signals to SRAM input ports.
4. SRAM clocks in input signals. Output data D0 gets ready.
5. You get the read-back data at t3.
6. For the Input Register Disabled/Output Register Enabled case, when you read the data, set clk_en_i and wr_en_i port values after t1.
7. Large RAM connects those signals to SRAM. SRAM clocks in addr_i and wr_data_i. Data D0 gets ready.
8. Large RAM registers the output data with the output register after t2 and connects it to the output port rd_data_o.
9. You get the read back data at t3.

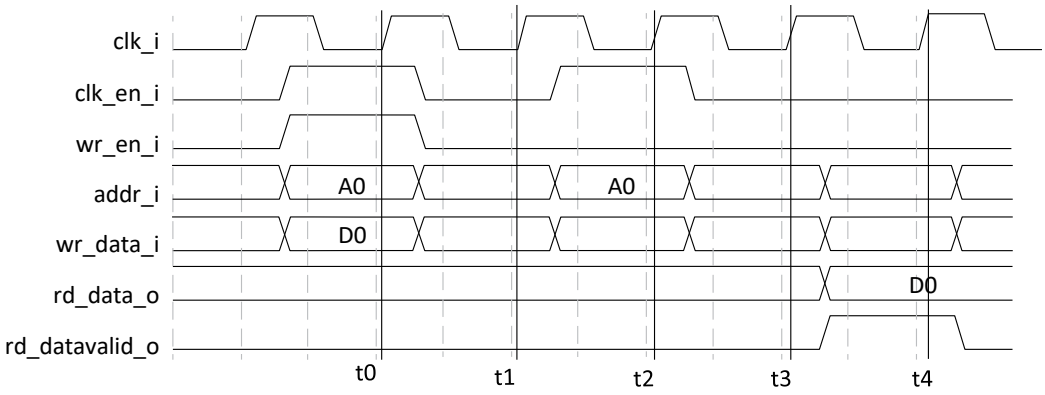

Figure 9.4. Single-Port Mode Timing Diagram with Both Input and Output Registers Enabled

As shown in Figure 9.4, the data flow is as follows:

1. addr_i and wr_data_i are clocked in the SRAM at t0 in the user's view.
2. Large RAM registers the input signals clk_en_i, wr_en_i, addr_i, and wr_data_i with input registers. Those signals are clocked in the SRAM at t1 in the user's view.
3. When you read data, the Large RAM IP registers the input signals after the positive edge of t2 and connects them to SRAM input ports.
4. SRAM clocks them in, outputs data, and gets ready.
5. The Large RAM registers the output data with the output register after t3 and connects it to the output port rd_data_o.
6. You get the read-back data at t4.

9.2. True Dual-Port LRAM (Large_RAM_DP_True)

In True Dual-Port Mode, both ports can be used to write and read. Input can be configured as register in, and output can be configured as register out. Dual-Port Mode is implemented in the Single-Port SRAM model. To accommodate the requests from both ports at the same time, the enclosed Single-Port RAM runs the clock with doubled frequency. In the Dual-Port mode, if reading and writing operations come at one CIB clock cycle, those operations are mapped to the Single-Port SRAM model.

The SRAM enclosed in the Large RAM IP is synchronous. The IP Catalog generates the memory module, as shown in Figure 9.5.

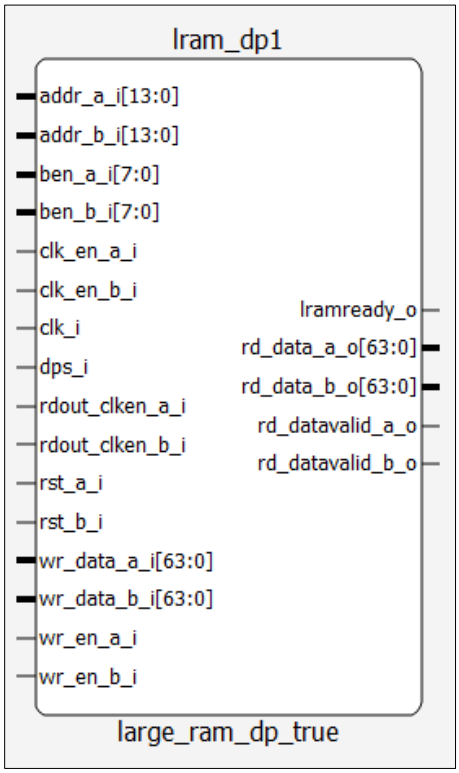

Figure 9.5. True Dual-Port Large RAM Generated by IP Catalog

Table 9.3 lists the ports and definitions for the True Dual-Port mode of the Large RAM primitive.

Table 9.3. True Dual-Port Mode Signal

Port Name	Direction	Width	Description
clk_i	Input	1	Clock for Port A
wr_data_a_i[DWA-1:0]	Input	Data Width	Input Data Port A (1–32 bits)
addr_a_i[AWA-1:0]	Input	Address Width	Port A Address (10–16 bits)
wr_en_a_i	Input	1	Port A Write Enable
clk_en_a_i	Input	1	Port A Clock Enable
ben_a_i[n-1:0]	Input	4	Port A Byte Enable n takes values from 1 to 4. Optional signal For each bit position: 0 – The corresponding byte should be written. 1 – The corresponding byte should not be written.
rsta_i	Input	1	Port A Logic Reset
rdout_clken_a_i	Input	1	Port A Output Register Clock Enable

Port Name	Direction	Width	Description
rd_datavalid_a_o	Output	1	Output Enable Port A
rd_data_a_o[DWA-1:0]	Output	Data Width	Output Data Port A
dps_i	Input	1	Dynamic Power Select
wr_data_b_i[DWB-1:0]	Input	Data Width	Input Data Port B (1–32 bits)
addr_b_i[AWB-1:0]	Input	Address Width	Port B Address (10–16 bits)
wr_en_b_i	Input	1	Port B Write Enable
clk_en_b_i	Input	1	Port B Clock Enable
ben_b_i[3:0]	Input	4	Port B Byte Enable, optional signal n takes values from 1 to 4. For each bit position: 0 – The corresponding byte should be written. 1 – The corresponding byte should not be written.
rstb_i	Input	1	Port B Logic Reset
rdout_clken_b_i	Input	1	Port B Output Register Clock Enable
rd_datavalid_b_o	Output	1	Output Enable Port B
rd_data_b_o[DWB-1:0]	Output	Data Width	Output Data Port B
lramready_o	Output	1	Large RAM IP Ready Indicator
errdeca_o[1:0]	Output	2	Error Correction Indicator
errdecb_o[1:0]	Output	2	Error Correction Indicator
errdet_o	Output	1	Large RAM IP Error Status

Note: The lramready_o signal is LOW if dps_i is asserted.

Table 9.4 shows the attributes for the True Dual-Port mode of the Large RAM primitive.

Table 9.4. Attributes Summary for True Dual-Port Mode

Attribute	Description	Values	Default Value
General Attributes			
Port A Address Depth[1, 2]	Port A address depth	2–131072	16384
Port A Data Width[1, 2]	Port A data width	1–64	32
Port B Address Depth[1, 2]	Port B address depth[1, 2]	2–131072	16384
Port B Data Width[1, 2]	Port B data word width[1, 2]	1–64	32
Enable Output Register (Port A)	Data Out port A (Q) can be registered or not using this selection.	True, False	True
Enable Output Register (Port B)	Data Out port B (Q) can be registered or not using this selection.	True, False	True
Enable Read Out Clock En (Port A)	Clock Enable for the output port A. This option requires enabling the output register.	True, False	False
Enable Read Out Clock En (Port B)	Clock Enable for the output port B. This option requires enabling the output register.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Deassertion	Selection for the Reset deassertion to be synchronous or asynchronous to the Clock	async, sync	sync
Enable Byte Enable (Port A)[3, 4]	Enables the Byte Enable function for Port A's write port.	True, False	False
Enable Byte Enable (Port B)[3, 4]	Enables the Byte Enable function for Port B's write port.	True, False	False
Initialization Attributes			
Memory Initialization[5]	Allows you to initialize the memory to all 1s, 0s, or to provide custom initialization through a memory file.	none, all 0s, all 1s, Memory File	none

Attribute	Description	Values	Default Value
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	none
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex
Miscellaneous Options			
Write/Read Related			
Enable ECC[4, 6]	Enables the ECC functionality of the IP.	True, False	False
Enable Write-Through A	Enables the Write-Through mode for Port A.	True, False	False
Enable Write-Through B	Enable the Write-Through mode for Port B.	True, False	False
Enable Unaligned Read[6]	Enables the unaligned read functionality of the Soft IP which shifts the data out based on the current port input at the time of the read command.	True, False	False
Others			
Enable Preserve Array	Allows the LRAM to preserve the array when the IP is set to the low power mode.	True, False	True
Enable GSR	Enables the GSR to reset this IP.	True, False	True

Notes:

1. For mixed width configurations, total bit size must be equal, that is, ADEPTH*ADATA = BDEPTH*BDATA.
2. For mixed width configuration, the ratio between ADATA and BDATA must be 2 or 4.
3. Byte-enable can only be enabed when ADATA >= 16 for the port A, and/or BDATA >= 16 for the port B.
4. Byte-enable and ECC cannot be used simultaneously.
5. Initialization files should be provided with respect to ADDR_DEPTH_A x DATA_WIDTH_A.
6. ECC and Unaligned Read can only be enabled when ADATA = BDATA = 32.

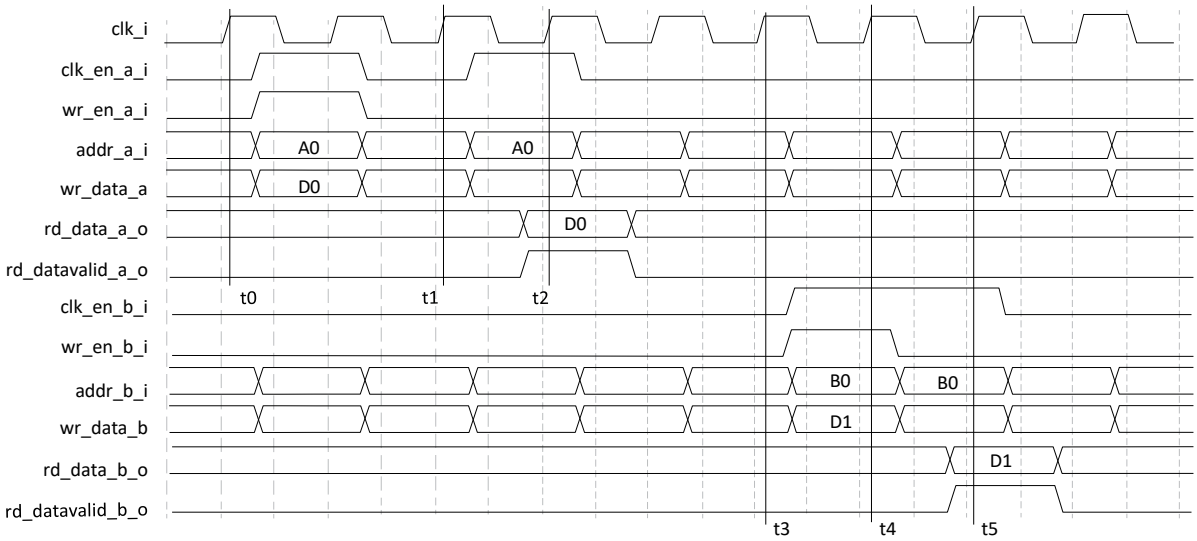

Figure 9.6. Dual-Port Mode Timing Diagram with Port A and Port B Working in Different Cycles, Input and Output Registers Disabled for Both Ports

As shown in Figure 9.6, the data flow is as follows:

For Port A:

1. You prepare the data at t0.
2. Large RAM clocks in clk_en_a_i, wr_en_a_i, addr_a_i, and wr_data_a_i to SRAM.
3. When you read the data, set the clk_en_a_i and wr_en_a_i port values after t1. Large RAM connects those signals to SRAM.

4. SRAM clocks in addr_a_i and wr_data_a_i, and output data gets ready.
5. Large RAM connects it to rd_data_a_o, and you get the read-back data at t2.

For Port B:

1. You prepare the data at t3.
2. Large RAM clocks in clk_en_b_i, wr_en_b_i, addr_b_i, and wr_data_b_i to SRAM.
3. When you read the data, set the clk_en_b_i and wr_en_b_i port values. Large RAM connects those signals to SRAM at t4.
4. SRAM clocks in addr_b_i and wr_data_b_i, and output data gets ready.
5. Large RAM connects it to rd_data_b_o, and you get the read-back data at t5.

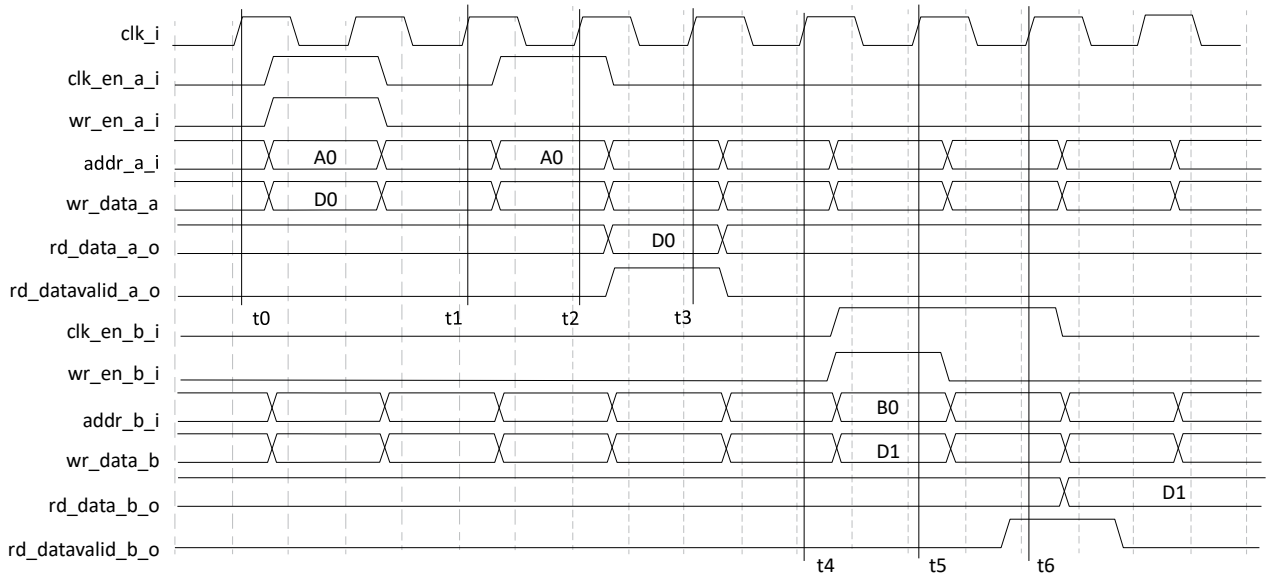

Figure 9.7. Dual-Port Mode Timing Diagram with Port A and Port B Working in Different Cycles, Input and Output Registers Disabled for Both Ports

As shown in Figure 9.7, the data flow is as follows:

For Port A:

1. You prepare the data at t0.
2. Large RAM clocks in clk_en_a_i, wr_en_a_i, addr_a_i, and wr_data_a_i to SRAM.
3. When you read the data, set the clk_en_a_i and wr_en_a_i port values after t1. Large RAM connects those signals to SRAM.
4. SRAM clocks in addr_a_i and wr_data_a_i, and output data gets ready.
5. Large RAM registers the output data with the output register after t2 and connects it to the output port rd_data_a_o.
6. You get the read-back data at t3.

For Port B:

1. You prepare the data at t4.
2. Large RAM clocks in clk_en_b_i, wr_en_b_i, addr_b_i, and wr_data_b_i to SRAM at t4.
3. When you read the data, you set the clk_en_b_i and wr_en_b_i port values. Large RAM connects those signals to SRAM.
4. SRAM clocks in addr_b_i and wr_data_b_i, and output data gets ready after t5.

5. Large RAM registers the output data with the output register after t6 and connects it to the output port rd_data_b_o.
6. You get the read-back data at the next positive edge of the clock.

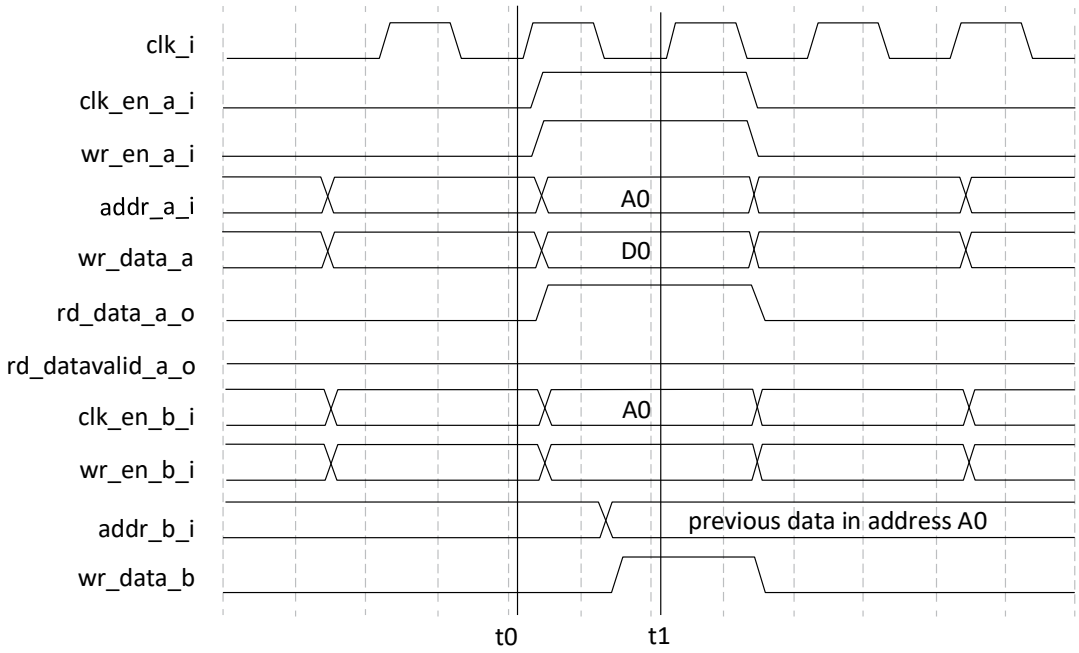

Figure 9.8. Dual-Port Mode Timing Diagram with Port A and Port B Working in the Same Cycle, Input and Output Registers Disabled for Both Ports

As shown in Figure 9.8, the data flow is as follows:

1. Port A writes address A0 and Port B reads address A0 at the same clock cycle.
2. At t0, the Port B address is clocked into SRAM, and output data is ready after t0.
3. At t1, Port A's address and data are clocked into SRAM for writing.
4. You get Port B read-back data at t1.

Note: When both ports are writing and reading the same address, reading takes precedence over writing in one cycle, and the output of the reading operation is the previous data in the address.

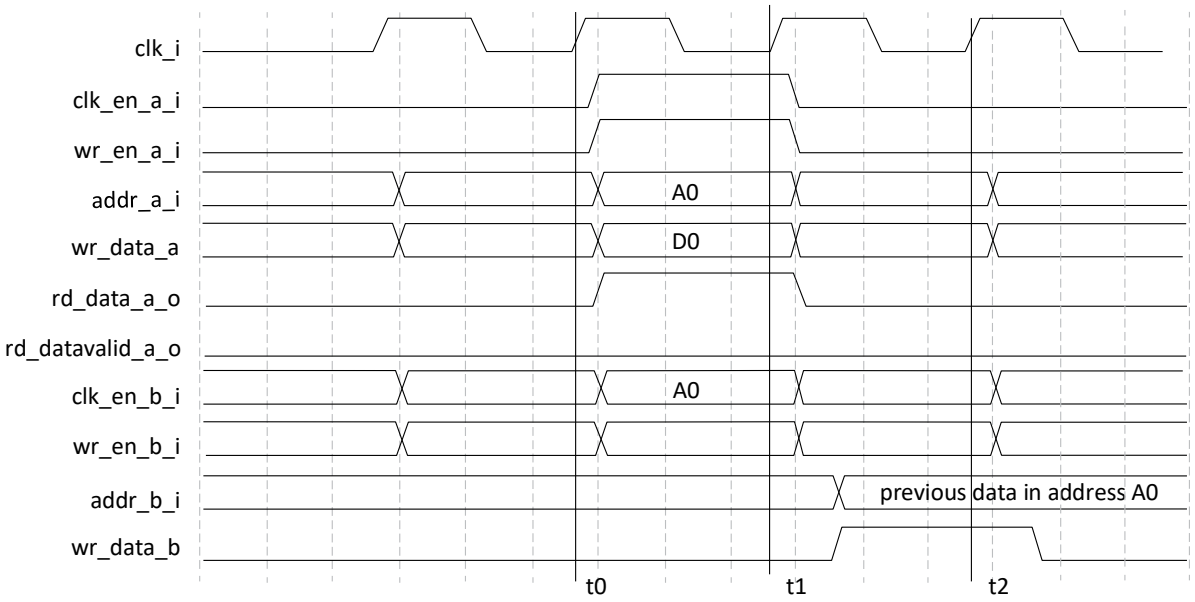

Figure 9.9. Dual-Port Mode Timing Diagram with Ports A and B Working in the Same Cycle, Input Register Disabled/Output Register Enabled for Both Ports

As shown in Figure 9.9, the data flow is as follows:

1. Port A writes address A0 and Port B reads address A0 at the same clock cycle.
2. Port B address is clocked into SRAM, and output data is ready after t0.
3. At t1, Port A's address and data are clocked into SRAM for writing.
4. Large RAM registers the output data from Port B with the output register after t1 and connects it to the output port rd_data_b_o.
5. You get the Port B read-back data at t2.

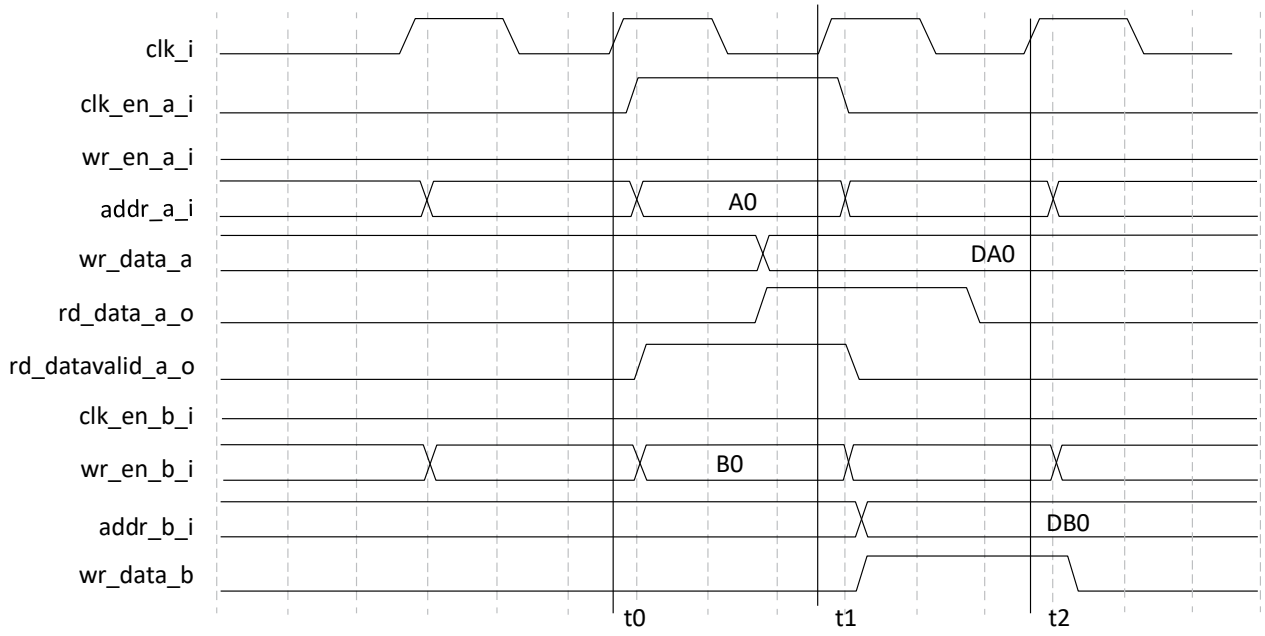

Figure 9.10. Dual-Port Mode Timing Diagram with Ports A and B Reading in the Same Cycle, Both Input and Output Registers Disabled for Both Ports

As shown in Figure 9.10, the data flow is as follows:

1. Both Port A and Port B read different addresses at the same clock cycle.
2. Port A address is clocked into SRAM, and output data DA0 is ready after t0.
3. You get the Port A read-back data at t1.
4. Port B address is clocked into SRAM, and output data DB0 is ready after t1.
5. You get the Port B read-back data at t2.

Note: When reading from both ports in the same cycle but from various addresses, data for port B comes with one clock delay. This is because the LRAM primitive has just one port, and both addresses cannot be read without delay.

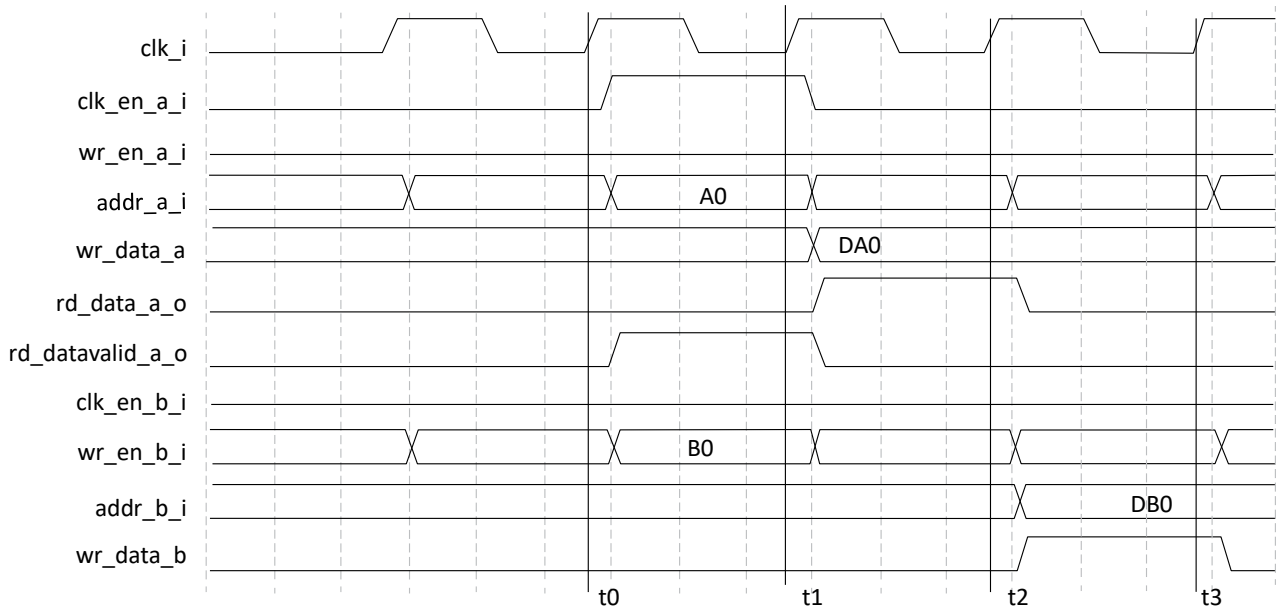

Figure 9.11. Dual-Port Mode Timing Diagram with Ports A and B Working in the Same Cycle, Input Register Disabled/Output Register Enabled for Both Ports

As shown in Figure 9.11, the data flow is as follows:

1. Both Port A and Port B read different addresses at the same clock cycle.
2. Port A address is clocked into SRAM, and output data DA0 is ready after t0.
3. Large RAM registers output data DA0 with the output register and connects it to the output port rd_data_a_o.
4. You get Port A read-back data after t1.
5. Port B address is clocked into SRAM, and output data DB0 is ready after t2.
6. Large RAM registers the output data DB0 with the output register after t2 and connects it to the output port rd_data_b_o.
7. You get Port B read-back data at t3.

9.3. Pseudo Dual-Port LRAM (Large_RAM_DP)

In Pseudo Dual-Port mode, Port A works as a writing port and Port B works as a reading port. Input and output register bypass mode is supported in the Single-Clock Pseudo Dual-Port mode. In this mode, both ports are writing to and reading from the same address. Reading takes precedence over writing in one cycle, so the output of reading is the previous data in the address. The IP Catalog generates the memory module, as shown in Figure 9.12.

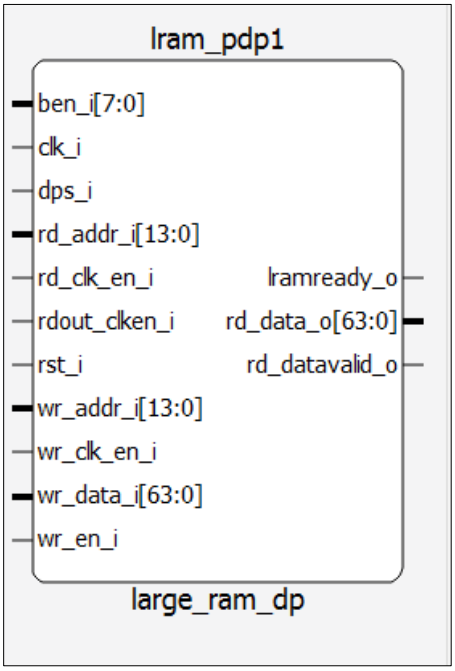

Figure 9.12. Pseudo Dual-Port Large RAM Generated by IP Catalog

Table 9.5 lists the ports and definitions for Pseudo Dual-Port mode of the Large RAM primitive.

Table 9.5. Pseudo Dual-Port Mode Signals

Port Name	Direction	Width	Description
clk_i	Input	1	Clock for Port A
wr_data_i[DWA-1:0]	Input	Data Width	Input Data Port A (1–32 bits)
wr_addr_i[AWA-1:0]	Input	Address Width	Port A Address (10–16 bits)
wr_clk_en_i	Input	1	Port A Clock Enable
ben_i[n-1:0]	Input	4	Port A Byte Enable, optional signal n takes values from 1 to 4. For each bit position: 0 – The corresponding byte should be written. 1 – The corresponding byte should not be written.
rst_i	Input	1	Port A and B Logic Reset
dps_i	Input	1	Dynamic Power Select
rd_addr_i[AWB-1:0]	Input	Address Width	Port B Address (10–16 bits)
rd_clk_en_i	Input	1	Port B Clock Enable
rdout_clken_i	Input	1	Port B Output Register Clock Enable
wr_en_i	Input	1	Write Enable
rd_data_o[DWB-1:0]	Output	Data Width	Output Data Port B
rd_datavalid_o	Output	1	Output Enable Port B
lramready_o	Output	1	Large RAM IP Ready Indicator
errdecb_o[1:0]	Output	2	Error Correction Indicator

Port Name	Direction	Width	Description
errdet_o	Output	2	Large RAM IP Error Status

Note: The lramready_o signal is LOW if dps_i is asserted.

Table 9.6 shows the attributes for the Pseudo Dual-Port mode of the Large RAM primitive.

Table 9.6. Attributes Summary for Pseudo Dual-Port Mode

Attribute	Description	Values	Default Value
General Attributes			
Write Port Address Depth[1, 2]	Write port address depth	2–131072	16384
Write Port Data Width[1, 2]	Write port data word width	1–64	32
Read Port Address Depth[1, 2]	Read port address depth	2–131072	16384
Read Port Data Width[1, 2]	Read port data word width	1–64	32
Enable Output Register	Data Out port (Q) can be registered or not using this selection.	True, False	True
Enable Read Out Clock En	Clock Enable for the output clock. This option requires enabling the output register.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Deassertion	Selection for the Reset release to be synchronous or asynchronous to the Clock	async, sync	sync
Enable Byte Enable[3, 4]	Enables the Byte Enable function for the write port.	True, False	False
Initialization Attributes			
Memory Initialization[5]	Allows you to initialize your memory to all 1s, 0s, or providing custom initialization through a memory file.	none, all 0s, all 1s, Memory file	none
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	none
Memory File Format	This option allows you to select if the memory file is formatted as binary or hex.	binary, hex	hex
Miscellaneous Options			
Write/Read Related			
Enable ECC[4, 6]	Enables ECC functionality of the IP.	True, False	False
Enable Unaligned Read[6]	Enables the unaligned read functionality of the Soft IP which shifts the data out based on the current port input at the time of the read command.	True, False	False
Others			
Enable Preserve Array	Allows the LRAM to preserve the array when the IP is set to low power mode.	True, False	True
Enable GSR	Enables the GSR to reset this IP.	True, False	True

Notes:

1. Total Number of bits between write and read ports must match, that is, WADDR_DEPTH * WDATA_WIDTH = RADDR_DEPTH * RDATA_WIDTH.
2. For mixed-width implementations, the allowable factor is 2 or 4, that is, WDATA_WIDTH = 2*RDATA_WIDTH, 4*WDATA_WIDTH = RDATA_WIDTH.
3. Byte-Enable can only be used for write port >= 16 bits.
4. Byte-Enable cannot be used with ECC.
5. A memory file is provided with respect to the write port, WADDR_DEPTH x WDATA_WIDTH.
6. ECC and/or Unaligned Read can only be used when WDATA_WIDTH = RDATA_WIDTH = 32.

For relevant timing diagrams, refer to Figure 9.8 and Figure 9.9.

9.4. Large Read-Only Memory (Large_ROM)

When used as a ROM, only one port is used to read. Input can be configured as register in, and output can be configured as register out. The SRAM enclosed in the Large RAM IP is synchronous. IP Catalog generates the memory module, as shown in Figure 9.13.

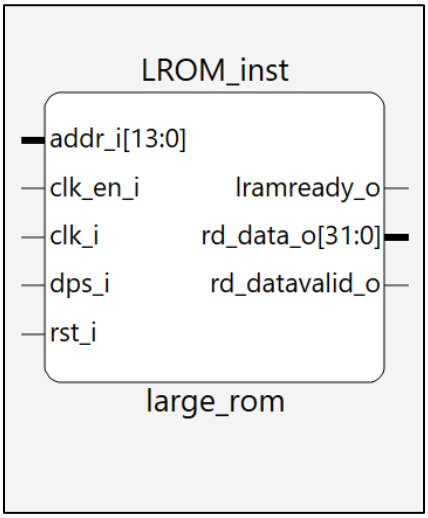

Figure 9.13. Large ROM Generated by IP Catalog

The following table lists the ports and definitions for ROM mode of the Large RAM primitive.

Table 9.7. ROM Mode Signals

Port Name	Direction	Width	Description
clk_i	Input	1	Clock for Port A
addr_i[AWA-1:0]	Input	Address Width	Port A Address (10–16 bits)
clk_en_i	Input	1	Port A Clock Enable
rst_i	Input	1	Port A Logic Reset
dps_i	Input	1	Dynamic Power Select
rdout_clken_i	Input	1	Port A Output Register Clock Enable
rd_datavalid_o	Output	1	Output Enable Port A
rd_data_o[DWB-1:0]	Output	Data Width	Output Data Port A
lramready_o	Output	1	Large RAM IP Ready Indicator
errdeca_o[1:0]	Output	2	Error Correction Indicator
errdet_o	Output	1	Large RAM IP Error Status

Note: The lramready_o signal is LOW if dps_i is asserted.

Table 9.8 shows the attributes for the ROM mode of the Large RAM primitive.

Table 9.8. Attributes Summary for ROM Mode

Attribute	Description	Values	Default Value
General Attributes			
Address Depth	Read port address depth	2–131072	16384
Data Width	Read port data width	1–64	32
Enable Output Register	Data Out (Q) can be registered or not using this selection.	True, False	True
Enable Read Out Clock En	Clock Enable for the read output clock. This option requires enabling the output register.	True, False	False
Reset Assertion	Selection for the reset to be synchronous or asynchronous to the Clock	async, sync	sync
Reset Deassertion	Selection for the reset deassertion to be synchronous or asynchronous to the Clock	async, sync	sync
Initialization Attributes			
Memory File	When Memory File is selected, you can browse to the memory file for custom initialization of RAM.	—	none
Memory File Format	This option allows you to select whether the memory file is formatted as binary or hex.	binary, hex	hex
Miscellaneous Options			
Write/Read Related			
Enable ECC*	Enables the ECC functionality of the IP.	True, False	False
Enable Unaligned Read*	Enables the unaligned read functionality of the Soft IP which shifts the data out based on the current port input at the time of the read command.	True, False	False
Others			
Enable Preserve Array	Allows the LRAM to preserve the array when the IP is set to the low power mode.	True, False	True
Enable GSR	Enables the GSR to reset this IP.	True, False	True

***Note**:
ECC and Unaligned Read can only be enabled when RDATA_WIDTH = 32.

The waveform in Figure 9.14 shows the internal timing for the ROM LRAM. The address is clocked into the SRAM when the Clock Enable selection is enabled. In case the output registers are bypassed, the new data is available right after the rising edge of the same clock cycle, on which the read address is clocked into the SRAM with the Clock Enable selection enabled.

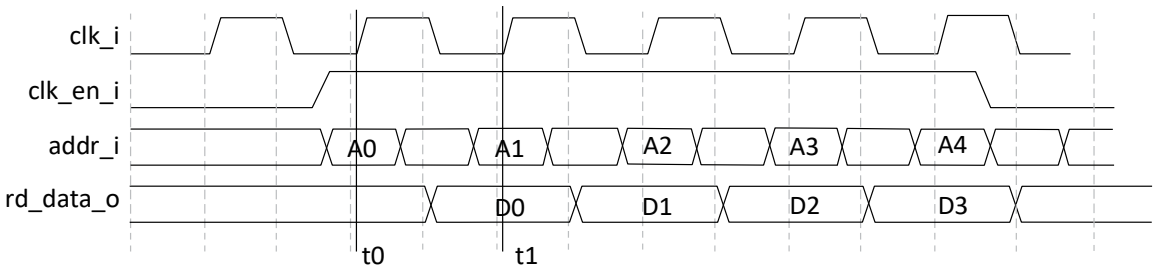

Figure 9.14. ROM Timing Diagram, Output Register Disabled

As shown in Figure 9.14, the data flow is as follows:

1. addr_i is clocked in the SRAM at t0.
2. You set the clk_en_i port value and get the read-back data at t1.

9.5. ECC and Byte Enable

This soft IP design implements an ECC module for the Lattice FPGA families that can be applied to increase memory reliability in critical applications. The ECC module provides Single Error Correction – Double Error Detection (SECDED) capability based on a class of optimal minimum odd weight error parity codes that provides better performance than typical Hamming-based SECDED codes. ECC syndrome is calculated over all four bytes of data. If you incorrectly enable byte write together with ECC, the inner ECC is disabled, and byte write still works correctly.

The Byte Enable feature enables you to mask the bytes written in the RAM. The Byte Enable control can be per 8-bit or 9-bit. The selection can be made in the Module/IP Block Wizard while generating the module.

Byte Enable and ECC are mutually exclusive and cannot be used together.

9.6. Using Various Data Widths on Various Ports

When LRAM memory is configured as True Dual-Port or Pseudo Dual-Port memory, it has separate Data Width (DW) and Address Width (AW) parameters for ports A and B. The parameters can be configured independently. However, there are a few constraints for their values.

- The Data Width of the wide port should be the multiple of narrow port's Data Width. The ratio can be 1, 2, or 4.
- Full memory space for both ports should be the same:

  (2^AW_A)*DW_A = (2^AW_B)*DW_B,

  where AW_X is the Address Width of port X and DW_X is the Data Width of port X. If the Data Widths are equal, the Address Widths should be the same. If the Data Width ratio is two, the Address Width difference should be one. If the Data Width ratio is four, the Address Width difference should be two.
- When Data Widths are not the same, the ECC is disabled even if Byte Enable is not checked.
- The Number of Bytes (NB) used for each port can be calculated using the following formulas:

  For the Narrow Port: NB = ceil(Data Width/8).

  For the Wide Port: NB = (Data Widths Ratio) * (NB of Narrow port).

  For example:

  if:

  DW_A = 2 and DW_B = 8,

  then:

  NB_A = 1 and NB_B = 4.

If Byte Enable is set for a port, then its width, which is in bits, is equal to the Number of Bytes for that port.

Byte Enable can be set only if the Number of Bytes is greater than one on the corresponding port and the number of bits is a multiple of 8 on both ports.

9.7. Write Mode Attribute

Any port that has both read access and write access has a write mode attribute. This attribute is available for Port A in the Single-Port Mode and for both Port A and Port B in True Dual-Port Mode. In Pseudo Dual-Port and ROM modes, no write mode attribute is available as there are no ports with both read access and write access.

There are three possible values for the write mode attribute: Normal, Write Through, and Read Before Write. All three modes are supported in Single-Port Large RAM, while only the first two are supported in True Dual-Port Large RAM.

- In Normal mode, the output data is not changed or updated during the write operation.
- In Write Through mode, the output data is updated with the input data during the write cycle.
- In Read Before Write mode, the output data port is updated with the existing data stored in the write address during a write cycle. This mode is supported only in the Single-Port LRAM.

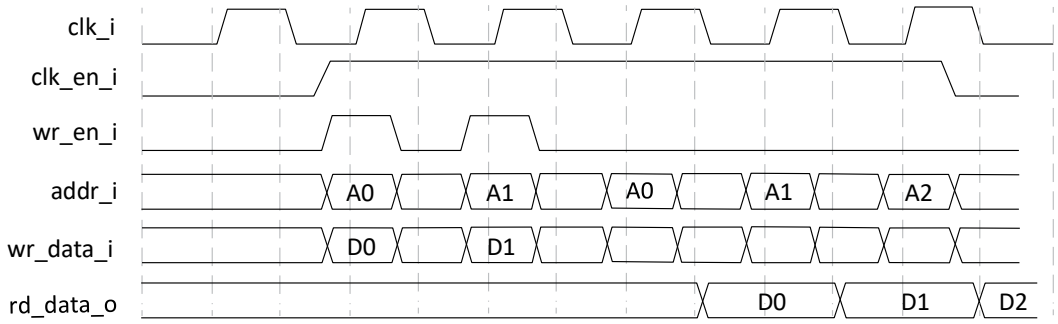

Figure 9.15. Single-Port LRAM Timing Diagram in Normal Mode, Output Register Disabled

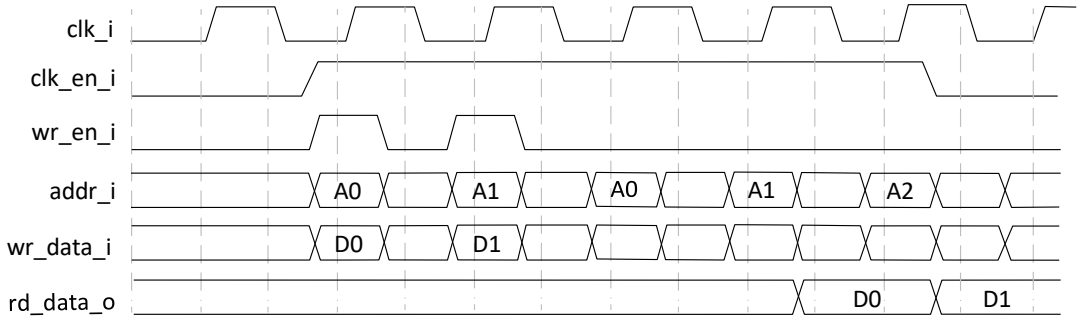

Figure 9.16. Single-Port LRAM Timing Diagram in Normal Mode, Output Register Enabled

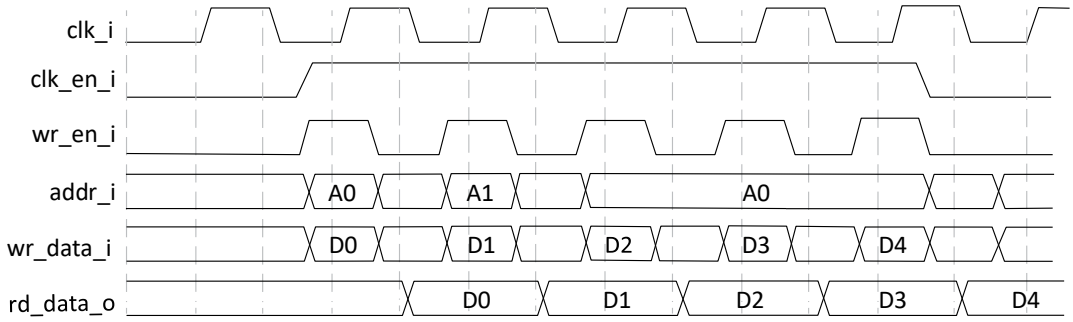

Figure 9.17. Single-Port LRAM Timing Diagram in Write Through Mode, Output Register Disabled

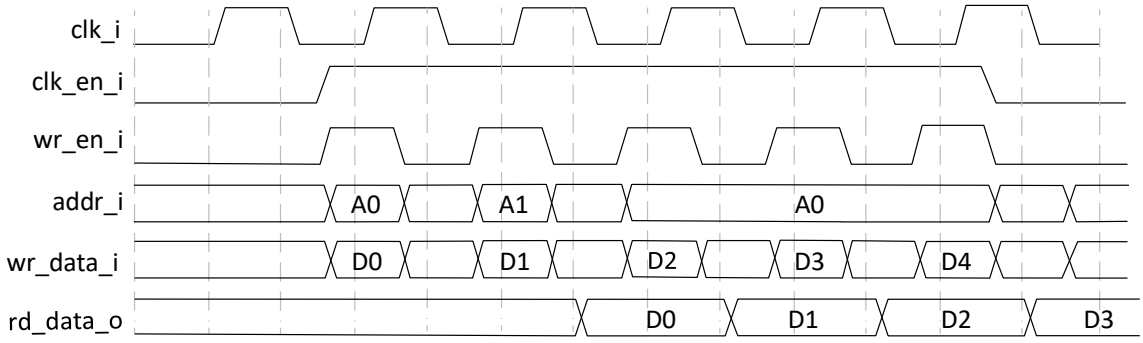

Figure 9.18. Single-Port LRAM Timing Diagram in Write Through Mode, Output Register Disabled

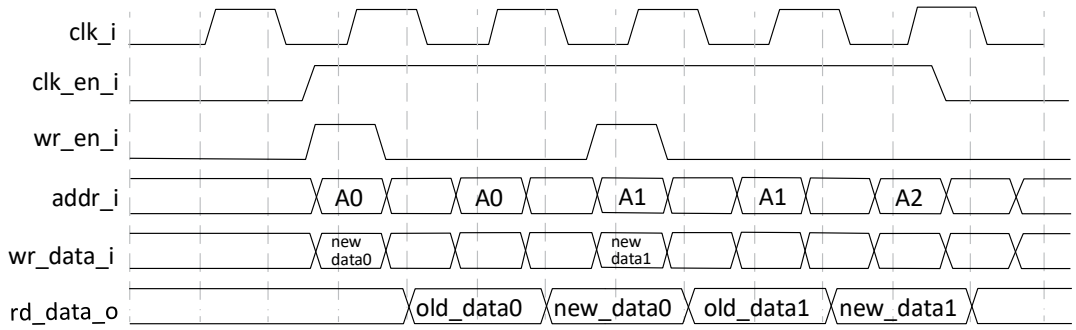

Figure 9.19. Single-Port LRAM Timing Diagram in Read Before Write Mode, Output Register Disabled

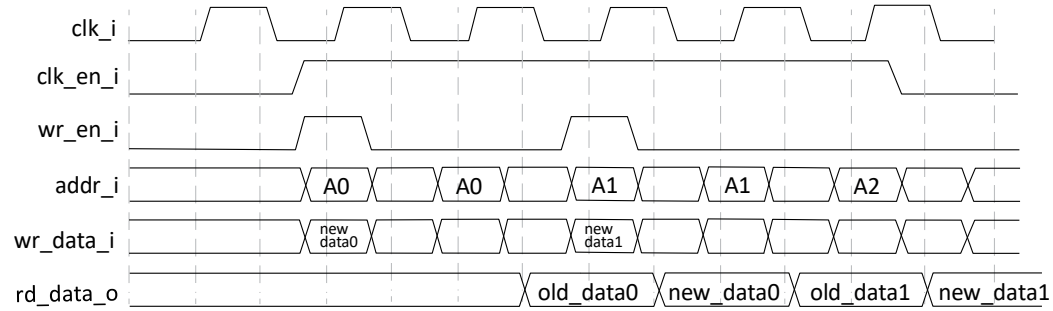

Figure 9.20. Single-Port LRAM Timing Diagram in Read Before Write Mode, Output Register Enabled

10. Initializing Memory

In each memory mode, it is possible to specify the power-on state of each bit in the memory array. This allows the memory to be used as ROM if desired. Each bit in the memory array can have a value of 0 or 1.

10.1. Initialization File Formats

The initialization file is an ASCII file, which you can create or edit using any ASCII editor. The IP Catalog supports two memory file formats:

- Binary File
- Hex File

The file name for the memory initialization file is *.mem, for example, <file_name>.mem. Each row includes the value to be stored in a particular memory location. The number of characters or the number of columns represents the number of bits for each address or the width of the memory module, respectively.

The memory initialization can be static or dynamic. In the case of static initialization, the memory values are stored in the bitstream. Dynamic initialization of memories involves memory values stored in the external flash that can be updated by user logic knowing the EBR address locations. The size of the bitstream, either the bit or rbt file, is larger due to the static values stored in it.

The initialization file is primarily used for configuring the ROMs. RAMs can also use the initialization file to preload memory contents.

10.1.1. Binary File

The binary file is a text file of 0s and 1s. The rows indicate the number of words, and the columns indicate the width of the memory.

Memory Size 20×32

```
00100000010000000010000001000000
00000001000000010000000100000001
00000010000000100000001000000010
00000011000000110000001100000011
00000100000001000000010000000100
00000101000001010000010100000101
00000110000001100000011000000110
00000111000001110000011100000111
00001000010010000000100001001000
00001001010010010000100101001001
00001010010010100000101001001010
00001011010010110000101101001011
00001100000011000000110000001100
00001101001011010000110100101101
00001110001111100000111000111110
00001111001111110000111100111111
00010000000100000001000000010000
00010001000100010001000100010001
00010010000100100001001000010010
00010011000100110001001100010011
```

10.1.2. Hex File

The hex file is a text file of hexadecimal characters arranged in a similar row-column arrangement. The number of rows in the file is the same as the number of address locations, with each row indicating the content of the memory location.

Memory Size 8×16

```
A001
0B03
1004
CE06
0007
040A
0017
02A4
```

References

- Lattice Nexus Platform webpage
- Memory Modules – Lattice Radiant Software User Guide (FPGA-IPUG-02033)
- Lattice Radiant FPGA design software
- Lattice Insights for Lattice Semiconductor training courses and learning plans

Technical Support Assistance

Submit a technical support case through www.latticesemi.com/techsupport.

For frequently asked questions, refer to the Lattice Answer Database at https://www.latticesemi.com/Support/AnswerDatabase.

Revision History

Revision 1.9, March 2026

Section	Change Summary
Large RAM (LRAM)	Added the note below to Table 9.1. Single-Port Mode Signals, Table 9.3. True Dual-Port Mode Signal, Table 9.5. Pseudo Dual-Port Mode Signals and Table 9.7. ROM Mode Signals: *Note: The lramready_o signal is LOW if dps_i is asserted*.

Revision 1.8, September 2025

Section	Change Summary
All	Removed addressed hex related descriptions globally.
Memory Generation	• In the description of available memory modules in IP Catalog before Figure 2.1. Memory Modules Available in IP Catalog, changed *Read-Only Memory Large RAM (Large_ROM)* to *Read-Only Memory (Large_ROM)*. • Updated Figure 2.1. Memory Modules Available in IP Catalog, Figure 2.2. IP Catalog in Lattice Radiant Software, Figure 2.3. Example: Generating Pseudo Dual-Port RAM RAM_DP Using IP Catalog, and Figure 2.4. Example: Generating Pseudo Dual-Port RAM RAM_DP Module Customization – General Options.
Memory Features	In ECC in Memory Modules, added the following note: *Note: ECC is only supported in Large RAM (LRAM) across all modes, and in Pseudo Dual-Port RAM (RAM_DP)*.
Memory Modules	Table 4.3. Single-Port Memory Attributes in Nexus Platform Devices: • updated the attribute name of *Enable Byte Enable* to its current; • updated the attribute name of *Memory Initialization* to its current and updated its related Values and Default Value; • updated the Values and Default Value of *Memory File Format*. Table 4.6. True Dual-Port RAM Attributes for Nexus Platform Devices: • updated the Values of the *Port A Data Width* and *Port B Data Width* attributes; • updated the attribute names of *Enable Byte Enable A* and *Enable Byte Enable B* to the current; • added the *Reset Deassertion A* and *Reset Deassertion B* attributes; • updated the attribute name of *Memory Initialization* to its current and updated its related Values and Default Value; • updated the Values and Default Value of *Memory File Format*. Table 4.9. Pseudo Dual-Port RAM Attributes for Nexus Platform Devices: • added the *Enable ECC* attribute and related table notes; • updated the Values and Default Value of the *Memory Initialization* and the *Memory File Format* attributes; • updated descriptions of the *Read Port Address Depth*, the *Read Port Data Width*, the *Write Port Address Depth*, and the *Write Port Data Width* attributes. Table 4.12. ROM Attributes for Nexus Platform Devices: • removed the *Enable ECC* attribute; • removed the repeated row of the *Address Depth* attribute; • updated the attribute name of *Memory Initialization* to its current and updated its related Description, Values, and Default Value; • updated the Values and Default Value of the *Memory File Format* attribute; • updated the attribute name *Enable Output ClockEn* to its current; • updated the attribute name *Reset Assertion* to its current.

FIFO Memory	• Table 5.2. FIFO Attributes for Nexus Platform Devices:
	  • added the *Enable FWFT* attribute;
	  • updated the attribute name of *Enable Almost Empty Flag* to its current;
	  • updated the attribute name of *Enable Almost Full Flag* to its current;

Section	Change Summary
	• updated the attribute name of *Enable Data Count* to its current. • Moved the original Section *6 Dual-Clock First In First Out (FIFO_DC) – EBR-Based or LUT-Based* under this FIFO Memory section.
Dual-Clock First In First Out (FIFO_DC) – EBR-Based or LUT-Based	Table 5.4. FIFO_DC Attributes for Nexus Platform Devices: • added the *Enable FWFT* attribute; • updated the attribute name of *Enable Almost Empty Flag* to its current; • updated the attribute name of *Enable Almost Full Flag* to its current and updated its Default Value; • updated the attribute name of *Enable Data Count (Write)* to its current; • updated the attribute name of *Enable Data Count (Read)* to its current; • updated the Default Value of *Enable Output Register*.
Distributed Single-Port RAM (Distributed_SPRAM) – PFU Based	Table 6.2. Distributed_SPRAM Attributes for Nexus Platform Devices: • added the *Reset Assertion* attribute; • updated the Values of the *Memory Initialization* attribute; • updated the Default Value of the *Memory File Format* attribute.
Distributed Dual-Port RAM (Distributed_DPRAM) – PFU-Based	Table 7.2. Distributed_DPRAM Attributes for Nexus Platform Devices: • added the *Reset Assertion* attribute; • updated the Default Value of *Address Depth*; • updated the Values and Default Value of *Data Width*; • updated the Values of *Memory Initialization*; • updated the Default Value of *Memory File Format*.
Distributed ROM (Distributed_ROM) – PFU-Based	Table 8.2. Distributed ROM Attributes for Nexus Platform Devices: • added the *Reset Assertion* and *Memory Initialization* attributes; • updated the Default Value of the *Address Depth* attribute; • updated the Values and the Default Value of the *Data Width* attribute; • updated he Default Value of the *Memory File Format* attribute.
Large RAM (LRAM)	• Table 9.2. Attributes Summary for Single-Port Mode: replaced the old Table 10.2 with the current to reflect the latest attributes for the Large RAM primitive in the Single-Port mode. • Table 9.4. Attributes Summary for True Dual-Port Mode: replaced the old Table 10.4 with the current to reflect the latest attributes for the Large RAM primitive in the True Dual-Port mode. • Table 9.6. Attributes Summary for Pseudo Dual-Port Mode: replaced the old Table 10.6 with the current to reflect the latest attributes for the Large RAM primitive in the Pseudo Dual-Port Mode. • Table 9.8. Attributes Summary for ROM Mode: replaced the old Table 10.8 with the current to reflect the latest attributes for the Large RAM primitive in the ROM mode; • Updated section headings of Single-Port LRAM (Large_RAM_SP), True Dual-Port LRAM (Large_RAM_DP_True), Pseudo Dual-Port LRAM (Large_RAM_DP), and Large Read-Only Memory (Large_ROM) to the current. • Updated Figure 9.13. Large ROM Generated by IP Catalog.

Revision 1.7, March 2025

Section	Change Summary
Acronyms in This Document	Updated this section.
Memory Module	Fixed the following typos: • in the Single-Port RAM (RAM_DQ) – EBR-Based section, • changed *the primitive name is SP16KD* to *the primitive name is SP16K*;

Section	Change Summary

	• changed *if the memory required is larger than 18K, then cascading can be used using the CS port (CSA and CSB in this case)* to *if the memory required is larger than 18 kb, then cascading can be used using the CS port*.
	• in the Pseudo Dual-Port RAM (RAM_DP) – EBR-Based section,
	  • changed *if the memory required is larger than 18K, then cascading can be used using the CS port (CSA and CSB in this case)* to *if the memory required is larger than 18 kb, then cascading can be used using the CS ports, CSW and CSR in this case*;
	  • changed the table caption of Table 4.7. EBR-Based Pseudo Dual-Port Memory Port Definitions from *EBR-Based True Dual-Port Memory Port Definitions* to its current.

Distributed ROM (Distributed_ROM) – PFU-Based	Fixed the following typos: • changed the figure caption of Figure 9.2. PFU-Based Distributed ROM Timing Waveform – without Output Registers from *PFU-Based Distributed Dual-Port RAM Timing Waveform – without Output Registers* to its current; • changed the figure cation of Figure 9.3. PFU-Based Distributed ROM Timing Waveform – with Output Registers from *PFU-Based Distributed Dual-Port RAM Timing Waveform – with Output Registers* to its current.

Revision 1.6, March 2024

Section	Change Summary
All	Minor editorial fixes.
Disclaimers	Updated this section.
Memory Modules	Updated the information in Subsection 4.1.2 Reset to, *The Reset (or RST) signal resets output registers of the RAM*.
References	Added this section.
Technical Support Assistance	Added reference to the Lattice Answer Database on the Lattice website.

Revision 1.5, July 2022

Section	Change Summary
Dual Clock First-In-First-Out (FIFO_DC) – EBR-Based or LUT-Based	• Updated Table 5.2. FIFO Attributes for Nexus Platform Devices. Added a row and a footnote for Controller Implementation Type combinations. • Updated Table 6.2. FIFO_DC Attributes for Nexus Platform Devices. Added two rows for Controller Implementation Type combinations and Read Data Width. Added a footnote for Controller Implementation Type combinations.

Revision 1.4, May 2022

Section	Change Summary
Dual Clock First-In-First-Out (FIFO_DC) – EBR-Based or LUT-Based	Updated both Table 5.2. FIFO Attributes for Nexus Platform Devices and Table 6.2. FIFO_DC Attributes for Nexus Platform Devices. Added a row and a footnote for Controller Implementation Type combinations.

Revision 1.3, March 2022

Section	Change Summary
All	• Changed document title to Memory User Guide for Nexus Platform. • Added MachXO5-NX support.

Revision 1.2, June 2021

Section	Change Summary
All	• Added CertusPro-NX support. • Minor adjustments in style.

Revision 1.1, June 2020

Section	Change Summary
All	• Changed document title to Memory Usage Guide for Nexus Platform • Added Certus-NX support.
Introduction	Added LRAM ROM information.
Memory Generation	Updated the following figures: • Figure 2.1. Memory Modules Available in IP Catalog • Figure 2.2. IP Catalog in Lattice Radiant Software
Large RAM (LRAM)	General revision

Revision 1.0, November 2019

Section	Change Summary
All	Initial release

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